Atmel SAM4SP32A



CORTEX-M4 PRIME SoC

PRELIMINARY DATASHEET

Features

- Core
 - ARM® Cortex[™]-M4 with a 2Kbytes cache running at 120MHz
 - Memory Protection Unit (MPU)
 - DSP Instruction Set
 - Thumb®-2 instruction set
- Memories
 - 2048 Kbytes embedded Flash with optional dual bank and cache memory
 - 160 Kbytes embedded SRAM
 - 16 Kbytes ROM with embedded boot loader routines (UART, USB) and IAP routines
- System
 - Embedded voltage regulator for single supply operation
 - Power-on-Reset (POR), Brown-out Detector (BOD) and Watchdog for safe operation
 - Quartz or ceramic resonator oscillators: 3 to 20 MHz main power with Failure Detection and optional low-power 32.768 kHz for RTC or device clock
 - RTC with Gregorian and Persian Calendar mode, waveform generation in low power modes
 - RTC clock calibration circuitry for 32.768 kHz crystal frequency compensation
 - High precision 8/12 MHz factory trimmed internal RC oscillator with 4 MHz default frequency for device startup. In-application trimming access for frequency adjustment
 - Slow Clock Internal RC oscillator as permanent low-power mode device clock
 - Two PLLs up to 240 MHz for device clock and for USB
 - Temperature Sensor
 - Up to 22 Peripheral DMA (PDC) Channels
- Low Power Modes
 - Sleep and Backup Modes, down to 1 µA in Backup Mode
 - Ultra low-power RTC
- Peripherals
 - USB 2.0 Device: 12 Mbps, 2668 byte FIFO, up to 8 bidirectional Endpoints. On-Chip Transceiver
 - 2 USARTs with ISO7816, IrDA ®, RS-485, Manchester and Modem Mode
 - Two 2-wire UARTs
 - 2 Two Wire Interface (I2C compatible), 1 Synchronous Serial Controller (SSC)
 - 2 Three-Channel 16-bit Timer/Counter with capture, waveform, compare and PWM mode. Quadrature Decoder Logic and 2-bit Gray Up/Down Counter for Stepper Motor
 - 4-channel 16-bit PWM with Complementary Output, Fault Input, 12-bit Dead Time Generator Counter

- 32-bit Real-time Timer and RTC with calendar and alarm features
- One Analog Comparator with flexible input selection
- 32-bit Cyclic Redundancy Check Calculation Unit (CRCCU)
- Write Protected Registers
- I/O
 - Up to 38 I/O lines with external interrupt capability (edge or level sensitivity), debouncing, glitch filtering and on-die Series Resistor Termination
 - Three 32-bit Parallel Input/Output Controllers, Peripheral DMA assisted Parallel Capture Mode
- PRIME PLC Modem
 - Power Line Carrier Modem for 50 and 60 Hz mains
 - 97-carrier OFDM PRIME compliant
 - Baud rate Selectable: 21400 to 128600 bps
 - Differential BPSK, QPSK, 8-PSK modulations
 - Automatic Gain Control and signal amplitude tracking
 - Embedded on-chip DMAs
 - Media Access Control
 - Viterbi decoding and CRC PRIME compliant
 - 128-bit AES encryption
 - Channel sensing and collision pre-detection
- Package
 - 128-Lead LQFP
 - Pb-free and RoHS compliant
- Typical Applications
 - PRIME Smart Meters
 - PRIME Data Concentrator



Description

The SAM4SP32A is a new evolution of SAM4SD32 Flash microcontroller based on the high performance 32-bit ARM Cortex-M4 RISC processor with a PRIME Power Line Communication Modem SoC integrated.

The SAM4SP32A operates at a maximum speed of 120 MHz and features with a 2048 Kbytes of Flash, with optional dual bank implementation and 2Kbytes of cache memory, 160 Kbytes of SRAM, and 32Kbytes embedded SRAM memory available for PRIME specification requirements.

The peripheral set mainly includes a Certified PRIME Power line communication transceiver with a featured Class D power amplifier and a set of hardware accelerators blocks to execute the heavy tasks of the PRIME protocol without the interruption of the Cortex-M4 CPU. Furthermore, the SAM4SP32A includes a Full Speed USB Device port with embedded transceiver, , 2x USARTs, 2x UARTs, 2x TWIs, an I2S, as well as 1 PWM timer, 2x three channel general-purpose 16-bit timers (with stepper motor and quadrature decoder logic support), an RTC, a Synchronous Serial Controller (SSC) and an analog comparator.

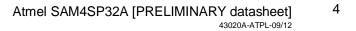
The Atmel SAM4SP32A SoC device combines robust and high performances PRIME PLC Modem with a powerfull Cortex-M4 microcontroller with the best ratio in terms of reduced power consumption, processing power and peripheral set. This enables the SAM4SP32A to sustain a wide range of applications including PRIME Smart Grid and data concentrator solutions.

SAM4SP32A operates from 3.0V to 3.6V



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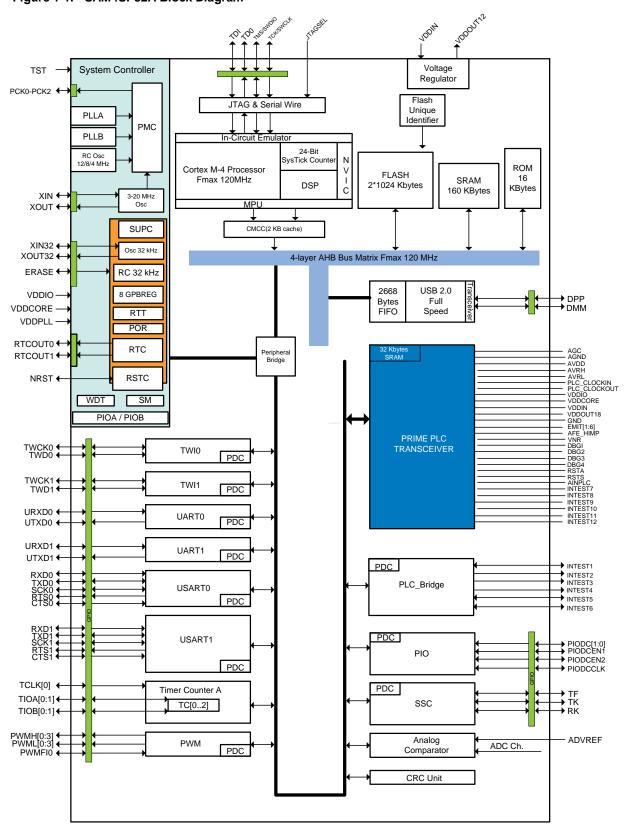


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1. Block Diagram



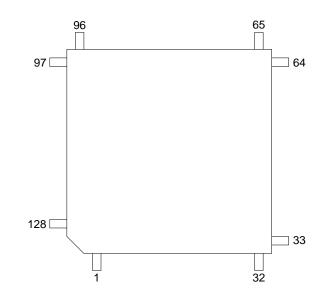




2. Package and Pinout

2.1 **128-Lead LQFP Package Outline**

Figure 2-1. Orientation of the 128-Lead Package





2.2 128-Lead LQFP Pinout

Table 2-1. SAM4SP32A 128-Lead LQFP pinout

1	ADVREF	33	PC0	65	INTEST7	97	TDO/TRACESWO/ PB5
2	GND	34	GND	66	INTEST10	98	DBG0
3	GND	35	VDDIO	67	INTEST12	99	JTAGSEL
4	AGC	36	PA16/PGMD4	68	INTEST11	100	DBG1
5	GND	37	NC	69	TDI/PB4	101	DBG2
6	VDDIO	38	PA15/PGMD3	70	VDDIO	102	GND
7	AGND	39	INTEST1	71	PA6/PGMNOE	103	VDDIO
8	PB0	40	INTEST2	72	PA5/PGMRDY	104	DBG3
9	AVDD	41	PA24/PGMD12	73	PA4/PGMNCMD	105	TMS/SWDIO/PB6
0	PB1	42	PC5	74	GND	106	DBG4
11	AGND	43	NC	75	EMIT1	107	RSTA
12	AVDD	44	NC	76	VDDIO	108	RSTS
13	VRH	45	VDDCORE	77	NRST	109	TCK/SWCLK/PB7
14	PB2	46	GND	78	TST	110	GND
15	AINPLC	47	PA25/PGMD13	79	EMIT2	111	VDDOUT18
16	PB3	48	VDDOUT18	80	EMIT3	112	GND
17	VRL	49	NC	81	PA3	113	VDDCORE
18	VDDIN	50	INTEST3	82	EMIT4	114	VDDIN
9	VDDOUT12	51	INTEST4	83	PA2/PGMEN2	115	ERASE/PB12
20	PA17/PGMD5	52	INTEST5	84	GND	116	VDDIN
21	PC26	53	PA10/PGMM2	85	VDDIO	117	DDM/PB10
22	PA18/PGMD6	54	GND	86	EMIT5	118	DDP/PB11
23	PA21/PGMD9	55	PA9/PGMM1	87	VDDIO	119	VDDIO
24	VDDCORE	56	INTEST6	88	VDDIO	120	VDDIO
25	PA19/PGMD7	57	GND	89	NC	121	PLC_CLOCKIN
26	PA22/PGMD10	58	VDDIO	90	EMIT6	122	PB13/DAC0
27	PA23/PGMD11	59	PA8/XOUT32/ PGMM0	91	GND	123	PLC_CLOCKOUT
28	PA20/PGMD8	60	INTEST9	92	VDDIO	124	GND
29	GND	61	GND	93	AFE_HIMP	125	PB8/XOUT
30	VDDIO	62	PA7/XIN32/ PGMNVALID	94	PA1/PGMEN1	126	GND
31	NC	63	INTEST8	95	PA0/PGMEN0	127	PB9/PGMCK/XIN
32	NC	64	VDDIO	96	VNR	128	VDDPLL



3. Signal Description

Table 3-1. Signal Description List

			Active	Voltage	
Signal Name	Function	Туре	Level	Reference	Comments
	Powe	er Supplies			
VDDIO	Peripherals I/O Lines and USB transceiver Power Supply	Power			3.0V to 3.6V
VDDIN	Voltage Regulator Input, ADC, DAC and Analog Comparator Power Supply	Power			3.0V to 3.6V
VDDCORE	Power the core, the embedded memories and the peripherals	Power			1.08V to 1.32V
VDDPLL	Oscillator and PLL Power Supply	Power			1.08V to 1.32V
VDDOUT18	LDO Output Power Supply	Power			1.8V Ouput
VDDOUT12	Voltage Regulator Output	Power			1.2V Output
AVDD	Analog Converter Power Supply	Power			3.0V to 3.6V
AGND	Analog Ground	Ground			
GND	Digital Ground	Ground			
	Clocks, Osc	illators and PL	Ls		
XIN	Main Oscillator Input	Input			Reset State:
XOUT	Main Oscillator Output	Output			-PIO Input
XIN32	Slow Clock Oscillator Input	Input			-Internal Pull-up disabled
XOUT32	Slow Clock Oscillator Output	Output		VDDIO	-Schmitt Trigger enabled ⁽¹⁾
PCKO - PCK2	Programmable Clock Output	Output			Reset State: -PIO Input -Internal Pull-up enabled -Schmitt Trigger enabled ⁽¹⁾
PLC_CLOCKIN	External clock Input reference	Input			
PLC_CLOCKOUT	External clock Output reference	Output			
	Analog Input	Voltage Refer	ence		1
AINPLC	Direct-analog input voltage	Analog			
AVRH	Analog input high voltage reference	Analog			
AVRL	Analog input low voltage reference	Analog			
ADVERF	Analog Comparator Reference	Analog			



Table 3-1. Signal Description List (Continued)

			Active	Voltage	
Signal Name	Function	Туре	Level	Reference	Comments
	Real	Time Clock			
RTCOUT0	Programmable RTC waveform output	Output			Reset State:
RTCOUT1	Programmable RTC waveform output			VDDIO	-PIO Input
		Output		VDDIO	-Internal Pull-up disabled
					-Schmitt Trigger enabled ⁽¹⁾
	Serial Wire/JTA	G Debug Port - S	SWJ-DP		
TCK/SWCLK	Test Clock/Serial Wire Clock	Input			Reset State:
TDI	Test Data In	Input			- SWJ-DP Mode
TDO/TRACESWO	Test Data Out / Trace Asynchronous Data Out	Output		VDDIO	- Internal pull-up disabled
TMS/SWDIO	Test Mode Select /Serial Wire Input/Output	Input/ I/O		-	- Schmitt Trigger enabled ⁽¹⁾
JTAGSEL	JTAG Selection	Input	High		Permanent Internal pull-down
	Flas	h Memory			· ·
ERASE	Flash and NVM Configuration Bits Erase Command	Input	High	VDDIO	Reset State: - Erase Input - Internal pull-down enabled - Schmitt Trigger enabled ⁽¹⁾
	Re	eset/Test			
NRST	Synchronous Microcontroller Reset	١/٥	Low		Permanent Internal pull-up
TST	Test Select	Input		VDDIO	Permanent Internal pull-down
	PRIME PLC TRANS	CEIVER Signal C	Controller	1	l
AGC	Automatic Gain Control	Output			
EMITx	PLC Transmission ports	Output			See footnote ⁽²⁾
VNR	PLC Zero Crossing Detection Signal	Input			
AFE_HIMP	Analog Front-End High-Impedance	Output			
RSTA	PLC Asynchronous reset	Input			Internal configuration: 33kΩ
RSTS	Initialization Signal	Input			typ. pull-down resistor

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Table 3-1. Signal Description List (Continued)

			Active	Voltage	
Signal Name	Function	Туре	Level	Reference	Comments
	PRIME PLC TRANS	CEIVER Configur	ration Pins		
DBGx	External Configuration Pins	I/O			See Pin Description for details
INTEST7 – INTEST12	External Configuration Pins	I/O			
	Universal Asynchronou	s Receiver Trans	sceiver - UA	RTx	
URXDx	UART Receive Data	Input			
UTXDx	UART Transmit Data	Output			
	PIO Controlle	r - PIOA - PIOB -	PIOC		
PA0 - PA31	Parallel IO Controller A	I/O			Reset State:
PB0 - PB14	Parallel IO Controller B	I/O		VDDIO	- PIO or System IOs(2)
PC0 - PC31	Parallel IO Controller C	I/O		VDDIO	- Internal pull-up enabled
		1/0			- Schmitt Trigger enabled ⁽¹⁾
	Universal Synchronous Asynch	nronous Receive	er Transmitt	er USARTx	1
SCKx	USARTx Serial Clock	I/O			
TXDx	USARTx Transmit Data	I/O			
RXDx	USARTx Receive Data	Input			
RTSx	USARTx Request To Send	Output			
CTSx	USARTx Clear To Send	Input			
	Synchronous	Serial Controller	r - SSC		
тк	SSC Transmit Clock	I/O			
RK	SSC Receive Clock	I/O			
TF	SSC Transmit Frame Sync	I/O			
	Timer	/Counter - TC			
TCLKx	TC Channel x External Clock Input	Input			
TIOAx	TC Channel x I/O Line A	I/O			
TIOBx	TC Channel x I/O Line B	I/O			
	Pulse Width Mode	ulation Controlle	er- PWMC		
PWMHx	PWM Waveform Output High for channel x	Output			
PWMLx	PWM Waveform Output Low for channel x	Output			Only output in complementary mode when dead time insertion is enabled.
PWMFI0	PWM Fault Input	Input			



Table 3-1. Signal Description List (Continued)

			Active	Voltage			
Signal Name	Function	Туре	Level	Reference	Comments		
	PL	C Brigde					
INTEST1 – INTEST6	External Configuration pins	I/O					
	Two-Wire	e Interface- TWI	I				
TWDx	TWIx Two-wire Serial Data	I/O					
ТWCКх	TWIx Two-wire Serial Clock	I/O					
	Analog Co	omparator - ACC	3				
AC0 - AC7	Analog Comparator Inputs	Analog					
	USB Full Speed Device						
DMM	USB Full Speed Data -	0			Reset State:		
	USB Full Speed Data +	Analog, Digital		VDDIO	- USB Mode		
DPP		2.8100			- Internal Pull-down ⁽³⁾		

Note:

- 1. Schmitt Triggers can be disabled through PIO registers.
- 2. Different configurations allowed depending on external topology and net behavior.
- Refer to USB Section of the product Electrical Characteristics for information on Pull-down value in USB Mode.



4. Pin Description

Table 4-1.Pin Description List

Pin Number	Pin Name	Functions	Туре	Comments
1	ADVREF		Analog	Analog Voltage Comparator reference
2, 3, 5, 29, 34, 46, 54, 57, 61, 74, 84, 91, 102, 110, 112, 124, 126	GND		Power	Digital Ground
4	AGC		Output	 Automatic Gain Control This digital output is managed by AGC hardware logic to drive external circuitry if input signal attenuation is needed
6, 30, 58, 64, 70, 76, 85, 88, 87, 92, 103, 119, 120,	VDDIO		Power	Digital power supply. Voltage range: 3.0V - 3.6 V Must be decoupled by external capacitors
7, 11	AGND		Power	Analog ground
8	PB0	PWMH0 AC4 RTCOUT0	I/O	 PIO Controller B Multiplexing (PB0): PWM Waveform Output High for channel 0 Analog Comparator Input channel 4 Programmable RTC waveform output See Signal Description for details.
9, 12	AVDD		Power	Analog converter power supply. Voltage range: 3.0V - 3.6 V
10	PB1	PWMH1 AC5 RTCOUT1	I/O	 PIO Controller B Multiplexing (PB1): PWM Waveform Output High for channel 1 Analog Comparator Input channel 5 Programmable RTC waveform output See Signal Description for details.
13	AVRH		Input	Analog input high voltage reference



Pin Number	Pin Name	Functions	Туре	Comments
14	PB2	URXD1 AC6 WKUP12	I/O	 PIO Controller B Multiplexing (PB2): UART1 Receive Input Data Analog Comparator Input channel 6 Wake-up Source 12 Fast start up of the Processor Active level: Low
15	AINPLC		Input	Direct-analog input voltage
16	PB3	UTXD1 PCK2 AC7	I/O	 PIO Controller B Multiplexing (PB3): UART1 Transmit Output Data Programmable clock output 2 Analog Comparator Input channel 7 See Signal Description for details.
17	AVRL		Input	Analog input low voltage reference
18, 35, 114, 116	VDDIN		Р	Voltage Regulator Input, Analog Comparator Power Supply. Voltage range: 3.0V – 3.6 V
19	VDDOUT12		Р	Voltage output regulator of 1.2 volts
20	PA17/PGMD5	TD PCK1 PWMH3 AC0	I/O	 PIO Controller A Multiplexing (PA17): Synchronous Serial Controller (SSC) Transmit Output Data Programmable clock output 1 PWM Waveform Output High for channel 3 Analog Comparator Input channel 0 See Signal Description for details.
21	PC26	TIOA4	I/O	 PIO Controller C Multiplexing (PC26): Tmer/Counter Channel 4 I/O Line A General purpose I/O
22	PA18/PGMD6	RD PCK2 AC1	I/O	 PIO Controller A Multiplexing (PA18): Synchronous Serial Controller (SSC) Receive Input Data Programmable clock output 2 Analog Comparator Input channel 1 See Signal Description for details.



Pin Number	Pin Name	Functions	Туре	Comments
23	PA21/PGMD9	RXD1 PCK1	I/O	 PIO Controller A Multiplexing (PA21): USART1 Receive Input Data Programmable clock output 1 See Signal Description for details.
24, 45, 113	VDDCORE		Р	Core, embedded memories and the peripherals power supply: Voltage range of 1.08V to 1.32V
25	PA19/PGMD7	RK PWML0 AC2WKUP 9	I/O	 PIO Controller A Multiplexing (PA19): Synchronous Serial Controller (SSC) I/O Receive Clock PWM Waveform Output Low for channel 0 Analog Comparator Input channel 2 Wake-up Source 9 Fast start up of the Processor Active level: Low
26	PA22/PGMD10	TXD1	I/O	PIO Controller A Multiplexing (PA22): USART1 Transmit I/O Data
27	PA23/PGMD11	SCK1 PWMH0 PIODCLLK	I/O	 PIO Controller A Multiplexing (PA23): USART1 I/O Serial Clock PWM Waveform Output High for channel 0 Parallel Capture Mode Input Clock Voltage reference: VDDIO
28	PA20/PGMD8	RF PWML1 AC3 WKUP10	I/O	 PIO Controller A Multiplexing (PA20): Synchronous Serial Controller (SSC) I/O Receive Frame Sync PWM Waveform Output Low for channel 1 Analog Comparator Input channel 3 Wake-up Source 10 Fast start up of the Processor Active level: Low
31, 32, 37, 43, 44,	NC		-	No connect



Pin Number	Pin Name	Functions	Туре	Comments
				PIO Controller C Multiplexing (PC0):
33	PC0	PWML0	I/O	 PWM Waveform Output Low for channel 0
				General purpose I/O
				PIO Controller A Multiplexing (PA16):
				 Synchronous Serial Controller (SSC) I/O Transmit Clock
				 Timer/Counter (TC) Channel 1 I/O Line B
36	PA16/PGMD4	TK TIOB1 PWML2 I/O	 PWM Waveform Output Low for channel 2 	
		WKUP15 PIODCEN2		Wake-up Source 15
		FIODGENZ		Fast start up of the Processor
				Active level: Low
				PIO Controller - Parallel Capture Mode Enable 2
				Voltage reference: VDDIO
	PA15/PGMD3	TF TIOA1 PWML3		PIO Controller A Multiplexing (PA15):
			I/O	 Synchronous Serial Controller (SSC) I/O Transmit Frame Sync
				 Timer/Counter (TC) Channel 1 I/O Line A
38				 PWM Waveform Output Low for channel 3
		WKUP14 PIODCEN1		Wake-up Source 14
		PIODCENT		Fast start up of the Processor
				Active level: Low
				PIO Controller - Parallel Capture Mode Enable 1
				Voltage reference: VDDIO
39	INTEST1		0	External configuration pin. This pin must connect to INTEST7 (pin 65)
40	INTEST2		0	External configuration pin. This pin must connect to INTEST8 (pin 63)
				PIO Controller A Multiplexing (PA24):
				USART1 Request To Send
41	PA24/PGMD12	RTS1 PWMH1 PIODC0	I/O	 PWM Waveform Output High for channel 1
				PIO Controller-Parallel Capture Mode Data 0



Pin Number	Pin Name	Functions	Туре	Comments
42	PC5		I/O	PIO Controller C Multiplexing (PC5): General purpose I/O
47	PA25/PGMD13	CTS1 PWMH2 PIODC1	I/O	 PIO Controller A Multiplexing (PA25): USART1 Clear To Send PWM Waveform Output High for channel 2 PIO Controller-Parallel Capture Mode Data 1
48, 111	VDDOUT18		Power	1.8V LDO Output Power Supply. Just Requires output capacitor. Not intended for external use
50	INTEST3		0	External configuration pin. This pin must connect to INTEST9 (pin 60)
51	INTEST4		0	External configuration pin. This pin must connect to INTEST10 (pin 66)
52	INTEST5		0	External configuration pin. This pin must connect to INTEST11 (pin 68)
53	PA10/PGMM2	UTXD0	I/O	PIO Controller A Multiplexing (PA10): • UART Transmit Output Data •
55	PA9/PGMM1	URXD0 PWMFI0 WKUP6	I/O	 PIO Controller A Multiplexing (PA9): UART Receive Input Data PWM Fault Input Wake-up Source 6 Fast start up of the Processor Active level: Low
56	INTEST6		0	External configuration pin. This pin must connect to INTEST12 (pin 67)
59	PA8/ XOUT32/PGMM0	CTS0 WKUP5 XOUT32	I/O	 PIO Controller A Multiplexing (PA8): USART0 Clear To Send Wake-up Source 5 Fast start up of the Processor Active level: Low Slow Clock Oscillator Output See Signal Description for details.
60	INTEST9		Ι	External configuration pin. This pin must connect to INTEST3 (pin 50)



Pin Number	Pin Name	Functions	Туре	Comments	
62	PA7/ XIN32/PGMNVALID	RTS0 PWMH3 XIN32	I/O	 PIO Controller A Multiplexing (PA7): USART0 Request To Send PWM Waveform Output High for channel 3 Slow Clock Oscillator Input See Signal Description for details. 	
63	INTEST8		I	External configuration pin. This pin must connect to INTEST2 (pin 40)	
65	INTEST7		Ι	External configuration pin. This pin must connect to INTEST1 (pin 39)	
66	INTEST10		I	External configuration pin. This pin must connect to INTEST4 (pin 51)	
67	INTEST12		I	External configuration pin. This pin must connect to INTEST6 (pin 56)	
68	INTEST11		I	External configuration pin. This pin must connect to INTEST5 (pin 52)	
69	TDI/PB4	TWD1 PWMH2 TDI	I/O	 PIO Controller B Multiplexing (PB4): Two-Wire Interface – TWI1 Two-wire I/O Serial Data PWM Waveform Output High for channel 2 Serial Wire/JTAG Debug Port (SWJ-DP) Test Data In See Signal Description for details. 	
71	PA6/PGMNOE	TXD0 PCK0	I/O	PIO Controller A Multiplexing (PA6): USART0 Transmit I/O Data Programmable Clock Output See Signal Description for details. 	
72	PA5/PGMRY	RXD0 WKUP4	I/O	PIO Controller A Multiplexing (PA5): USART0 Receive Input Data Wake-up Source 4 Fast start up of the Processor Active level: Low	



Pin Number	Pin Name	Functions	Туре	Comments
				PIO Controller A Multiplexing (PA4):
				 Two-Wire Interface-TWI0 Two- wire I/O Serial Clock
73	PA4/PGMNCMD	TWCK0 TCLK0	I/O	 Timer/Counter (TC) Channel 0 External Clock Input
	WKUP3			 Wake-up Source 3 Fast start up of the Processor Active level: Low
75, 79,				PLC Transmission ports.
80, 82, 86, 90,	EMIT(1:6)		Output	 See Signal Description for details.
				Synchronous PRIME PLC Reset
77	NRST		I/O	 See Signal Description for details.
				Test Select
78	TST		I	 See Signal Description for details.
		TWD0		PIO Controller A Multiplexing (PA3):
81	PA3		I/O	 Two-Wire Interface - TWI0 Two- wire I/O Serial Data
				PIO Controller A Multiplexing (PA2):
				 PWM Waveform Output High for channel 2
83	PA2/PGMEN2	PWMH2 SCK0	I/O	USART0 I/O Serial Clock
-		WKUP2		Wake-up Source 2
				Fast start up of the Processor
				Active level: Low



Pin Number	Pin Name	Functions	Туре	Comments
93	AFE_HIMP		Output	 Analog Front-End High-Impedance This digital output is used by the chip to select between low-impedance and high-impedance transmission branch (when working with a "two half-H-bridge branches" analog front end configuration). This way, the system adapts its transmission external circuitry to the net impedance, improving transmission behavior. The polarity of this pin can be inverted by hardware. Please refer to the Reference Design for further information.
94	PA1/PGMEN1	PWMH1 TIOB0 WKUP1	I/O	 PIO Controller A Multiplexing (PA1): PWM Waveform Output High for channel 1 Timer/Counter (TC) Channel 0 I/O Line B Wake-up Source 1 Fast start up of the Processor Active level: Low
95	PA0/PGMEN0	PWMH0 TIOA0 WKUP0	I/O	 PIO Controller A Multiplexing (PA0): PWM Waveform Output High for channel 0 Timer/Counter (TC) Channel 0 I/O Line A Wake-up Source 0 Fast start up of the Processor Active level: Low
96	VNR		Input	 PLC Zero Crossing Detection Signal This input detects the zero- crossing of the mains voltage, needed to determine proper switching times. Depending on whether an isolated or a non- isolated power supply is being used, isolation of this pin should be taken into account in the circuitry design. Please refer to the Reference Design for further information.



Pin Number	Pin Name	Functions	Туре	Comments		
97	TDO/ TRACESWO/PB5	TWCK1 PWML0 WKUP13 TDO TRACESWO	I/O	 PIO Controller B Multiplexing (PB5): Two-Wire Interface - TWI1 Two- wire I/O Serial Clock PWM Waveform Output Low for channel 0 Wake-up Source 13 Fast start up of the Processor Active level: Low TDO - Test Data Out / Trace Asynchronous DataOut (TRACESWO) See Signal Description for details. 		
98	DBG0		Input	Internal configuration: must connect $33k\Omega$ typ. pull-up resistor		
99	JTAGSEL		A-I	Analog input used to select the JTAG boundary scan when asserted at a high level. See Signal Description for details. 		
100	DBG1		Input	Internal configuration: must $33k\Omega$ typ. pull-up resistor		
101	DBG2		Output	No connect		
104	DBG3		Input	Internal configuration: must $33k\Omega$ typ. pull-up resistor		
105	TMS/ SWDIO/PB6	TMS SWDIO	I/O	 PIO Controller B Multiplexing (PB6): TMS - Test Mode Input Select / (SWDIO) Serial Wire I/O See Signal Description for details. 		
106	DBG4		Input	No connect		
107	RSTA		Input	 PLC Asynchronous reset RSTA is a digital input pin used to perform a hardware reset of the ASIC RSTA is active high 		



Pin Number	Pin Name	Functions	Туре	Comments
108	RSTS		Input	 Initialization Signal During power-on, D_INIT should be released before asynchronous reset signal RSTA, in order to ensure proper system start up. Not minimum time is required between both releases, ∆t>0 D_INIT is active high
109	TCK/SWCLK/ PB7	TCK SWCLK	I/O	 PIO Controller B Multiplexing (PB7): TCK -Test Clock/(SWCLK) Serial Wire Clock See Signal Description for details.
115	ERASE/PB12	PWML1 ERASE	I/O	 PIO Controller B Multiplexing (PB12): PWM Waveform Output Low for channel 0 Flash and NVM Configuration Bits Erase Command See Signal Description for details.
117	DDM/PB10	DMM	A-I/O	 PIO Controller B Multiplexing (PB10): USB Full Speed Data – See Signal Description for details.
118	DDP/PB11	DPP	A-I/O	 PIO Controller B Multiplexing (PB11): USB Full Speed Data + See Signal Description for details.
121	PLC_CLOCKIN		Input	 PLC_CLOCKIN must be connected to one terminal of a crystal (when a crystal is being used) or tied to ground if a compatible oscillator is being used



Pin Number	Pin Name	Functions	Туре	Comments	
123	PLC_CLOCKOUT		I/O	 External clock reference PLC_CLOCKOUT must be connected to one terminal of a crystal (when a crystal is being used) or to one terminal of a compatible oscillator (when a compatible oscillator is being used) 	
125	PB8/XOUT	XOUT	Output	PIO Controller B Multiplexing (PB8): Main Oscilator Output	
127	PB9/PGMCK/XIN	XIN	Input	PIO Controller B Multiplexing (PB9): Main Oscilator Input	
128	VDDPLL		Power	Oscillator and PLL Power Supply • 1.08V to 1.32V	



5. Power Considerations

5.1 **Power Supplies**

The SAM4SP32A has several types of power supply pins:

- VDDCORE pins: Power the core, the embedded memories and the peripherals. Voltage ranges from 1.08V to 1.32V.
- VDDIO pins: Power the Peripherals I/O lines (Input/Output Buffers), USB transceiver, Backup part, 32 kHz crystal oscillator and oscillator pads. Voltage ranges from 3.0V to 3.6V.
- VDDIN pin: Voltage Regulator Input, and Analog Comparator Power Supply. Voltage ranges from 3.0V to 3.6V.
- VDDPLL pin: Powers the PLLA, PLLB, the Fast RC and the 3 to 20 MHz oscillator. Voltage ranges from 1.08V to 1.32V.
- AVDD pin: PRIME PLC Analog Converter Power Supply. Voltage ranges from 3.0V to 3.6V.

5.2 Voltage Regulator

The SAM4SP32A embeds two voltage regulators that are managed by the Supply Controller.

The first internal regulator is designed to supply the internal core of SAM4SP32A It features two operating modes:

- In Normal mode, the voltage regulator consumes less than 500 μA static current and draws 80 mA of output current. Internal adaptive biasing adjusts the regulator quiescent current depending on the required load current. In Wait Mode quiescent current is only 5 μA.
- In Backup mode, the voltage regulator consumes less than 1 µA while its output (VDDOUT12) is driven internally to GND. The default output voltage is 1.20V and the start-up time to reach Normal mode is less than 300 µs.

The second internal regulator is designed to supply the internal PRIME PLC Transceiver. Its output (VDDOUT18) is driven internally to GND and the default output voltage is 1.8V. The VDDOUT18 pin just requires an output capacitor in the range of 0.1μ F-10µF and it is not intended for external use.

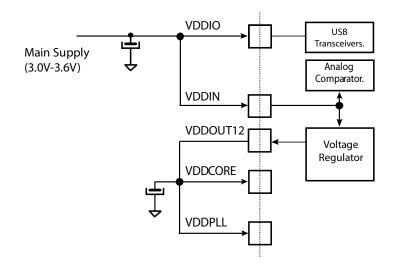
For adequate input and output power supply decoupling/bypassing, refer to the "Voltage Regulator" section in the "Electrical Characteristics" section of the datasheet.

5.3 **Typical Powering Schematics**

The SAM4SP32A supports a 3.0V-3.6V single supply mode. The internal regulator input is connected to the source and its output feeds VDDCORE. Figure 5-1 shows the power schematics.

As VDDIN powers the voltage regulator, and the analog comparator, when the user does not want to use the embedded voltage regulator, it can be disabled by software via the SUPC (note that this is different from Backup mode).

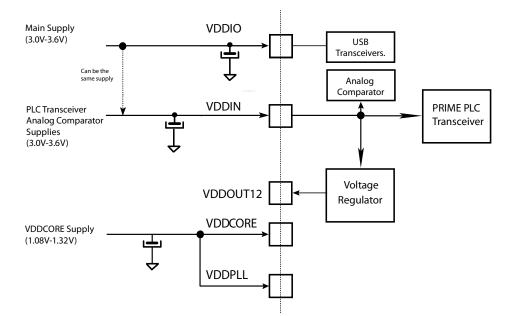




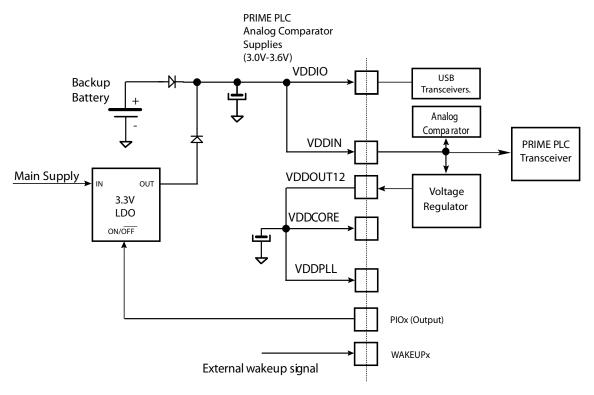
Note: Restrictions

For USB, VDDIO needs to be greater than 3.0V.

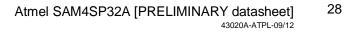
Figure 5-2. Core Externally Supplied







Note: The two diodes provide a "switchover circuit" (for illustration purpose) between the backup battery and the main supply when the system is put in backup mode.





5.4 Active Mode

Active mode is the normal running mode with the core clock running from the fast RC oscillator, the main crystal oscillator or the PLLA. The power management controller can be used to adapt the frequency and to disable the peripheral clocks.

5.5 Low-power Modes

In low-power mode, the 3.3 Volts power source must be shut down before running in any low-power mode. The PRIME PLC transceiver peripheral is turned off during a low-power mode configuration. The various low-power modes of the SAM4SP32A are described below:

5.5.1 Backup Mode

The purpose of backup mode is to achieve the lowest power consumption possible in a system which is performing periodic wake-ups to perform tasks but not requiring fast startup time.

The Supply Controller, zero-power power-on reset, RTT, RTC, Backup registers and 32 kHz oscillator (RC or crystal oscillator selected by software in the Supply Controller) are running. The regulators, PRIME PLC transceiver and the core supply are off.

Backup mode is based on the Cortex-M4 deep sleep mode with the voltage regulators disabled.

The SAM4SP32A can be awakened from this mode through WUP0-15 pins, the supply monitor (SM), the RTT or RTC wake-up event.

Backup mode is entered by using bit VROFF of Supply Controller (SUPC_CR) and with the SLEEPDEEP bit in the Cortex-M4 System Control Register set to 1.

Entering Backup mode:

- Set the SLEEPDEEP bit of Cortex_M4, set to 1.
- Set the VROFF bit of SUPC_CR at 1

Exit from Backup mode happens if one of the following enable wake up events occurs:

- WKUPEN0-15 pins (level transition, configurable debouncing)
- Supply Monitor alarm
- RTC alarm
- RTT alarm

5.5.2 Wait Mode

The purpose of the wait mode is to achieve very low power consumption while maintaining the whole device in a powered state for a startup time of less than few hundred μ s. Current Consumption in Wait mode is typically few μ A (total current consumption) if the internal voltage regulator is used.

In this mode, the clocks of the core, peripherals and memories are stopped. However, the core, peripherals and memories power supplies are still powered except for the PRIME PLC transceiver which remains turned off. From this mode, a fast start up is available.

This mode is entered via WAITMODE =1 (Waitmode bit in CKGR_MOR) and with LPM = 1 (Low Power Mode bit in PMC_FSMR) and with FLPM = 00 or FLPM=01 (Flash Low Power Mode bits in PMC_FSMR).

The Cortex-M4 is able to handle external events or internal events in order to wake-up the core. This is done by configuring the external lines WUP0-15 as fast startup wake-up pins (refer to 0). RTC or RTT Alarm and USB wake-up events can be used to wake up the CPU.



Entering Wait Mode:

- Select the 4/8/12 MHz fast RC oscillator as Main Clock
- Set the LPM bit in the PMC Fast Startup Mode Register (PMC_FSMR)
- Set the FLPM bitfield in the PMC Fast Startup Mode Register (PMC_FSMR)
- Set Flash Wait State at 0
- Set the WAITMODE bit = 1 in PMC Main Oscillator Register (CKGR_MOR)
- Wait for Master Clock Ready MCKRDY=1 in the PMC Status Register (PMC_SR)

5.5.3 Sleep Mode

The purpose of sleep mode is to optimize power consumption of the device versus response time. In this mode, only the core clock is stopped. The peripheral clocks can be enabled. The current consumption in this mode is application dependent.

This mode is entered via Wait for Interrupt (WFI) with LPM = 0 in PMC_FSMR.

The processor can be awakened from an interrupt if WFI instruction of the Cortex M4 is used.

5.5.4 Low Power Mode Summary Table

The modes detailed above are the main low-power modes. Each part can be set to on or off separately and wake up sources can be individually configured. Table 5-1 shows a summary of the configurations of the low-power modes.



Note: Internal Main clock resynchronization cycles are necessary between the writing of MOSCRCEN bit and the effective entry in Wait mode. Depending on the user application, waiting for MOSCRCEN bit to be cleared is recommended to ensure that the core will not execute unde-sired instructions.

Table 5-1.	Low Power Mode Configuration Summary
------------	--------------------------------------

Mode	SUPC, 32 kHz Oscillator, RTC, RTT Backup Registers, POR (Backup Region)	Regulator	Core Memory Periphericals	Mode Entry	Potential Wake Up Sources	Core at Wake Up	PIO State while in Low Power Mode	PIO State at Wake Up	Consumption	Wake-up Time ⁽¹⁾
Backup Mode	ON	OFF	OFF (Not powered)	VROFF = 1 +SLEEPDEEP bit = 1	WUP0-15 pins SM alarm RTC alarm RTT alarm	Reset	Previous state saved	PIOA & PIOB & PIOC Inputs with pull ups	1.5 µА typ ⁽⁴⁾	< 0.5 ms
Wait Mode	ON	ON	Powered (Not clocked)	Waitmode=1 +SLEEPDEEP bit = 0 +LPM bit = 1	Any Event from: Fast startup through WUP0-15 pins RTC alarm RTT alarm USB wake-up	Clocked back	Previous state saved	Unchanged	15 μΑ/ 25 μΑ ⑸	< 10 µs
Sleep Mode	ON	ON	Powered ⁽¹⁾ (Not clocked)	WFE or WFI +SLEEPDEEP bit = 0 +LPM bit = 0	Entry mode =WFI Interrupt Only; Any Enabled Interrupt	Clocked back	Previous state saved	Unchanged	(6)	(6)

Note:

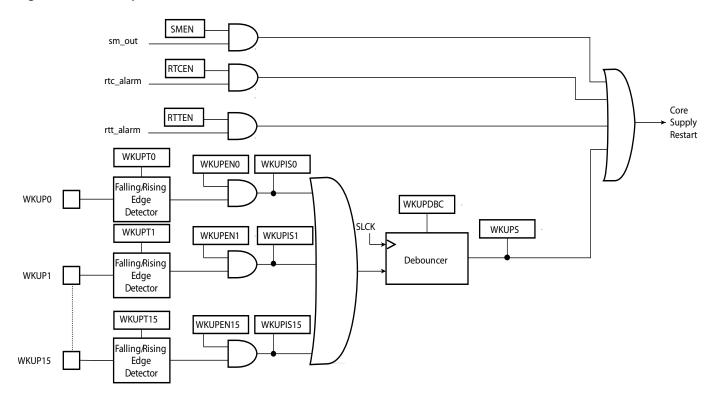
- 1. When considering wake-up time, the time required to start the PLL is not taken into account. Once started, the device works with the 4/8/12 MHz fast RC oscillator. The user has to add the PLL start-up time if it is needed in the system. The wake-up time is defined as the time taken for wake up until the first instruction is fetched.
- 2. The external loads on PIOs are not taken into account in the calculation.
- 3. Supply Monitor current consumption is not included.
- 4. Total Current consumption.
- 5. 15 μA on VDDCORE, 25 μA for total current consumption (using internal voltage regulator), 18 μA for total current consump-tion (without using internal voltage regulator).
- 6. Depends on MCK frequency.
- 7. In this mode the core is supplied and not clocked but some peripherals can be clocked.



5.6 Wake-up Sources

The wake-up events allow the device to exit the backup mode. When a wake-up event is detected, the Supply Controller performs a sequence which automatically re-enables the core power supply and the SRAM power supply, if they are not already enabled.

Figure 5-4. Wake-up Sources



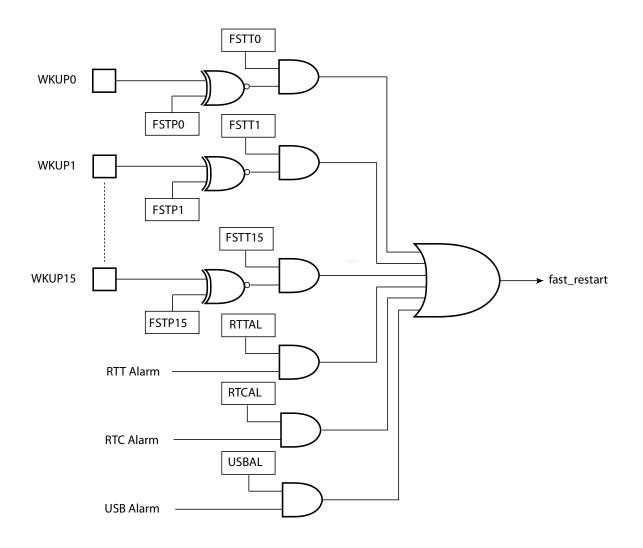


5.7 Fast Startup

The SAM4SP32A allows the processor to restart in a few microseconds while the processor is in wait mode or in sleep mode. A fast start up can occur upon detection of a low level on one of the 19 wake-up inputs (WKUP0 to 15 + SM + RTC + RTT).

The fast restart circuitry, as shown in Figure 5-5, is fully asynchronous and provides a fast start-up signal to the Power Management Controller. As soon as the fast start-up signal is asserted, the PMC automatically restarts the embedded 4/8/12 MHz Fast RC oscillator, switches the master clock on this 4 MHz clock and reenables the processor clock.







6. Input/Output Lines

The SAM4SP32A has several kinds of input/output (I/O) lines such as general purpose I/Os (GPIO) and system I/Os. GPIOs can have alternate functionality due to multiplexing capabilities of the PIO controllers. The same PIO line can be used whether in I/O mode or by the multiplexed peripheral. System I/Os include pins such as test pins, oscillators, erase or analog inputs.

6.1 General Purpose I/O Lines

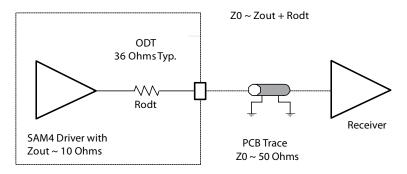
GPIO Lines are managed by PIO Controllers. All I/Os have several input or output modes such as pull-up or pulldown, input Schmitt triggers, multi-drive (open-drain), glitch filters, debouncing or input change interrupt. Programming of these modes is performed independently for each I/O line through the PIO controller user interface. For more details, refer to the product "PIO Controller" section.

The input/output buffers of the PIO lines are supplied through VDDIO power supply rail.

The SAM4SP32A embeds high speed pads able to handle up to 45 MHz for PLC bridge clock lines and 35 MHz on other lines. See AC Characteristics Section of the datasheet for more details. Typical pull-up and pull-down value is 100 k Ω for all I/Os.

Each I/O line also embeds an ODT (On-Die Termination), (see Figure 6-1 below). It consists of an internal series resistor termination scheme for impedance matching between the out-put (SAM4SP32A) driver and the PCB trace impedance preventing signal reflection. The series resistor helps to reduce IOs switching current (di/dt) thereby reducing in turn, EMI. It also decreases overshoot and undershoot (ringing) due to inductance of interconnect between devices or between boards. In conclusion ODT helps diminish signal integrity issues.

Figure 6-1. On-Die Termination



6.2 System I/O Lines

System I/O lines are pins used by oscillators, test mode, reset, JTAG, and the like. Described below in Table 6-1 are the SAM4SP32A system I/O lines shared with PIO lines.

These pins are software configurable as general purpose I/O or system pins. At startup the default function of these pins is always used.



Table 6-1. System I/O Configuration Pin List

SYSTEM_IO bit number	Default function after reset	Other Functions	Constraints for normal start	Configuration
				computation
12	ERASE	PB12	Low level at startup ⁽¹⁾	
10	DMM	PB10	-	In Matrix User Interface
11	DPP	PB11	-	Registers (Refer to the
7	TCK/SWCLK	PB7	-	System I/O Configuration Register in the "Bus
6	TMS/SWDIO	PB6	-	Matrix" section of the
5	TDO/TRACEESWO	PB5	-	datasheet.)
4	TDI	PB4	-	
-	PA7	XIN32	-	See footnote ⁽²⁾ below
-	PA8	XOUT32	-	See looulote below
-	PB9	XIN	-	See footnote ⁽³⁾ below
-	PB8	XOUT	-	See roothole below

Note:

- 1. If PB12 is used as PIO input in user applications, a low level must be ensured at startup to prevent Flash erase before the user application sets PB12 into PIO mode,
- 2. In the product Datasheet Refer to: "Slow Clock Generator" of the "Supply Controller" section.
- 3. In the product Datasheet Refer to: "3 to 20 MHZ Crystal Oscillator" information in the "PMC" section

6.2.2 Serial Wire JTAG Debug Port (SWJ-DP) Pins

The SWJ-DP pins are TCK/SWCLK, TMS/SWDIO, TDO/SWO, TDI and commonly provided on a standard 20-pin JTAG connector defined by ARM. For more details about voltage refer-ence and reset state, refer to Table 3-1.

At startup, SWJ-DP pins are configured in SWJ-DP mode to allow connection with debugging probe. Please refer to the "Debug and Test" Section of the product datasheet.

SWJ-DP pins can be used as standard I/Os to provide users more general input/output pins when the debug port is not needed in the end application. Mode selection between SWJ-DP mode (System IO mode) and general IO mode is performed through the AHB Matrix Special Function Registers (MATRIX_SFR). Configuration of the pad for pull-up, triggers, debouncing and glitch filters is possible regardless of the mode.

The JTAGSEL pin is used to select the JTAG boundary scan when asserted at a high level. It integrates a permanent pull-down resistor of about 15 k Ω to GND, so that it can be left unconnected for normal operations.

By default, the JTAG Debug Port is active. If the debugger host wants to switch to the Serial Wire Debug Port, it must provide a dedicated JTAG sequence on TMS/SWDIO and TCK/SWCLK which disables the JTAG-DP and enables the SW-DP. When the Serial Wire Debug Port is active, TDO/TRACESWO can be used for trace.

The asynchronous TRACE output (TRACESWO) is multiplexed with TDO. So the asynchro-nous trace can only be used with SW-DP, not JTAG-DP. For more information about SW-DP and JTAG-DP switching, please refer to the "Debug and Test" Section.

6.3 Test Pin

The TST pin is used for JTAG Boundary Scan Manufacturing Test or Fast Flash programming mode of the SAM4SP32A series. The TST pin integrates a permanent pull-down resistor of about 15 k Ω to GND, so that it can be left unconnected for normal operations. To enter fast programming mode, see the Fast Flash Programming Interface (FFPI) section. For more on the manufacturing and test mode, refer to the "Debug and Test" section of the product datasheet.



6.4 NRST Pin

The NRST pin is bidirectional. It is handled by the on-chip reset controller and can be driven low to provide a reset signal to the external components or asserted low externally to reset the microcontroller. It will reset the Core and the peripherals except the Backup region (RTC, RTT and Supply Controller). There is no constraint on the length of the reset pulse and the reset controller can guarantee a minimum pulse length. The NRST pin integrates a permanent pull-up resistor to VDDIO of about 100 k Ω . By default, the NRST pin is configured as an input.

6.5 ERASE Pin

The ERASE pin is used to reinitialize the Flash content (and some of its NVM bits) to an erased state (all bits read as logic level 1). It integrates a pull-down resistor of about 100 k Ω to GND, so that it can be left unconnected for normal operations.

This pin is debounced by SCLK to improve the glitch tolerance. When the ERASE pin is tied high during less than 100 ms, it is not taken into account. The pin must be tied high during more than 220 ms to perform a Flash erase operation.

The ERASE pin is a system I/O pin and can be used as a standard I/O. At startup, the ERASE pin is not configured as a PIO pin. If the ERASE pin is used as a standard I/O, startup level of this pin must be low to prevent unwanted erasing. Refer to Peripheral Signal Multiplexing on I/O Lines Also, if the ERASE pin is used as a standard I/O output, asserting the pin to low does not erase the Flash.



7. Processor and Architecture

7.1 ARM Cortex-M4 Processor

- Thumb-2 (ISA) subset consisting of all base Thumb-2 instructions, 16-bit and 32-bit.
- Harvard processor architecture enabling simultaneous instruction fetch with data load/store.
- Three-stage pipeline.
- Single cycle 32-bit multiply.
- Hardware divide.
- Thumb and Debug states.
- Handler and Thread modes.
- Low latency ISR entry and exit.

7.2 APB/AHB Bridge

The SAM4SP32A embeds One Peripheral bridge:

The peripherals of the bridge are clocked by MCK.

7.3 Matrix Master

The Bus Matrix of the SAM4SP32A manages 4 masters, which means that each master shall perform an access concurrently with others, to an available slave.

Each master has its own decoder, which is defined specifically for each master. In order to simplify the addressing, all the masters have the same decodings.

Table 7-1. List of Bus Matrix Masters

Master 0	Cortex-M4 Instruction/Data
Master 1	Cortex-M4 System
Master 2	Peripheral DMA Controller (PDC)
Master 3	CRC Calculation Unit

7.4 Matrix Slaves

The Bus Matrix of the SAM4SP32A manages 5 slaves. Each slave has its own arbiter, allowing a different arbitration per slave.

Table 7-2. List of Bus Matrix Slaves

Slave 0	Internal SRAM
Slave 1	Internal ROM
Slave 2	Internal Flash
Slave 3	External Bus Interface
Slave 4	Peripheral Bridge



7.5 Master to Slave Access

All the Masters can normally access all the Slaves. However, some paths do not make sense, for example allowing access from the Cortex-43 S Bus to the Internal ROM. Thus, these paths are forbidden or simply not wired, and shown as "-" in the following table.

		0	1	2	3
Slaves	Masters	Cortex-M4 I/D Bus	Cortex-M4 S Bus	PDC	CRCCU
0	Internal SRAM	-	Х	Х	х
1	Internal ROM	х	-	Х	х
2	Internal Flash	х	-	-	х
3	External Bus Interface	-	Х	Х	х
4	Peripherical Bridge	-	Х	Х	-

Table 7-3. SAM4SP32A Master to Slave Access

7.6 Peripherical DMA Controller

- Handles data transfer between peripherals and memories
- Low bus arbitration overhead
 - One Master Clock cycle needed for a transfer from memory to peripheral
 - Two Master Clock cycles needed for a transfer from peripheral to memory
- Next Pointer management for reducing interrupt latency requirement

The Peripheral DMA Controller handles transfer requests from the channel according to the following priorities (Low to High priorities):

Table 7-4. Peripherical DMA Controller

Instance name	Channel T/R
PWM	Transmit
TWI1	Transmit
TWI0	Transmit
UART1	Transmit
UARTO	Transmit
USART1	Transmit
USART0	Transmit
PLC bridge	Transmit
SSC	Transmit



Table 7-5. Peripherical DMA Controller

Instance name	Channel T/R
PIOA	Receive
TWI1	Receive
TWI0	Receive
UART1	Receive
UARTO	Receive
USART1	Receive
USART0	Receive
PLC bridge	Receive
SSC	Receive

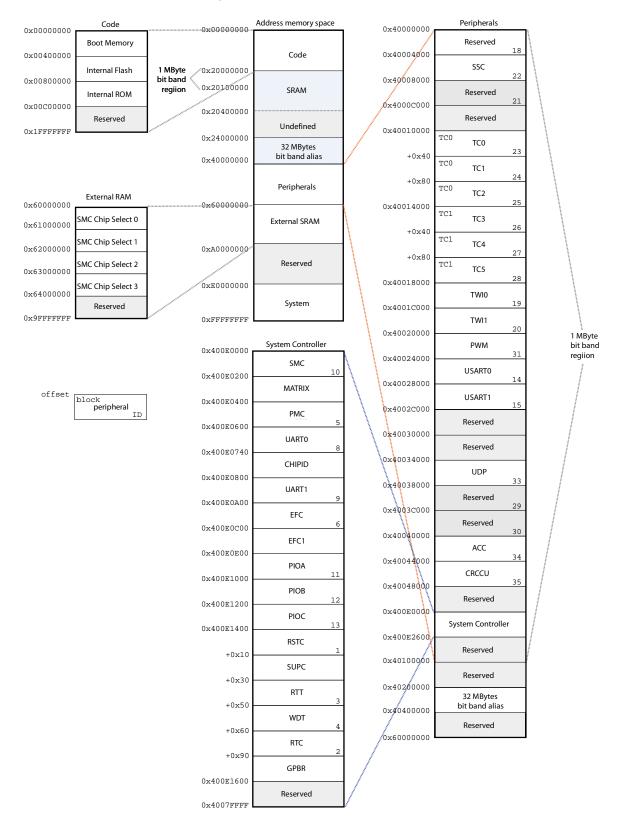
7.7 **Debug and Test Features**

- Debug access to all memory and registers in the system, including Cortex-M4 register bank when the core is running, halted, or held in reset.
- Serial Wire Debug Port (SW-DP) and Serial Wire JTAG Debug Port (SWJ-DP) debug access
- Flash Patch and Breakpoint (FPB) unit for implementing breakpoints and code patches
- Data Watchpoint and Trace (DWT) unit for implementing watch points, data tracing, and system profiling
- Instrumentation Trace Macrocell (ITM) for support of printf style debugging
- IEEE®1149.1 JTAG Boundary scan on All Digital Pins



8. SAM4SP32A Product Mapping

Figure 8-1. SAM4SP32A Product Mapping





9. Memories

9.1 Embedded Memories

9.1.1 Internal SRAM

The SAM4SP32A device embeds a total of 160-Kbytes high-speed SRAM.

The SRAM is accessible over System Cortex-M4 bus at address 0x2000 0000. The SRAM is in the bit band region. The bit band alias region is from 0x2200 0000 to 0x23FF FFFF.

9.1.2 Internal ROM

The SAM4SP32A embeds an Internal ROM, which contains the SAM Boot Assistant (SAM-BA®), In Application Programming routines (IAP) and Fast Flash Programming Interface (FFPI).

At any time, the ROM is mapped at address 0x0080 0000.

9.1.3 Embedded Flash

9.1.3.1 Flash Overview

Flash size is 2x1024 Kbytes.

The memory is organized in sectors. Each sector has a size of 64 KBytes. The first sector of 64 Kbytes is divided into 3 smaller sectors.

The three smaller sectors are organized to consist of 2 sectors of 8 KBytes and 1 sector of 48 KBytes. Refer to 41 below.

Figure 9-1. Global Flash Organization

Sector size	Sector name
8 KBytes	Small Sector 0
8 KBytes	Small Sector 1 Sector 0
48 KBytes	Larger Sector
64 KBytes	Sector 1
64 KBytes	Sector n



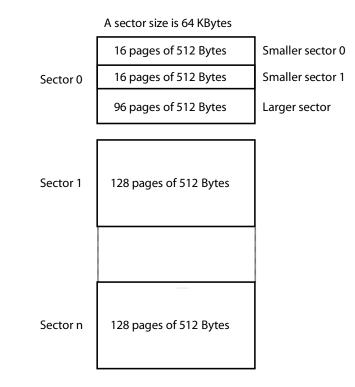
Each Sector is organized in pages of 512 Bytes. For sector 0:

- The smaller sector 0 has 16 pages of 512Bytes
- The smaller sector 1 has 16 pages of 512 Bytes
- The larger sector has 96 pages of 512 Bytes

From Sector 1 to n:

The rest of the array is composed of 64 KBytes sector of each 128 pages of 512bytes. Refer to Figure 9-2 below.

Figure 9-2. Flash Sector Organization



- SAM4SP32A: the Flash size is 2 x 1024 KBytes
 - Internal Flash0 address is 0x0040_0000
 - Internal Flash1 address is 0x0050_0000

Refer to Figure 9-3 below for the organization of the Flash following its size.



2 x 8kBytes 1 x 48kBytes 15 x 64kBytes

Flash 1 MBytes

Erasing the memory can be performed as follows:

on a 512-byte page inside a sector, of 8K Bytes (1)

Note: EWP and EWPL commands can be only used in 8 KBytes sectors.

- on a 4-Kbyte Block inside a sector of 8 KBytes/48 Kbytes/64 Kbytes
- on a sector of 8 KBytes/48 KBytes/64 KBytes
- on chip

The memory has one additional reprogrammable page that can be used as page signature by the user. It is accessible through specific modes, for erase, write and read operations. Erase pin assertion will not erase the User Signature page.

Erase memory by page is possible only in Sector of 8 Kbytes.

(1) EWP and EWPL commands can be only used in sector 8KBytes sectors.

9.1.3.2 Enhanced Embedded Flash Controller

The Enhanced Embedded Flash Controller (HEFC4) manages accesses performed by the masters of the system. It enables reading the Flash and writing the write buffer. It also contains a User Interface, mapped on the APB.

The Enhanced Embedded Flash Controller ensures the interface of the Flash block.

It manages the programming, erasing, locking and unlocking sequences of the Flash using a full set of commands.

One of the commands returns the embedded Flash descriptor definition that informs the sys-tem about the Flash organization, thus making the software generic.

9.1.3.3 Flash Speed

The user needs to set the number of wait states depending on the frequency used:

For more details, refer to the "AC Characteristics" sub-section of the product "Electrical Characteristics".



9.1.3.4 Lock Regions

Several lock bits are used to protect write and erase operations on lock regions. A lock region is composed of several consecutive pages, and each lock region has its associated lock bit.

Table 9-1.Lock bit number

Product	Product Number of lock bits	
SAM4SP32A	256 (128 + 128)	8 Kbytes

If a locked-region's erase or program command occurs, the command is aborted and the EEFC triggers an interrupt.

The lock bits are software programmable through the EEFC User Interface. The command "Set Lock Bit" enables the protection. The command "Clear Lock Bit" unlocks the lock region.

Asserting the ERASE pin clears the lock bits, thus unlocking the entire Flash.

9.1.3.5 Security Bit Feature

The SAM4SP32A features a security bit, based on a specific General Purpose NVM bit (GPNVM bit 0). When the security is enabled, any access to the Flash, SRAM, Core Registers and Internal Peripherals either through the ICE interface or through the Fast Flash Programming Interface, is forbidden. This ensures the confidentiality of the code programmed in the Flash.

This security bit can only be enabled, through the command "Set General Purpose NVM Bit 0" of the EEFC User Interface. Disabling the security bit can only be achieved by asserting the ERASE pin at 1, and after a full Flash erase is performed. When the security bit is deactivated, all accesses to the Flash, SRAM, Core registers, Internal Peripherals are permitted.

It is important to note that the assertion of the ERASE pin should always be longer than 200 ms.

As the ERASE pin integrates a permanent pull-down, it can be left unconnected during normal operation. However, it is safer to connect it directly to GND for the final application.

9.1.3.6 Calibration Bits

NVM bits are used to calibrate the brownout detector and the voltage regulator. These bits are factory configured and cannot be changed by the user. The ERASE pin has no effect on the calibration bits.

9.1.3.7 Unique Identifier

SAM4SP32A device integrates its own 128-bit unique identifier. These bits are factory configured and cannot be changed by the user. The ERASE pin has no effect on the unique identifier.

9.1.3.8 User Signature

Each part contains a User Signature of 512 bytes. It can be used by the user to store user information such as trimming, keys, etc., that the customer does not want to be erased by asserting the ERASE pin or by software ERASE command. Read, write and erase of this area are allowed.

9.1.3.9 Fast Flash Programming Interface

The Fast Flash Programming Interface allows programming the device through either a serial JTAG interface or through a multiplexed fully-handshaked parallel port. It allows gang programming with market-standard industrial programmers.

The FFPI supports read, page program, page erase, full erase, lock, unlock and protect commands.

The Fast Flash Programming Interface is enabled and the Fast Programming Mode is entered when TST and PA0 and PA1are tied low.



9.1.3.10 SAM-BA Boot

The SAM-BA Boot is a default Boot Program which provides an easy way to program in-situ the on-chip Flash memory.

The SAM-BA Boot Assistant supports serial communication via the UART and USB.

The SAM-BA Boot provides an interface with SAM-BA Graphic User Interface (GUI).

The SAM-BA Boot is in ROM and is mapped in Flash at address 0x0 when GPNVM bit 1 is set to 0.

9.1.3.11 GPNVM Bits

The GPNVM bits of the SAM4SP32A are only available on FLash0. There is no GPNVM bit on Flash1. The GPNVM0 is the security bit. The GPNVM1 is used to select the boot mode (boot always at 0x00) on ROM or FLASH. The SAM4SP32A embeds an additional GPNVM bit : GPNVM2. This GPNVM bit is used only to swap the Flash0 and Flash1. If GPNVM bit 2 is:

ENABLE: If the Flash1 is mapped at address 0x0040_0000 (Flash1 and Flash0 are continuous).

DISABLE: If the Flash0 is mapped at address 0x0040_0000 (Flash0 and Flash1 are continuous).

Table 9-2. General Purpose Non volatile Memory Bits

GPNVMBit[#]	t[#] Function			
0	Security bit			
1	Boot mode selection			
2	Flash selection (Flash 0 or Flash 1)			

9.1.4 Boot Strategies

The system always boots at address 0x0. To ensure maximum boot possibilities, the memory layout can be changed via GPNVM.

A general purpose NVM (GPNVM) bit is used to boot either on the ROM (default) or from the Flash.

The GPNVM bit can be cleared or set respectively through the commands "Clear General-purpose NVM Bit" and "Set General-purpose NVM Bit" of the EEFC User Interface.

Setting GPNVM Bit 1 selects the boot from the Flash, clearing it selects the boot from the ROM. Asserting ERASE clears the GPNVM Bit 1 and thus selects the boot from the ROM by default.

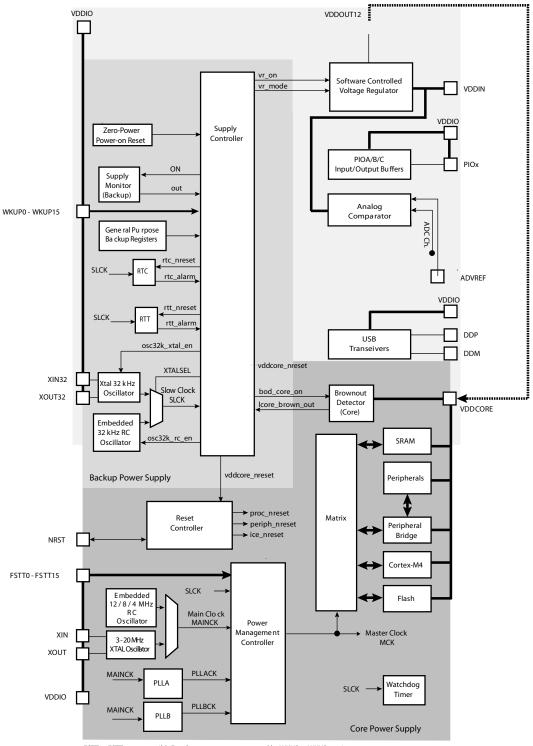
Setting the GPNVM Bit 2 selects bank 1, clearing it selects the boot from bank 0. Asserting ERASE clears the GPNVM Bit 2 and thus selects the boot from bank 0 by default.



10. System Controller

The System Controller is a set of peripherals, which allow handling of key elements of the system, such as power, resets, clocks, time, interrupts, watchdog, etc

Figure 10-1. System Controller Block Diagram



FSTT0 - FSTT15 are possibleFast Startup sources, generated by WKUP0 - WKUP15 pins, but are not physical pins.



10.1 System Controller and Peripherals Mapping

Please refer to SAM4SP32A Product Mapping.

All the peripherals are in the bit band region and are mapped in the bit band alias region.

10.2 Power-on-Reset, Brownout and Supply Monitor

The SAM4SP32A embeds three features to monitor, warn and/or reset the chip:

- Power-on-Reset on VDDIO
- Brownout Detector on VDDCORE
- Supply Monitor on VDDIO

10.2.1 Power-On-Reset

The Power-on-Reset monitors VDDIO. It is always activated and monitors voltage at start up but also during power down. If VDDIO goes below the threshold voltage, the entire chip is reset. For more information, refer to the Electrical Characteristics section of the datasheet.

10.2.2 Brownout Detector on VDDCORE

The Brownout Detector monitors VDDCORE. It is active by default. It can be deactivated by software through the Supply Controller (SUPC_MR). It is especially recommended to disable it during low-power modes such as wait or sleep modes.

If VDDCORE goes below the threshold voltage, the reset of the core is asserted. For more information, refer to the Supply Controller (SUPC) and Electrical Characteristics sections of the datasheet.

10.2.3 Supply Monitor on VDDIO

The Supply Monitor monitors VDDIO. It is not active by default. It can be activated by software and is fully programmable with 16 steps for the threshold (between 3.0 V to 3.6 V). It is controlled by the Supply Controller (SUPC). A sample mode is possible. It allows dividing the supply monitor power consumption by a factor of up to 2048. For more information, refer to the SUPC and Electrical Characteristics sections of the datasheet.

10.3 Reset Controller

The Reset Controller is based on a Power-on-Reset cell, and a Supply Monitor on VDDCORE. The Reset Controller is capable to return to the software the source of the last reset, either a general reset, a wake-up reset, a software reset, a user reset or a watchdog reset. The Reset Controller controls the internal resets of the system and the NRST pin input/output. It is capable to shape a reset signal for the external devices, simplifying to a minimum connection of a push-button on the NRST pin to implement a manual reset. The configuration of the Reset Controller is saved as supplied on VDDIO.

10.4 Supply Controller (SUPC)

The Supply Controller controls the power supplies of each section of the processor and the peripherals (via Voltage regulator control).

The Supply Controller has its own reset circuitry and is clocked by the 32 kHz Slow Clock generator.

The reset circuitry is based on a zero-power power-on reset cell and a brownout detector cell. The zero-power poweron reset allows the Supply Controller to start properly, while the soft-ware-programmable brownout detector allows detection of either a battery discharge or main voltage loss.



The Slow Clock generator is based on a 32 kHz crystal oscillator and an embedded 32 kHz RC oscillator. The Slow Clock defaults to the RC oscillator, but the software can enable the crystal oscillator and select it as the Slow Clock source.

The Supply Controller starts up the device by sequentially enabling the internal power switches and the Voltage Regulator, then it generates the proper reset signals to the core power supply.

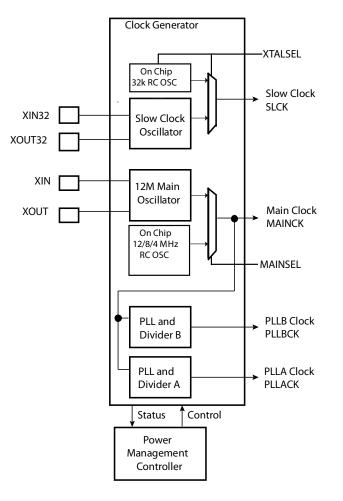
It also enables to set the system in different low-power modes and to wake it up from a wide range of events.

10.5 Clock Generator

The Clock Generator is made up of:

- One Low-power 32768Hz Slow Clock Oscillator with bypass mode
- One Low-power RC Oscillator
- One 3-20 MHz Crystal Oscillator, which can be bypassed
- One Fast RC Oscillator, factory programmed. Three output frequencies can be selected: 4, 8 or 12 MHz. By default 4 MHz is selected.
- One 80 to 240 MHz PLL (PLLB) providing a clock for the USB Full Speed Controller
- One 80 to 240 MHz programmable PLL (PLLA), provides the clock, MCK to the processor and peripherals. The PLLA input frequency is from 3 MHz to 32 MHz.

Figure 10-2. Clock Generator Block Diagram





10.6 Power Management Controller

The Power Management Controller provides all the clock signals to the system. It provides:

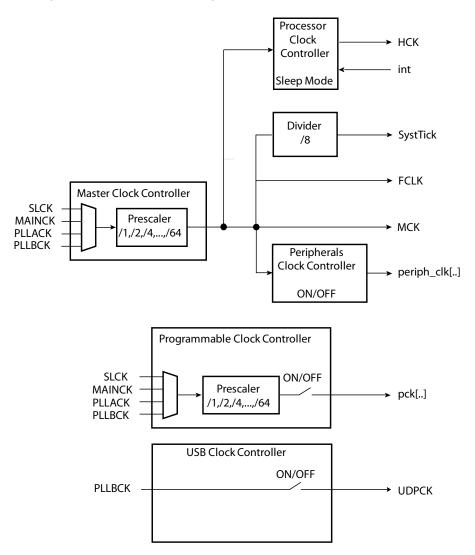
- the Processor Clock, HCLK
- the Free running processor clock, FCLK
- the Cortex SysTick external clock
- the Master Clock, MCK, in particular to the Matrix and the memory interfaces
- the USB Clock, UDPCK
- independent peripheral clocks, typically at the frequency of MCK
- three programmable clock outputs: PCK0, PCK1 and PCK2

The Supply Controller selects between the 32 kHz RC oscillator and the crystal oscillator. The unused oscillator is disabled automatically so that power consumption is optimized.

By default, at startup the chip runs out of the Master Clock using the fast RC oscillator running at 4 MHz.

The user can trim the 8 and 12 MHz RC Oscillator frequency by software.

Figure 10-3. Power Management Controller Block Diagram





The SysTick calibration value is fixed at 12500, which allows the generation of a time base of 1 ms with SysTick clock at 12.5 MHz (max HCLK/8 = 100 MHz/8 = 12500, so STCALIB = 0x30D4).

10.7 Watchdog Timer

- 16-bit key-protected only-once Programmable Counter
- Windowed, prevents the processor to be in a deadlock on the watchdog access

10.8 SysTick Timer

- 24-bit down counter
- Self-reload capability
- Flexible System timer

10.9 Real Time Timer

- Real-Time Timer, allowing backup of time with different accuracies
 - 32-bit Free-running backup Counter
 - Integrates a 16-bit programmable prescaler running on slow clock
 - Alarm Register capable to generate a wake-up of the system through the Shut Down Controller

10.10 Real Time Clock

- Low power consumption
- Full asynchronous design
- Two hundred year Gregorian and Persian calendar
- Programmable Periodic Interrupt
- Trimmable 32.7682 kHz crystal oscillator clock source
- Alarm and update parallel load
- Control of alarm and update Time/Calendar Data In
- Waveform output capability on GPIO pins in low power modes

10.11 General-Purpose Backup Registers

• Eight 32-bit backup general-purpose registers

10.12 Nested Vectored Interrupt Controller

- Thirty maskable external interrupts
- Sixteen priority levels
- Processor state automatically saved on interrupt entry, and restored on
- Dynamic reprioritizing of interrupts
- Priority grouping.
 - selection of pre-empting interrupt levels and non pre-empting interrupt levels.
- Support for tail-chaining and late arrival of interrupts.
 - back-to-back interrupt processing without the overhead of state saving and restoration between interrupts.
- Processor state automatically saved on interrupt entry, and restored on interrupt exit, with no instruction overhead.



10.13 Chip Identification

• Chip Identifier (CHIPID) registers permit recognition of the device and its revision.

Table 10-1. SAM4SP32A Chip ID's Register

Chip Name	Flash Size (KBytes)	RAM Size (KBytes)	Pin Count	CHIPID_CIDR	CHIPID_EXID		
SAM4SP32A	2*1024	160	128	0X29A7_0EE8	-		
JTAG ID: 05B3_203F							

10.14 **UART**

- Two-pin UART
 - Implemented features are 100% compatible with the standard Atmel USART
 - Independent receiver and transmitter with a common programmable Baud Rate Generator
 - Even, Odd, Mark or Space Parity Generation
 - Parity, Framing and Overrun Error Detection
 - Automatic Echo, Local Loopback and Remote Loopback Channel Modes
 - Support for two PDC channels with connection to receiver and transmitter

10.15 PIO Controllers

- 3 PIO Controllers, PIOA, PIOB and PIOC controlling a maximum of 37 I/O Lines
- Each PIO Controller controls up to 22 programmable I/O Lines
- Fully programmable through Set/Clear Registers

Table 10-2. PIO available on SAM4SP32A

Version	Pins
PIOA	22
PIOB	12
PIOC	3

- Multiplexing of four peripheral functions per I/O Line
- For each I/O Line (whether assigned to a peripheral or used as general purpose I/O)
 - Input change interrupt
 - Programmable Glitch filter
 - Programmable debouncing filter
 - Multi-drive option enables driving in open drain
 - Programmable pull-up on each I/O line
 - Pin data status register, supplies visibility of the level on the pin at any time
 - Additional interrupt modes on a programmable event: rising edge, falling edge, low level or high level
 - Lock of the configuration by the connected peripheral
- Synchronous output, provides set and clear of several I/O lines in a single write
- Write Protect Registers
- Programmable Schmitt trigger inputs
- Parallel capture mode



- Can be used to interface a CMOS digital image sensor, etc....
- One clock, 8-bit parallel data and two data enable on I/O lines
- Data can be sampled one time out of two (for chrominance sampling only)
- Supports connection of one Peripheral DMA Controller channel (PDC) which offers buffer reception without processor intervention





10.16 Peripheral Identifiers

Table 10-3 defines the Peripheral Identifiers of the SAM4SP32A. A peripheral identifier is required for the control of the peripheral interrupt with the Nested Vectored Interrupt Controller and control of the peripheral clock with the Power Management Controller.

			РМС		
Instance ID	Instance Name	NVIC Interrupt	Clock Control	Instance Description	
0	SUPC	Х		Supply Controller	
1	RSTC	Х		Reset Controller	
2	RTC	Х		Real Time Clock	
3	RTT	Х		Real Time Timer	
4	WDT	Х		Watchdog Timer	
5	PMC	Х		Power Management Controller	
6	EFC0	Х		Enhanced Embedded Flash Controller 0	
7	EFC1	Х		Enhanced Embedded Flash Controller 1	
8	UART0	Х	Х	UART 0	
9	UART1	Х	Х	UART 1	
10	SMC	Х	Х	Static Memory Controller	
11	PIOA	Х	Х	Parallel I/O Controller A	
12	PIOB	Х	Х	Parallel I/O Controller B	
13	PIOC	Х	Х	Parallel I/O Controller C	
14	USART0	Х	Х	USART 0	
15	USART1	Х	Х	USART 1	
16	-	-	-	Reserved	
17	-	-	-	Reserved	
18	-	Х	Х	Reserved	
19	TWI0	Х	Х	Two Wire Interface 0	
20	TWI1	Х	Х	Two Wire Interface 1	
21	-	-	-	Reserved	
22	SSC	Х	Х	Synchronous Serial Controller	
23	тсо	Х	Х	Timer/Counter 0	
24	TC1	Х	Х	Timer/Counter 1	
25	-	-	-	Reserved	
26	-	-	-	Reserved	
27	-	-	-	Reserved	
28	-	-	-	Reserved	
29	-			Reserved	
30	-			Reserved	
31	PWM	Х	Х	Pulse Width Modulation	
32	CRCCU	Х	Х	CRC Calculation Unit	
33	ACC	Х	Х	Analog Comparator	
34	UDP	Х	Х	USB Device Port	

Table 10-3. Peripherical Identifiers





10.17 Peripheral Signal Multiplexing on I/O Lines

The SAM4SP32A features 3 PIO controllers (PIOA, PIOB and PIOC), that multiplex the I/O lines of the peripheral set.

The SAM4SP32A controls up to 22 lines. Each line can be assigned to one of three peripheral functions: A, B or C. The multiplexing tables in the following paragraphs define how the I/O lines of the peripherals A, B and C are multiplexed on the PIO Controllers. The column "Comments" has been inserted in this table for the user's own comments; it may be used to track how pins are defined in an application.

Note that some peripheral functions which are output only, might be duplicated within the tables.

10.17.1 PIO Controller A Multiplexing

Table 10-4. Multiplexing on PIO Controller A (PIOA)

I/O	Peripherical A	Peripherical B	Peripherical C	Extra Function	System Function	Comment
Line	. enpirenear	r enprioriour B	r enprientear e		eyetem raneaen	connent
PAO	PWMH0	TIOA0	A17	WKUP0		
PA1	PWMH1	TIOB0	A18	WKUP1		
PA2	PWMH2	SCK0	DATRG	WKUP2		
PA3	TWD0	NPCS3				
PA4	ТWСК0	TCLK0		WKUP3		
PA5	RXD0	NPCS3		WKUP4		
PA6	TXD0	РСКО				
PA7	RTS0	PWMH3			XIN32	
PA8	CTS0	ADTRG		WKUP5	XOUT32	
PA9	URXD0	NPCS1	PWMFI0	WKUP6		
PA10	UTXD0	NPCS2				
PA15	TF	TIOA1	PWML3	WKUP14/PIODCEN1		
PA16	тк	TIOB1	PWML2	WKUP15/PIODCEN2		
PA17	TD	PCK1	PWMH3	AC0		
PA18	RD	PCK2	A14	AC1		
PA19	RK	PWML0	A15	AC2/WKUP9		
PA20	RF	PWML1	A16	AC3/WKUP10		
PA21	RXD1	PCK1				
PA22	TXD1	NPCS3	NCS2			
PA23	SCK1	PWMH0	A19	PIODCCLK		
PA24	RTS1	PWMH1	A20	PIODCO		
PA25	CTS1	PWMH2	A23	PIODC1		



10.17.2 PIO Controller B Multiplexing

I/O Line	Peripherical A	Peripherical B	Peripherical C	Extra Function	System Function	Comment
PBO	PWMH0			AC4/RTCOUT0		
PB1	PWMH1			AC5/RTCOUT1		
PB2	URXD1	NPCS2		AC6/WKUP12		
PB3	UTXD1	PCK2		AC7		
PB4	TWD1	PWMH2			TDI	
PB5	TWCK1	PWML0		WKUP13	TDO/TRACESWO	
PB6					TMS/SWDIO	
PB7					TCK/SWCLK	
PB8					XOUT	
PB9					XIN	
PB10					DMM	
PB11					DPP	
PB12	PWML1				ERASE	

Table 10-5. Multiplexing on PIO Controller B (PIOB)

10.17.3 PIO Controller C Multiplexing

Table 10-6. Multiplexing on PIO Controller C (PIOC)

Ι/Ο	Doriphorical A	Doriphorical P	Dorinharical C	Extra Eurotion	System Function	Commont
Line	Peripherical A	Репрпенса в	Peripriencal C		System Function	Comment
PCO	D0	PWML0				
PC5	D5					
PC26	A8	TIOA4				



11. Embedded Peripherals Overview

11.1 Two Wire Interface (TWI)

- Master, Multi-Master and Slave Mode Operation
- Compatibility with Atmel two-wire interface, serial memory and I2C compatible devices
- One, two or three bytes for slave address
- Sequential read/write operations
- Bit Rate: Up to 400 kbit/s
- General Call Supported in Slave Mode
- Connecting to PDC channel capabilities optimizes data transfers in Master Mode only
 - One channel for the receiver, one channel for the transmitter
 - Next buffer support

11.2 Universal Asynchronous Receiver Transceiver (UART)

- Two-pin UART
 - Independent receiver and transmitter with a common programmable Baud Rate Generator
 - Even, Odd, Mark or Space Parity Generation
 - Parity, Framing and Overrun Error Detection
 - Automatic Echo, Local Loopback and Remote Loopback Channel Modes
 - Support for two PDC channels with connection to receiver and transmitter

11.3 USART

- Programmable Baud Rate Generator
- 5- to 9-bit full-duplex synchronous or asynchronous serial communications
 - 1, 1.5 or 2 stop bits in Asynchronous Mode or 1 or 2 stop bits in Synchronous Mode
 - Parity generation and error detection
 - Framing error detection, overrun error detection
 - MSB- or LSB-first
 - Optional break generation and detection
 - By 8 or by-16 over-sampling receiver frequency
 - Hardware handshaking RTS-CTS
 - Receiver time-out and transmitter timeguard
 - Optional Multi-drop Mode with address generation and detection
 - Optional Manchester Encoding
 - Full modem line support on USART1 (DCD-DSR-DTR-RI)
- RS485 with driver control signal
- ISO7816, T = 0 or T = 1 Protocols for interfacing with smart cards
 - NACK handling, error counter with repetition and iteration limit
- SPI Mode
 - Master or Slave
 - Serial Clock programmable Phase and Polarity
 - SPI Serial Clock (SCK) Frequency up to MCK/4
- IrDA modulation and demodulation



- Communication at up to 115.2 Kbps
- Test Modes
 - Remote Loopback, Local Loopback, Automatic Echo

11.4 Synchronous Serial Controller (SSC)

- Provides serial synchronous communication links used in audio and telecom applications (with CODECs in Master or Slave Modes, I₂S, TDM Buses, Magnetic Card Reader)
- Contains an independent receiver and transmitter and a common clock divider
- Offers configurable frame sync and data length
- Receiver and transmitter can be programmed to start automatically or on detection of different event on the frame sync signal
- Receiver and transmitter include a data signal, a clock signal and a frame synchronization signal

11.5 Timer Counter (TC)

- Two 16-bit Timer Counter Channels
- Wide range of functions including:
 - Frequency Measurement
 - Event Counting
 - Interval Measurement
 - Pulse Generation
 - Delay Timing
 - Pulse Width Modulation
 - Up/down Capabilities
- Each channel is user-configurable and contains:
 - One external clock input
 - Five internal clock inputs
 - Two multi-purpose input/output signals
- Two global registers that act on all three TC Channels
- Quadrature decoder
 - Advanced line filtering
 - Position / revolution / speed
- 2-bit Gray Up/Down Counter for Stepper Motor

11.6 Pulse Width Modulation Controller (PWM)

- One Four-channel 16-bit PWM Controller, 16-bit counter per channel
- Common clock generator, providing Thirteen Different Clocks
 - A Modulo n counter providing eleven clocks
 - Two independent Linear Dividers working on modulo n counter outputs
 - High Frequency Asynchronous clocking mode
- Independent channel programming
 - Independent Enable Disable Commands
 - Independent Clock Selection
 - Independent Period and Duty Cycle, with Double Buffering
 - Programmable selection of the output waveform polarity



- Programmable center or left aligned output waveform
- Independent Output Override for each channel
- Independent complementary Outputs with 12-bit dead time generator for each channel
- Independent Enable Disable Commands
- Independent Clock Selection
- Independent Period and Duty Cycle, with Double Buffering
- Synchronous Channel mode
 - Synchronous Channels share the same counter
 - Mode to update the synchronous channels registers after a programmable number of periods
- Connection to one PDC channel
 - Provides Buffer transfer without processor intervention, to update duty cycle of synchronous channels
- One programmable Fault Input providing an asynchronous protection of outputs
- Stepper motor control (2 Channels)

11.7 USB Device Port (UDP)

- USB V2.0 full-speed compliant, 12 Mbits per second.
- Embedded USB V2.0 full-speed transceiver
- Embedded 2688-byte dual-port RAM for endpoints
- Eight endpoints
 - Endpoint 0: 64bytes
 - Endpoint 1 and 2: 64 bytes ping-pong
 - Endpoint 3: 64 bytes
 - Endpoint 4 and 5: 512 bytes ping-pong
 - Endpoint 6 and 7: 64 bytes ping-pong
 - Ping-pong Mode (two memory banks) for Isochronous and bulk endpoints
- Suspend/resume logic
- Integrated Pull-up on DDP
- Pull-down resistor on DDM and DDP when disabled

11.8 Analog Comparator

- One analog comparator
- High speed option vs. low-power option
 - 170 µA/xx ns active current consumption/propagation delay
 - 20 µA/xx ns active current consumption/propagation delay
- Selectable input hysteresis
 - 0, 15 mV, 30mV (Typ)
- Minus input selection:
 - Temperature Sensor
 - ADVREF
 - Plus input selection:
 - All analog inputs
- output selection:
 - Internal signal



- external pin
- selectable inverter
- window function
- Interrupt on:
 - Rising edge, Falling edge, toggle
 - Signal above/below window, signal inside/outside window

11.9 Cyclic Redundancy Check Calculation Unit (CRCCU)

- 32-bit cyclic redundancy check automatic calculation
- CRC calculation between two addresses of the memory

11.10 PLC Brigde

• Six I/O lines to connect to PRIME PLC Transceiver for external configurations





12. PRIME PLC Transceiver

The SAM4SP32A MCU embeds a Certified PRIME Power line communication transceiver with a featured Class D power amplifier and a set of hardware accelerators blocks to execute the heavy tasks of the PRIME protocol without the interruption of the Cortex-M4 CPU.

The PRIME PLC Transceiver peripheral integrates:

- Power Line Carrier Modem for 50 and 60 Hz mains
- 97-carrier OFDM PRIME compliant
- Baud rate Selectable: 21400 to 128600 bps
- Differential BPSK, QPSK, 8-PSK modulations
- Automatic Gain Control and signal amplitude tracking
- Embedded on-chip DMAs
- Media Access Control
- Viterbi decoding and CRC PRIME compliant
- 128-bit AES encryption
- Channel sensing and collision pre-detection

12.1 SAM4SP32A PRIME PHY Layer

12.1.1 SAM4SP32A PHY Layer

The physical layer of SAM4SP32A consists of a hardware implementation of the PRIME Physical Layer Entity, which is an Orthogonal Frequency Division Multiplexing (OFDM) system in the CENELEC A-band. This PHY layer transmits and receives MPDUs (MAC Protocol Data Unit) between neighbor nodes.

From the transmission point of view, the PHY layer receives its inputs from the MAC (Medium Access Control) layer, via DMA. At the end of transmission branch, data is output to the physical channel.

On the reception side, the PHY layer receives its inputs from the physical channel, and at the end of reception branch, the data flows to the MAC layer, via DMA.

A PHY layer block diagram is shown below:

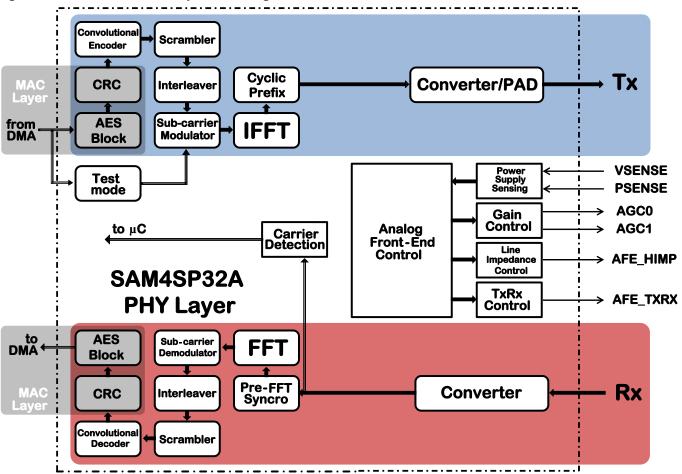


Figure 12-1. SAM4SP32A PHY Layer Block Diagram

The diagram can be divided in four sub-blocks: Transmission branch, Emission branch, Analog Front End control and Carrier Detection.

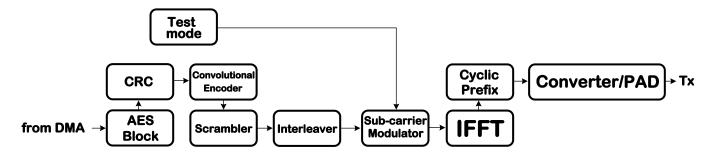


12.1.1.2 Transmission and Reception branches

Phy layer takes data to be sent from dedicated DMA channel (PHY_TX). 128-bit AES encryption is done "on the fly", and the Clyclic Redundancy Check (CRC) fields are hardware-generated in real time. These CRCs are properly appended to the transmission data. The rest of the chain is hardware-wired, and performs automatically all the tasks needed to send data according to PRIME specifications.

In Figure 12-2, the block diagram of the transmission brach Is shown.

Figure 12-2. Transmission branch



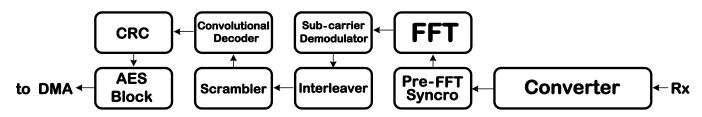
The output is differentially modulated using a BPSK/DQPSK/D8PSK scheme. After modulation, IFFT (Inverse Fourier Transform) block and cyclic prefix block allows to implement an OFDM scheme.

A Converter and a Power Amplifier Driver is the last block in the transmission branch. This block is responsible for adjusting the signal to reach the best transmission efficiency, thus reducing consumption and power dissipation.

Test mode: When selected, test mode injects data directly to Sub-carrier modulation block. When in test mode, data can be injected continuously to the line using only a set of selected frequencies, in order to test channel behavior.

The reception branch performs automatically all the tasks needed to process received data. Phy layer delivers data to MAC layer through the dedicated DMA channel (PHY_RX).

Figure 12-3. Reception branch



12.1.1.3 Carrier Detection

Looking for an easy detection of incoming messages, PRIME specification defines a chirp signal located at the beginning of the PRIME frames devised to ease synchronization in the receptor. By means of detection techniques, the receiver can know accurately when the chirp has been completely received and then the correct instant when the frame begins.

Before starting a transmission, it is also necessary to use carrier detection in order to check if another device is already emitting, thus avoiding collisions. If any device is emitting, the carrier detection triggers a microcontroller interruption and sets an internal flag, thus the transmission will be stopped.

The main drawback of this process is that chirp signal length (2.4 milliseconds) is not short enough to guarantee very low collision ratio.



To improve this drawback, the OFDM PLC Modem implements two different algorithms to detect the carrier as soon as possible, aiming to reduce collisions and improving the medium access behavior. By these early detection techniques, the system achieves low collision ratio, and the communication throughput increases significantly.

12.1.1.4 Analog Front End control

The Phy layer controls the Analog Front End by means of four sub-blocks:

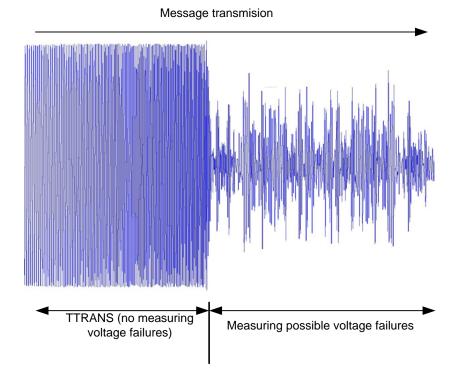
- Power Supply sensing
- Gain control
- Line Impedance control
- TxRx control

12.1.1.5 Power Supply Sensing: VSENSE and PSENSE

The power supply is continuously monitored to avoid power supply failures that could damage the supply device. This block senses the power channel using two different inputs:

VSENSE: VSENSE detects whether voltage falls below 3.3v during a number of cycles while a
message is being transmitted. This measurement is done after a transitory guard time (TTRANS in
figure below). If a Voltage failure occurs, the transmission is shut down and sending messages again
will be not possible if an internal flag (VFAILURE) is not previously cleared.

Figure 12-4. Transitory guard time in message transmission



PSENSE: PSENSE measures the power source current consumption, shutting down the transmission if the consumption exceeds a defined threshold (stored in MAXPOT phy layer registers, see 12.1.5.34). This measurement is done after a transitory guard time. As the current measurement varies over time, an averaging is done taking into account an average parameter (Alpha), a configurable number of cycles (NUMCYCLES, see 12.1.5.35) and a configurable length of each cycle (A_NUMMILIS, see 12.1.5.36).



If a power failure occurs, the transmission is shut down and sending messages again will be not possible if an internal flag (PFAILURE, see 12.1.5.22) is not previously cleared.

The system considers that a power failure has occurs when the value read from MEAN registers (see 12.1.5.30) is above the user-definable value stored in MAXPOT registers.

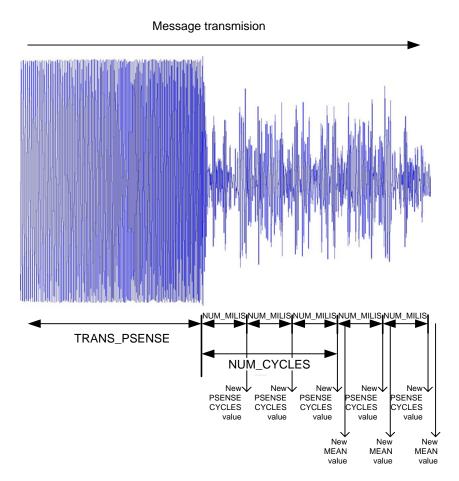


Figure 12-5. PSENSE parameters

Psense and Vsense configurations parameters are automatically set by the Phy layer.

See related peripheral registers for more information about Psense and Vsense.

12.1.1.6 Gain Control

This block implements two Automatic Gain Control outputs to adjust the received signal level to a suitable range. Both of them are set to '1' when the received signal is above two system thresholds in order to activate external attenuators placed in the external analog front end.

The value of these outputs is set during the beginning of a received message and is hold until the end of the message.

AGC0 and AGC1 follow different algorithms, thus using both of them ensures a more accurate gain control.

See AGC_CONFIG register in for information about AGC configuration.

12.1.1.7 Line Impedance Control

This block modifies the configuration of the Analog Front End by means of AFE-HIMP output. When working with a suitable external configuration, the system can change the filter conditions in order to adjust its behavior to the line impedance values. See last SAM4SP32A reference design for further information about Line Impedance topologies.



12.1.1.8 TxRx Control

This block modifies the configuration of the Analog Front End by means of AFE-TXRX output. Thus is possible to change filter conditions between transmission/reception.

See reference design for further information about TxRx control.

12.1.2 PHY parameters

As described below, the PHY layer is specified by certain main parameters, which are fixed for each specific constellation/coding combination. These parameters have to be identical in a network in order to achieve compatibility.

Table 12-1. PRIME Phy main parameters

PRIME Phy parameter	Value
Base Band Clock (Hz)	250000
Subcarrier spacing (Hz)	488,28125
Number of data subcarriers	84 (header), 96 (payload)
Number of pilot subcarriers	13 (header), 1 (payload)
FFT interval (samples)	512
FFT interval (μs)	2048
Cyclic Prefix (samples)	48
Cyclic Prefix (μs)	192
Symbol interval (samples)	560
Symbol interval (µs)	2240
Preamble period (µs)	2048

Table 12-2 shows the PHY data rate during payload transmission, and maximum MSDU length for various modulation and coding combinations

Table 12-2. Phy parameters depending on the modulation

	DBI	PSK	DQI	PSK	D8PSK	
Convolutional Code (1/2)	On	Off	On	Off	On	Off
Information bits per subcarrier	0,5	1	1	2	1,5	3
Information bits per OFDM symbol	48	96	96	192	144	288
Raw data rate (kbps approx)	21,4	42,9	42,9	85,7	64,3	128,6
MAX MSDU length with 63 symbols (bits)	3016	6048	6040	12096	9064	18144



Table 12-3 shows the modulation and coding scheme and the size of the header portion of the PHY frame

Table 12-3. Header parameters

	DBPSK
Convolutional Code (1/2)	On
Information bits per subcarrier	0,5
Information bits per OFDM symbol	42

All the parameters of the physical layer such as the base band clock, subcarrier spacing, number of subcarriers...; are defined in PRIME Specification, and have to be identical in a network in order to achieve compatibility.

12.1.3 PHY Protocal Data Unit (PPDU) Format

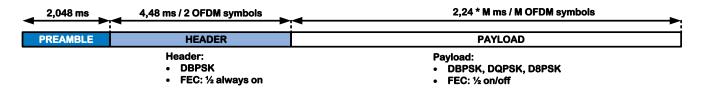
Figure 12-6 shows how OFDM symbols are transmitted in a PPDU (Physical layer Protocol Data Unit). The preamble is used at the beginning of every PPDU for synchronization purposes.

Figure 12-6. PHY layer transmitter block diagram



Phy layer adaptively modifies attenuation values applied to the whole signal. Also, additional attenuations are applied to the chirp section of the signal (preamble) and to the rest of the signal itself (header+payload), to smoothly adapt amplitude values and transitions.

Figure 12-7. PPDU OFDM symbols and duration



12.1.4 PHY Service Specification

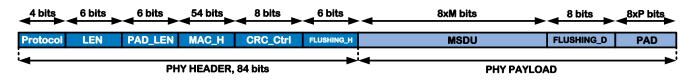
There is an interface specified in PRIME for the PHY layer, with several primitives relative to both data and control planes.

PHY layer has a single 20-bit free-running clock measured in 10μ s steps. Time measured by this clock is the one to be used in some PHY primitives to indicate a specific instant in time.

SAM4SP32A includes a hardware implementation of this clock, which consists of a 20-bit register. This register is read-only and it can be accessed as a 32-bit variable by the ADD8051C3A microcontroller.



Figure 12-8. Header and payload structure



Prime specifies a complete set of primitives to manage the PHY Layer, and the PHY-SAP (PHY Service Access Point) from MAC layer. Atmel PRIME stack integrates all this functions, making them transparent to the final user and simplifying the management.



12.1.5 PHY Layer registers

Relative addresses in the PLC modem intenrnal memory map given.

12.1.5.1 PHY_SFR Register

	Register							
Name	Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	B it 0
PHY_SFR	BCH_ERR	CD	UMD			TXRX		INT_PHY
ame:	PHY_SFR							
ddress:	0xFE2A							
ccess:	Read/write							
eset:	0x87							
٠	:	Reserved b	pit					
٠	BCH_ERR:	Busy Chan	nel Error Fla	ag.				
				by hardware therwise, thi		•	ence of an	OFDM signa
			used for retu E specification	-	ult of "Busy	Channel" in	the PHY_D	ATA.confirm
٠	CD:	Carrier Det	ect bit.					
		This bit is s whole rece	•	nardware wh	en an OFDN	/I signal is de	etected, and	it is active du
		This bit is u	ised in chan	nel access (CSMA-CA a	lgorithm) for	performing	channel-sens
•	UMD:	Unsupporte	ed Modulatio	on Scheme	flag.			
		-	•		•			C is received, ot supported
٠	TXRX:	Transmissi	on order.					
		at TX_TIM	E register a	-	emission le	evel is spec	ified at AT	the Time valu
		If this bit i returns '1'.	s read, only	y returns '0'	when phys	sical transm	ission has	started. Othe
		The transm	ission will b	egin when T	IMER_BEAG	CON_REF is	s equal to T>	K_TIME.

• **INT_PHY:** Physical Layer interruption

This bit is internally connected to the external microcontroller interrupt /EXT_INT.

It is low-level active. It is set to '0' by physical layer and is cleared by writing '1' in the bit PHY_SFR(0).



12.1.5.2 SYS_CONFIG Register

_								
Name	Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	B it 0
SYS_CON	FIG			CONV_PD	PHY_PD	PHY_ERR_EN	PHY_ERR	PHY_RST
Name:	SYS_CON	FIG						
Address:	0xFE2C							
Access:	Read/write							
Reset:	0x04							
		Reserved bits						
•	CONV PD:	: Converter Pov						
						ternal converter er down mode, t	•	•
		This bit is high	-level active					
٠	PHY_PD:	PHY Power D	own					
		blocks involve	ed in comm	unication rer	nain inactiv	PHY power dow e. Thus, the system pected to ensure	stem will be	unable to
		Setting Pl	HY power do	wn mode				
		1-Set I	Physical Lay	er reset (SYS	_CONFIG(0)),	,	
		2-Set 0	CONV_PD a	nd PHY_PD i	fields			
		Exiting Pl	HY power do	wn mode				
		1-Clea	r CONV_PD	and PHY_PL) fields			
		2-Clea	r Physical La	ayer reset (S)	/S_CONFIG	(0)), PHY_RST=	<i>'</i> 0'	

This bit is high-level active.

• PHY_ERR_EN: Physical Layer Watchdog enable

This bit enables or disables Physical layer watchdog. Physical layer watchdog is enabled by default.

This bit is high-level active.

• **PHY_EN:** Physical Layer Error Flag

This flag indicates if a Physical layer error has occurred. Physical layer watchdog has a 200milliseconds sampling period. When Physical layer detects an error, it activates the Physical layer interrupt and this flag is set.

To restore situation, microcontroller must reset Physical layer by means of PHY_RST bit (SYS_CONFIG(0)).

• PHY_RST: Physical Layer Reset

This bit resets the Physical layer. To perform a Physical layer reset cycle, microcontroller must set this bit to '1' and then must clear it to '0'.



12.1.5.3 PHY_CONFIG Register

Name	e Bit Bit 7 6					Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	B it 0
PHY_CON	FIG	-	-	CINR_MODE	PAD_LEN_AC	AES_EN	CD_MOD1_EN	CD_MOD2_DET	MAC_EN		
Name:	PH	Y_CO	NFIG								
Address:	0xF	0xFE68									
Access:	Rea	ad/writ	e								
Reset:	0x1	F									

- --: Reserved bits
- **CINR_MODE**:Carrier to Interference + Noise Ratio mode
 - This bit enables/disables CINR mode when set to '1'.
 - '0': CINR mode disabled.
 - '1': CINR mode enabled.
- PAD_LEN_AC: This field allows the system to work with two different representations of the Phy header PAD_LEN field (PAD_LEN represented before coding or PAD_LEN represented after coding).
 - '0': PAD_LEN field in PHY header is represented before coding. This is the suitable value to fulfill PRIME specification.
 - '1': PAD_LEN field in PHY header is represented after coding.
- **AES_EN:** This field enables/disables "on the fly" AES encryption and decryption by hardware.
 - '0': "on the fly" AES encryption/decryption disabled.
 - '1': "on the fly" AES encryption/decryption enabled.
- CD_MOD1_EN: This field enables/disables Carrier Detection mode 1.
 - '0': Carrier Detection mode 1 disabled.
 - '1': Carrier Detection mode 1 enabled.
- CD_MOD2_DET: This field enables/disables Carrier Detection mode 2.
 - '0': Carrier Detection mode 2 disabled.
 - '1': Carrier Detection mode 2 enabled.
- MAC_EN: This field enables/disables CRC processing by hardware.
 - '0': CRC processing disabled.
 - '1': CRC processing enabled.



12.1.5.4 ATTENUATION Register

Name	Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	B it 0		
ATTENUA	TENUATION ATTENUATION(7:0)									
Name:	ATTENUATION									
Address:	0xFE24	0xFE24								
Access:	Read/write									
Reset:	0xFF									
•	ATTENUATION:	Global	attenuation	for the trans	mitted signal	(chirp+signal).	The 16-bit s	signal level		

ON: Global attenuation for the transmitted signal (chirp+signal). The 16-bit signal level is multiplied by this 8-bit value and the result is truncated to 16 bits. Attenuation value = 0xFF → the transmitted signal amplitude is not attenuated. Attenuation value = 0x00 → the transmitted signal amplitude is nullified.



12.1.5.5 ATT_CHIRP Register

Name	Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	B it 0
ATT_CHIR	P			ATT_C	CHIRP(7:0)			
Name:	ATT_CHIRP							
Address:	0xFE9B							
Access:	Read/write							
Reset:	0xFF							
•	ATT_CHIRP:	This re	gister stores	the attenuat	tion value for	the chirp. The	16-bit chirp	data is

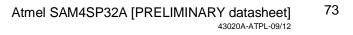
RP: I his register stores the attenuation value for the chirp. The 16-bit chirp data is multiplied with this 8-bit value and the 24-bit result is truncated to 16 bits. Attenuation value = $0xFF \rightarrow$ the chirp amplitude is not attenuated Attenuation value = $0x00 \rightarrow$ the chirp amplitude is nullified



12.1.5.6 ATT_SIGNAL Register

	-							
Name	e Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	B it 0
ATT_SIGN	IAL							
Name:	ATT_SIGNAL							
Address:	0xFE9C							
Access:	Read/write							
Reset:	0xFF							
٠	ATT_SIGNAL:		•			he signal with bit value and th	•	

truncated to 16 bits. Attenuation value = $0xFF \rightarrow$ the signal amplitude is not attenuated Attenuation value = $0x00 \rightarrow$ the signal amplitude is nullified





12.1.5.7 TX_TIME Registers

TX_TIME TX_TIME(19:12) TX_TIME(11:4) TX_TIME(11:4)	@0xFE26
TX_TIME(11:4)	
	@0xFE27
TX_TIME(3:0) "0000"	@0xFE28
"0000000"	@0xFE29

Name: TX_TIME

Address: 0xFE26 - 0xFE29

Access: Read/write

Reset: 0x00, ..., 0x00;

• **TX_TIME:** This 20-bit value sets the time instant when the MPDU (MAC Protocol Data Unit) has to be transmitted. The time is expressed in 10μs steps.

When writing a new value to TX_TIME register, a specific writing order must be taken, always from the most significant byte (TX_TIME(19:12) at address 0xFE26) to the least significant byte (TX_TIME(3:0) at address 0xFE28), and it is required to write the 3 bytes to avoid wrong time comparisons in transmission.

The 20-bit TX_TIME value is managed by the microcontroller as a 4-byte variable. The TX_TIME value is aligned to the 20 most significant bits, being the 12 least significant bits padded with zeros.

This register is used by the physical layer for being in accordance with PRIME specifications about transmission time (see PRIME spec.)

Note: TXRX bit (PHY_SFR(2)) has to be cleared to '0' in order to init transmission. Once this bit has been cleared, the transmission will start when TIMER_BEACON_REF value is equal to TX_TIME.



12.1.5.8 TIMER_FRAME Registers

Name	Bit 7 Bit 6 Bit 5 Bit 4 Bit 3 Bit 2 Bit 1 B it 0										
TIMER_FRAME	TIMER_FRAME(19:12)	@0xFE2D									
	TIMER_FRAME(11:4)	@0xFE2E									
	TIMER_FRAME(3:0)										
	"0000000"										

Name: TIMER_FRAME

Address: 0xFE2D - 0xFE30

Access: Read only

Reset: 0x00, ..., 0x00;

• **TIMER FRAME:** Time of receipt of the preamble associated with the PSDU (PHY Service Data Unit). It is expressed in 10µs steps and is taken from the physical layer timer TIMER_BEACON_REF.

It is set by hardware and is a read-only register.

This register is used by the physical layer for being in accordance with PRIME specification about reception time (see PRIME specification).

The 20-bit TIMER_FRAME value is managed by the microcontroller as a 4-byte variable. The TIMER_FRAME value is aligned to the 20 most significant bits, being the 12 least significant bits padded with zeros. This simplifies arithmetic calculations with time values.



12.1.5.9 TIMER_BEACON_REF Registers

Name	Bit 7 Bit 6 Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	B it 0				
TIMER_BEACON_REF	TIMER	_BEACON	I_REF(19:	:12)			@0xFE47			
	TIMER	BEACON	N_REF (11	1:4)			@0xFE48			
	TIMER_BEACON_REF (3:0) "0000"									
	"0000000"									

Name: TIMER_BEACON_REF

Address: 0xFE47 - 0xFE4A

Access: Read only

Reset: 0x00, ..., 0x00;

• **TIMER_BEACON_REF:** Timer for the physical layer, which consists of a single 20-bit free-running clock measured in 10µs steps.

It indefinitely increases a unit each 10 microseconds from 0 to 1048575, overflowing back to 0.

It is set by hardware and is a read-only register.

This register is used by the physical layer for being in accordance with PRIME specification. It is reserved 32-bit in data memory to be able to declare as 32-bit variable. The 20-bit register MSB is aligned to the 32-bit variable MSB, in order to simplify arithmetic calculations with time values.

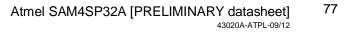


12.1.5.10 RX_LEVEL Registers

N	ame	Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	B it 0	
RX_	LEVEL				RX_LE	/EL(15:8)				@0xFE31
		RX_LEVEL(7:0)								@0xFE32
Name:	TABLE_ELE	TABLE_ELEMENT_INIT								
Address:	0xFE31 – 0xFE32									
Access:	Read only									
Reset:	0x00; 0x00									

• **RX_LEVEL**:These registers store the autocorrelation level of the chirp signal.

When the reception process has started, these registers are set by hardware.





12.1.5.11 RSSI_MIN Register

N	ame	Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	B it 0	
RSS	SI_MIN	RSSI_MIN(7:0)								
Name:	RSSI_MIN									
Address:	0xFE33									
Access:	Read only									
Reset:	0xFF									

• **RSSI_MIN:** Received Signal Strength Indication Min

This register stores the minimum RSSI value measured in the last message received. The measurement is done at symbol level. The value is stored in ¼dB steps

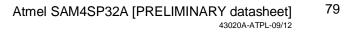


12.1.5.12 RSSI_AVG Register

N	ame	Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	B it 0	
RSS	SI_AVG				RSSI_A	AVG(7:0)				
Name:	RSSI_AVG	AVG								
Address:	0xFE34									
Access:	Read only									
Reset:	0x00									

• **RSSI_AVG:** Received Signal Strength Indication Average

This register stores the average RSSI value measured in the last message received. The measurement is done at symbol level. The value is stored in ¼dB steps





12.1.5.13 RSSI_MAX Register

N	ame	Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	B it 0
RSS	SI_MAX				RSSI_N	/IAX(7:0)			
Name:	RSSI_MAX								
Address:	0xFE35								
Access:	Read only								
Reset:	0x00								

• **RSSI_MAX:** Received Signal Strength Indication Max

This register stores the maximum RSSI value measured in the last message received. The measurement is done at symbol level. The value is stored in ¼dB steps



12.1.5.14 CINR_MIN Register

N	Name		Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	B it 0	
CIN	R_MIN				CINR_I	MIN(7:0)				
Name:	CINR_MIN									
Address:	0xFE38									
Access:	Read only									
Reset:	0xFF									

• CINR_MIN: Carrier to Interference + Noise ratio Min

This register stores the minimum CINR value measured in the last message received.

In order to calculate CINR properly, the algorithm takes beacon-type messages as a reference, since this message type allows knowing its content beforehand.

The system uses a table that must be loaded with the beacon data to be received, so CINR mode must be activated (see PHY_CONFIG register) and the same procedure used to send beacons must be followed. As CINR mode is activated, physical layer will load the message in the table instead of sending it (table load time is in the order of microseconds, and is much shorter than the one used to send the message).

Once the table is loaded, CINR must be disabled, and next messages CINR will be calculated taken the beacon loaded in the table as reference.

The measurement is done at symbol level.

The value is stored in ¼dB steps.



12.1.5.15 CINR_AVG Register

N	ame	Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	B it 0		
CIN	R_AVG				CINR_/	AVG(7:0)					
Name:	CINR_AVG	i									
Address:	0xFE39										
Access:	Read only										
Reset:	0x00										

• CINR_AVG:Carrier to Interference + Noise ratio Average

This register stores the average CINR measured in the last message received.

In order to calculate CINR properly, the algorithm takes beacon-type messages as a reference, since this message type allows knowing its content beforehand.

The system uses a table that must be loaded with the beacon data to be received, so CINR mode must be activated (see PHY_CONFIG register) and the same procedure used to send beacons must be followed. As CINR mode is activated, physical layer will load the message in the table instead of sending it (table load time is in the order of microseconds, and is much shorter than the one used to send the message).

Once the table is loaded, CINR must be disabled, and next messages CINR will be calculated taken the beacon loaded in the table as reference

The measurement is done at symbol level.

The value is stored in ¼dB steps.



12.1.5.16 CINR_MAX Register

N	ame	Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	B it 0
CIN	R_MAX				CINR_N	MAX(7:0)			
Name:	CINR_MAX								
Address:	0xFE3A								
Access:	Read only								
Reset:	0x00								

CINR_MAX:Carrier to Interference + Noise ratio Max

This register stores the maximum CINR value measured in the last message received.

In order to calculate CINR properly, the algorithm takes beacon-type messages as a reference, since this message type allows knowing its content beforehand.

The system uses a table that must be loaded with the beacon data to be received, so CINR mode must be activated (see PHY_CONFIG register) and the same procedure used to send beacons must be followed. As CINR mode is activated, physical layer will load the message in the table instead of sending it (table load time is in the order of microseconds, and is much shorter than the one used to send the message).

Once the table is loaded, CINR must be disabled, and next messages CINR will be calculated taken the beacon loaded in the table as reference

The measurement is done at symbol level.

The value is stored in ¼dB steps.



12.1.5.17 EVM_HEADER Registers

N	lame	Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	B it 0	
EVM_	HEADER				EVM_HEA	DER(15:8)				@0xFE3B
					EVM_HEA	DER (7:0)				@0xFE3C
Name:	EVM_HEAD	ER								
Address:	0xFE3B – 0x	FE3C								
Access:	Read only									
Reset:	0x00; 0x00									
•	EVM_HEAD	ER: He	eader Erro	or Vector	Magnitude	-				
			These registers store in a 16-bit value the maximum error vector magnitude measured in the reception of a message header.							magnitude
			The 7 MSB (EVM_HEADER(15:9)) represent the integer part in %, being t EVM_HEADER(8:0) bits the fractional part if more precision were required.							•
		sp va	ecificatior riable. T	n. It is res he 20-bit	served 32-I	bit in data B is aligne	memory ted to the 3	to be able	to declar	vith PRIME e as 32-bit in order to

12.1.5.18 EVM_PAYLOAD Registers

N	lame	Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	B it 0		
EVM_F	PAYLOAD				EVM_PAY	LOAD(15:8	3)			@0xFE3D	
					EVM_PAY	(LOAD(7:0))			@0xFE3E	
Name:	EVM_PAYLO	DAD									
Address:	0xFE3D – 0x	FE3E	JE								
Access:	Read only										
Reset:	0x00; 0x00										
•	EVM_PAYL	DAD: P	D: Payload Error Vector Magnitude-								
		These registers store in a 16-bit value the maximum error vector n measured in the reception of a message payload.							magnitude		

The 7 MSB (EVM_PAYLOAD(15:9)) represent the integer part in %, being the EVM_PAYLOAD(8:0) bits the fractional part if more precision were required.



12.1.5.19 EVM_HEADER_ACUM Registers

Name	Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	B it 0					
EVM_HEADER_ACUM		EVM_HEADER_ACUM(19:12)											
		EVM_HEADER_ACUM (11:4)											
	EVI	M_HEADEI	R_ACUM (3:0)		"00	00"		@0xFE41				
		"0000000"											

Name: EVM_HEADER_ACUM

Address: 0xFE3F - 0xFE42

Access: Read only

•

Reset: 0x00, ..., 0x00;

EVM_HEADER_ACUM: Header Total Error Vector Magnitude Accumulator

When receiving an OFDM symbol, the summation of all its individual carriers EVMs is calculated in order to further calculate the average EVM value. These registers store the maximum summation between the two OFDM symbols received in a message header.

12.1.5.20 EVM_PAYLOAD_ACUM Registers

Name	Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	B it 0					
EVM_PAYLOAD_ACUM			EVM_	PAYLOAD	_ACUM(19	9:12)			@0xFE43				
		EVM_PAYLOAD_ACUM(11:4)											
	EVN	I_PAYLOA	D_ACUM	(3:0)		"00	00"		@0xFE45				
		"0000000"											

Name: EVM_PAYLOAD_ACUM

Address: 0xFE43 – 0xFE46

Access: Read only

•

Reset: 0x00, ..., 0x00;

EVM_PAYLOAD_ACUM: Payload Total Error Vector Magnitude Accumulator

When receiving an OFDM symbol, the summation of all its individual carriers EVMs is calculated in order to further calculate the average EVM value. These registers store the maximum summation between all the OFDM symbols received in a message payload.



12.1.5.21 RMS_CALC Register

N	ame	Bit 7 Bit 6 Bit 5 Bit 4 Bit 3 Bit 2 Bit 1 Bit 0							
RMS	_CALC				RMS_C	ALC(7:0)			
Name:	RMS_CALC								
Address:	0xFE58								
Access:	Read only								
Reset:	0x00								

• **RMS_CALC:** This register stores an 8-bit value which magnitude is proportional to the emitted signal amplitude.

By measuring the amplitude of the emitted signal, the hardware can estimate the power line input impedance. Thus hardware can adjust emission configuration appropriately.



12.1.5.22 VSENSE_CONFIG Register

Nai	me	Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	B it 0
VSENSE	CONFIG			-		PFAILURE	PSENSE_SOFT	VFAILURE	VSENSE_EN
Name:	VSENSE_	CONFI	G						
Address:	0xFE59								
Access:	Read only	,							
Reset:	0x00								

• **PFAILURE:** Power Failure Flag

This flag is set to 1 when a power failure occurs. The transmission is stopped and a new transmission is not possible if this flag is not cleared previously.

When a power failure occurs, a consideration about decreasing voltage amplitude in the source should be taken.

This flag must be cleared by software.

- PSENSE_SOFT: Current measurement is done every time a transmission takes place. With PSENSE_SOFT the system can force a continuous current measurement, including both idle and transmission states.
 - '0': Current consumption is measured every time a transmission begins (after a guard time defined by TRANS_PSENSE). NUMMILIS, NUMCYCLES and TRANS_PSENSE values must be taken into account to accurate PSENSE measurements. This is the default mode and it is the expected one when SAM4SP32A is working.
 - '1': Current consumption is measured both in idle and transmission states. This mode is useful for design purposes, in order to find suitable values for the current threshold (MAXPOT registers) depending on the external net requirements.
- VFAILURE: Voltage Failure Flag

This flag is set to 1 when a voltage failure occurs. The transmission is stopped and a new transmission is not possible if this flag is not cleared previously.

When a voltage failure occurs, a consideration about decreasing voltage amplitude in the source should be taken.

This flag must be cleared by software.

• VSENSE_EN:VSENSE enable

This bit enables VSENSE.

- '0': VSENSE disabled (default).
- '1': VSENSE enabled.

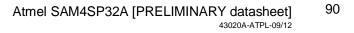


12.1.5.23 NUM_FAILS Register

N	ame	Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	B it 0
NUM	_FAILS				NUM_FAI	ILS(7:0)			
Name:	NUM_FAILS								
Address:	0xFE5A								
Access:	Read/write								
Reset:	0x02								

NUM_FAILS: This register stores the number of 50 ns cycles (clk=20MHz) during which a voltage failure must be detected before shutting off the transmission and setting VFAILURE flag. This detection shall be done after a guard period set by TTRANS from the beginning of the transmission.

Default value: $0x02 \rightarrow 2 * 50 = 100$ ns





12.1.5.24 TTRANS Register

•

		Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	B it 0		
TTRA	ANS				TTRA	NS(7:0)					
Name:	TTRANS										
Address: (0xFE5B										
Access:	Read/write										
Reset: (0x2D										

TTRANS:This register stores the number of 50 μ s cycles (clk=20MHz) to wait from the beginning
of the transmission before looking for a possible voltage failure.Default value: 0x2D \rightarrow 45 * 50 = 2.25ms (Thus, voltage failures are not expected until the

end of chirp signal period)



12.1.5.25 AGC0_KRSSI Register

N	ame	Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	B it 0
AGCO	_KRSSI	AGC0_KRSSI(7:0)							
Name:	AGC0_KRSS	SI							
Address:	0xFE5C								
Access:	Read/write								
Reset:	0x00	x00							

• AGC0_KRSSI: This register is used to correct RSSI (Received Signal Strength Indication) computation when Automatic Gain Control 0 (AGC0) is active.



12.1.5.26 AGC1 KRSSI Register

N	ame	Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	B it 0
AGC1	_KRSSI	AGC1_KRSSI(7:0)							
Name:	AGC1_KRSS	SI							
Address:	0xFE5D								
Access:	Read/write								
Reset:	0x00								

AGC1_KRSSI: This register is used to correct RSSI (Received Signal Strength Indication) computation
 when Automatic Gain Control 1 (AGC1) is active.



12.1.5.27 ZERO_CROSS_TIME Registers

Name	Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	B it 0				
ZERO_CROSS_TIME			ZER	O_CROSS	_TIME(19:	12)			@0xFE69			
		ZERO_CROSS_TIME (11:4)										
	ZE	RO_CROS	S_TIME (3	:0)		"00	00"		@0xFE6B			
	"0000000"											

Name: ZERO_CROSS_TIME

Address: 0xFE69 – 0xFE6C

Access: Read only

Reset: 0x00, ..., 0x00;

• ZERO_CROSS_TIME: Instant in time at which the last zero-cross event took place. It is expressed in 10µs steps and may take values from 0 to 1e6 (20-bit effective).

It is set by hardware and is a read-only register.

This register is used by the physical layer for being in accordance with PRIME specification. It is reserved 32-bit in data memory to be able to declare as 32-bit variable. The 20-bit register MSB is aligned to the 32-bit variable MSB, in order to simplify arithmetic calculations with time values.



12.1.5.28 ZERO_CROSS_CONFIG Register

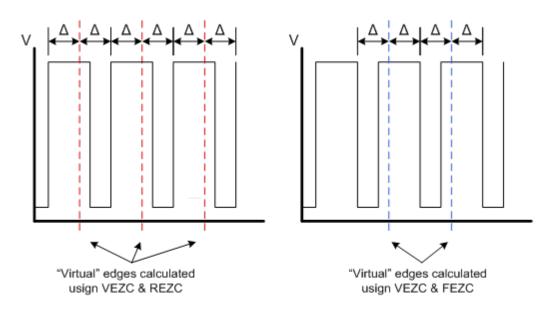
N	lame	Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	B it 0
ZERO_CR	OSS_CONFIG						VEZC	REZC	FEZC
Name:	ZERO_CROS	SS_CONF	IG						
Address:	0xFE6D								
Access:	Read/write								
Reset:	0x06								
•	: F	Reserved	bits						

• VEZC:

Virtual Edge for Zero Crossing

In this bit is equal to one, the hardware calculates the middle point between two VNR edges to calculate de zero crossing.

This mode is used when the VNR signal duty cycle is different from 50%:



VECZ can be used simultaneously with RECZ or FECZ.

- Using the three of them at a time is not recommended.
- REZC: Rising Edge for Zero Crossing If this bit is set to '1', the hardware uses the VNR rising edges to calculate zero-crossing. FEZC and REZC can be used simultaneously.
- FEZC: Falling Edge for Zero Crossing If this bit is set to '1', the hardware uses the VNR falling edges to calculate zero-crossing. FEZC and REZC can be used simultaneously.



12.1.5.29 PSENSECYCLES Registers

Nar	ne	Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2 Bit	t1 Bit0	
PSENSE	CYCLES					FLAG_PSENSE	D(18		@0xFE7D
						D(15:8)			@0xFE7E
						D(7:0)			@0xFE7F
Name:	PSENSEC	YCLES							
Address:	0xFE7D –	0xFE7F							
Access:	Read/write								
Reset:	0x00,, 0	x00;							
•	:		Reserve	d bits					
٠	FLAG_SE	NSE:	Wheneverset 1.	er a new	power v	value is written in	PSENSECYC	LES, FLAG_I	PSENSE is
			This flag	must be	cleared I	by software			
•	D(17:0):		Power se	upply cor	nsumptio	n measurement			
			•	during N	NUMMILI	s sampled (f _{clk} =2 S milliseconds is s	•		-
						is written after NU nilliseconds.	MMILIS, and	then a new va	alid value is
			transmission	begins or					

12.1.5.30 MEAN Registers

Na	me	Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	B it 0	
ME	AN			-		FLAG_MEAN		D(18:16)		@0xFE80
						D(15:8)				@0xFE81
						D(7:0)				@0xFE82
Name:	PSENSEC	YCLES								
Address:	0xFE80 – 0	0xFE82								
Access:	Read/write									
Reset:	0x00,, 0	x00;								
•	:		Reserve	d bits						
٠	FLAG_ME	AN:	Whenev	er a new	value is	written in MEAN, I	FLAG_M	EAN is se	et to '1'	
			This flag) must be	cleared	oy software				
٠	D(17:0):		PSENS A_NUM Note: T	ECYCLE MILIS ree he first v	S and h gister in [/] alid valu	erage power cons naving into accou 12.1.5.36). e is written after l every NUMMILIS i	INT the C	converger	nce facto	or "A" (see



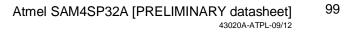
12.1.5.31 PMAX Registers

No		Bit 7	Bit 6		Bit 4	Dit 2	Bit 2	Dit 1	B it 0	
	ime	DIL /		Bit 5		Bit 3		Bit 1		
	IAX			•		FLAG_PMAX		D(18:16)		@0xFE83
						D(15:8)				@0xFE84
						D(7:0)				@0xFE85
Name:	PMAX									
Address:	0xFE83 –	0xFE85								
Access:	Read/write	;								
Reset:	0x00,, 0	0x00;								
•	:		Reserve	ed bits						
•	FLAG_PN	IAX:	Whenev	er a new	value is	written in PMAX, I	FLAG_PI	MAX is se	et to '1'.	
			This flag) must be	cleared	by software				
•	D(17:0):		consum cancelle	ption exc ed.	ceeds a (register (see 12. user defined thresh average power co	hold valu	ie, the cu	rrent trar	ismission is
			MAXPC	T thresh	old.					

12.1.5.32 TRANS_PSENSE Register

N	ame	Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	B it 0
TRANS	PSENSE				TRANS_P	SENSE(7:0))		
Name:	TRANS_PSE	INSE							
Address:	0xFE86								
Access:	Read/write								
Reset:	0x2B								

• **TRANS_PSENSE:** This register stores the number of 50 μ s cycles to wait from the beginning of a transmission before looking for a possible power failure. This guard time is taken to avoid transient period where the measurement would be inaccurate Default value: $0x2B \rightarrow 43 * 50 = 2.15ms$





12.1.5.33 P_TH Registers

Name	Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	B it 0	
P_TH						F	P_TH(18:16	5)	@0xFE87
				P_TH	(15:8)				@0xFE88
				P_Tł	ł(7:0)				@0xFE89

Name: P_TH

Address: 0xFE87 – 0xFE89

Access: Read/write

Reset: 0x07, 0xFF, 0xFF.

- --: Reserved bits
- **P_TH:** These registers contain a user defined power threshold. When the threshold value is exceeded, a low power consumption mode is automatically activated. In this low power consumption mode, the power dissipated in the transistors decreases at the expense of distortion increasing.



12.1.5.34 MAXPOT Registers

Name	Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	B it 0	
ΜΑΧΡΟΤ						MA	XPOT(18	3:16)	@0xFE8A
				MAXPO	T (15:8)				@0xFE8B
				MAXPO	OT (7:0)				@0xFE8C
									-

Name: MAXPOT

Address: 0xFE8A – 0xFE8C

Access: Read/write

Reset: 0x07, 0xFF, 0xFF.

- --: Reserved bits
- **MAXPOT:** These registers contain a user defined power consumption threshold. When this threshold is exceeded, current transmission is cancelled.

When the threshold is exceeded, two flags are activated:

- POTFAILURE flag (see VSENSE_CONFIG in 12.1.5.22). This flag indicates that a power failure has occurred.
- FLAG_PMAX flag (see PMAX in 12.1.5.31). This flag indicates that, after a power failure, the last mean power value measured has been stored in PMAX register.

To reset both flags is enough to reset either of them, the other will be automatically reset. This will enable to start new transmissions.



12.1.5.35 NUMCYCLES Register

N	ame	Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	B it 0	
NUM	CYCLES				NUMCY	CLES(7:0)				
Name:	NUMCYCLE	S								
Address:	0xFE8D									
Access:	Read/write									
Reset:	0x05									
٠	NUMCYCLE		lumber of aken as va		measuring	power be	fore obtai	ning a mea	an value th	at can be
			•		•	•		•	seconds), The first val	•

measurement value will be output in the fifth millisecond.

Example2: If NUMCYCLES=3(cycles) and NUMMILIS=20(milliseconds), 3 power measurements will be taken during 20 milliseconds each one. The first valid power measurement value will be output after 60 milliseconds.



12.1.5.36 A_NUMMILIS Register

N	ame	Bit 7	Bit 6 Bit 5	Bit 4 Bit 3	Bit 2 Bit 1 B it 0	
NUN	IMILIS		A(1:0)		NUMMILIS(4:0)	
Name:	A_NUMMILIS	6				
Address:	0xFE8E					
Access:	Read/write					
Reset:	0x21					
٠	:	F	Reserved bits			
٠	A(1:0):	C	Convergence Factor			
			veraging factor tha	at sets the conve	ergence speed of the mean calcul	ation
			x=00 sets quicker contermediate values.	onvergence, while	A=11 sets the slowest one. A=01,10) are
		ta n O	ake into account in o nean value can be c	rder to select a sui calculated slowly, b of time. When NU	rsion values, so NUMMILIS value mu table value for A. If NUMMILIS is high because the averaging in being calcu MMILIS is low, the mean value mus e accurate values.	n, the lated
•	NUMMILIS(4	:0): N	leasurement acquisi	tion time in millised	conds	
		S	Stores the measurem	ent acquisition tim	e in milliseconds.	
		n	•	e taken during 1 n	and NUMMILIS=1(milliseconds), 5 p nillisecond each one .The first valid p fifth millisecond.	
		n	neasurements will k	be taken during 2	and NUMMILIS=20(milliseconds), 3 p 0 milliseconds each one. The first t after 60 milliseconds.	



12.1.5.37 EMIT_CONFIG Register

Na	me	Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	B it 0
EMIT_C	ONFIG							TR_EMIT	TWO_H_BRIDGES
Name:	EMIT_CO	NFIG							
Address:	0xFE8F								
Access:	Read/write	•							
Reset:	0x03								

• TR_EMIT: Emission mode

This bit selects the emission mode (Internal Drive or External transistors bridge).

- '0': Emission is done by means of internal SAM4SP32A driver.
- '1': Emission is done by means of external transistors (Default).

• **TWO_H_BRIDGES:** This bit selects the number of semi-H-bridges in the external interface.

- '0': There is only one semi-H-bridge in the external interface.
- '1': There are two semi-H-bridges in the external interface and the field HIMP (AFE_CTL register) determines which one is active (Default).

Semi-H-Bridges must be connected following the table below

	TWO_H_BRIDGES='0'	TWO_H_BRIDGES='1'
EMIT1	Р	N1
EMIT2	Р	N1
EMIT3	Р	N1
EMIT4	Ν	P2
EMIT5	Ν	P2
EMIT6	Ν	P2



12.1.5.38 AFE_CTL Register

Nai	me	Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	B it 0
AFE_	CTL				HIMP	HIMP_INV	TXRX	TXRX_HARD	TXRX_INV
Name:	AFE_CTL	_							
Address:	0xFE90								
Access:	Read/writ	e							
Reset:	0x10								
٠	:		Reser	ved bits					
٠	HIMP:		Analo	g Front E	Ind Impe	dance contro	l bit-		
					s which		ctive whe	n working with	a two half-H-bridge
			• '0': '	Low imp	edance"	half-H-bridge	is active	(P2-N2).	
			• '1': '	"High im	pedance"	half-H-bridge	e is active	e (P1-N1).	
٠	HIMP_IN	V :		• •	rity contro				
					•	larity of the H	•	•	
								f the external p ains unchanged	oin HIMP output, the I
٠	TXRX:		The va pin lev		ed in this	bit is taken b	by the mic	rocontroller in c	order to set the TXRX
			• '0':	TXRX pii	n output =	= '0'.			
			• '1': [·]	TXRX pii	n output =	= '1'.			
٠	TXRX_H	ARD:	TXRX	pin cont	rol				
			This fi	eld seled	ts if the	TXRX pin is s	oftware/h	ardware contro	lled.
				TXRX piı E_CTL(2		are controlled	d. TXRX v	/alue is set by T	XRX bit field
			• '1': [•]	TXRX pii	n is hardv	vare controlle	ed.		
•	TXRX_IN	V :	TXRX	pin pola	rity contr	ol			
			This fi	eld inver	ts the po	larity of the T	XRX pin	output	



12.1.5.39 R Registers

Name	Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	B it 0				
R1		R1(7:0)										
R2	R2(7:0)											
R3				R3	(7:0)				0xFEA1			
R4				R4	(7:0)				0xFEA2			
R5				R5	(7:0)				0xFEA3			
R6				R6	(7:0)				0xFEA4			
R7				R7	(7:0)				0xFEA5			
R8	R8(7:0)											

Name: R1 – R8

Address: 0xFE9F – 0xFEA6

Access: Read/write

Reset: 0x60; 0x60; 0x60; 0x60; 0xFF; 0xFF; 0xFF; 0xFF.

R: The value in these registers strongly depends on the external circuit configuration.
 Atmel provides values to be used according with the design recommended in SAM4SP32A
 kits

Please contact Atmel Power Line if different external configurations are going to be used

Recommended values (according to the configuration recommended in SAM4SP32A kits) R1(7:0): 0x21 R2(7:0): 0x20 R3(7:0): 0x12 R4(7:0): 0x02 R5(7:0): 0x37 R6(7:0): 0x77 R7(7:0): 0x37 R8(7:0): 0x77

Order of precedence: In the event of a conflict between the Ri(7:0) values above and Ri(7:0) values specified in the latest documentation in an SAM4SP32A kit, the values in the kit documentation shall take precedence.



12.1.5.40 PHY_ERRORS Registers

N	ame	Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	B it 0		
PHY_I	ERRORS					PHY_ERRORS(4:0)					
Name:	PHY_ERRO	RS									
Address:	0xFE94										
Access:	Read/write										
Reset:	0x00										
٠	:	Re	served b	oits							
٠	PHY_ERRO	RS: Ph	ysical La	yer Error (Counter						
			•	i stores in licrocontro					nysical layer		
		The	e value s	tored in thi	is register	is cleared	every time	e the regis	ter is read.		



12.1.5.41 FFT_MODE Registers

Name Bit 7		Bit 6 Bit 5 Bit 4	Bit 3 Bit 2	Bit 1	B it 0
FFT_MODE		NSYM(5:0)		CONTINUOUS	TEST_MODE_EN
Name:	FFT_MODE				
Address:	0xFEB0				
Access:	Read/write				
Reset:	0x00				
٠	NSYM:	Number of symbols to	o transmit		
		When in continuous transmission mode, symbol data acts as a free-running buffer, increasing from 0 to NSYM-1 and overflowing back to symbol 0.			
٠	CONTINUOUS: This field enables/disables continuous transmission mode.				
		 '0': Continuous transmission mode disabled. 			
	 '1': Continuous transmission mode enabled. 				
٠	TEST_MODE_EN: This field enables/disables test mode				
		• '0': Test mode disabled.			
		 '1': Test mode enablished 	oled.		
	Configuration for test mode. This register is used by the physical layer to fulfill with PRIME specification (PLME_TESTMODE.request primitive and PLME_TESTMODE.confirm primitive, see PRIME specification). In this mode data provided to FFT is written in data memory at ADDR_PHY_INI_TX, codifying each value with 4 bits according to DPSK modulation mapping. The msb of the value is to indicate an input of zero when set to '1'. Each byte in data memory contains 2 input values for FFT, with the first value located at high bits. There are 97 input values for				
	FFT, so many as the number of subcarriers, so there are 48 bytes and a half of t				

for the next symbol data.

next byte used for codifying them. The other half of this byte (low bits) will be used



12.1.5.42 AGC_CONFIG Register

Name	;	Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	B it 0		
AGC_CO	AGC_CONFIG		-	AGC0_POL AGC0_VALUE		AGC0_MODE	AGC1_POL	AGC1_VALUE	AGC1_MODE		
Name:	AGC_	AGC_CONFIG									
Address:	0xFEB1										
Access:	Read/write										
Reset:	0x24										

SAM4SP32A has implemented two Automatic Gain Control outputs in order to adjust the received signal level to a suitable range. When in "automatic" mode, both of them are set to '1' when the received signal is above 16-bit-user-definable thresholds (AGC1_TH and AGC0_TH) in order to activate external attenuators placed in the external analog front end.

The value of these outputs is set during the beginning of a received message and is hold until the end of the message. AGC0 and AGC1 follow different algorithms, thus using both of them ensures more accurate gain control

•:	Reserved bits
AGC0_POL:	AGC0 polarity
	This bit sets the polarity of the AGC0 output.
	• '0': Polarity is inverted.
	 '1': Polarity is not inverted (default).
AGC0_VALUE:	AGC0 output value-
	This bit stores the value wrote by the user to be the AGC0 output.
	This bit is only taken into account when AGC0 "forced" mode is active (AGC0_MODE='1').
	AGC0_POL field can invert this value.
AGC0_MODE:	AGC0 mode
	This bit selects which AGC0 mode is being used
	• '0': "Automatic" Mode. AGC0 output will be managed by the MAC, depending on saturation detected in received signal. If saturation is detected, AGC0 output will be '1'. Else, AGC0 output will be '0'. AGC0_POL field can invert this value.
	(See SAT_TH registers in 12.1.5.43)
	 '1': "Forced" Mode. AGC0 output will be managed by the user, according to the value wrote in AGC0_VALUE field (AGC_CONFIG(4)).
AGC1_POL:	AGC1 polarity
	This bit sets the polarity of the AGC1 output.
	• '0': Polarity is inverted.
	 '1': Polarity is not inverted (default).
AGC1_VALUE:	AGC1 output value-
	This bit stores the value wrote by the user to be the AGC1 output.
	This bit is only taken into account when AGC1 "forced" mode is active (AGC1_MODE='1').
	AGC1_POL field can invert this value.



AGC1_MODE: AGC1 mode

•

This bit selects which AGC1 mode is being used

- '0': "Automatic" Mode. AGC1 output will be managed by the MAC, depending on saturation detected in received signal. If saturation is detected, AGC1 output will be '1'. Else, AGC1 output will be '0'. AGC1_POL field can invert this value. (See SAT_TH registers in 12.1.5.43)
- '1': "Forced" Mode. AGC1 output will be managed by the user, according to the value wrote in AGC1_VALUE field (AGC_CONFIG(4)).



12.1.5.43 SAT_TH Registers

Name		Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	B it 0		
S	SAT_TH SAT_TH(15:8)								@0xFEB7		
			SAT_TH(7:0)								
Name:	SAT_TH										

Address: 0xFEB7 – 0xFEB8

Access: Read/write

Reset: 0x40; 0x00

• **SAT_TH:** These registers store a threshold for the PLC input-signal amplitude.

If this threshold is exceeded, AGC thresholds (AGC0_TH and AGC1_TH) will be taken into account.

If this threshold is not exceeded, AGC0_TH and AGC1_TH thresholds will be ignored, thus the AGC algorithm will be never triggered.

Recommended value for Atmel reference design = 0x37AA.



12.1.5.44 AGC1_TH Registers

Name	Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	B it 0		
AGC1_TH		AGC1_TH(15:8)								
	AGC1_TH(7:0)									
									•	

Name: AGC1_TH

Address: 0xFE5F – 0xFE60

Access: Read/write

Reset: 0x40; 0x00

• AGC1_TH: AGC1 Threshold

These registers store the 16-bit upper threshold used by the AGC1 algorithm to determine that the input signal must be attenuated.

This threshold is only taken into account in AGC1 "automatic" mode (AGC_CONFIG.AGC1_MODE='0').

This threshold is only taken into account if SAT_TH value is exceeded.

Recommended value for Atmel reference design = 0x4A00.



12.1.5.45 AGC0_TH Registers

Name	Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	B it 0			
AGC0_TH		AGC0_TH(15:8)									
		AGC0_TH(7:0)									

Name: AGC0_TH

Address: 0xFEB2 – 0xFEB3

Access: Read/write

Reset: 0x10; 0x00

• AGC0_TH: AGC0 Threshold

These registers store the 16-bit upper threshold used by the AGC0 algorithm to determine that the input signal must be attenuated.

This threshold is only taken into account in AGC0 "automatic" mode (AGC_CONFIG.AGC0_MODE='0').

This threshold is only taken into account if SAT_TH value is exceeded.

Recommended value for Atmel reference design = 0x1000.



12.1.5.46 AGC_PADS Register

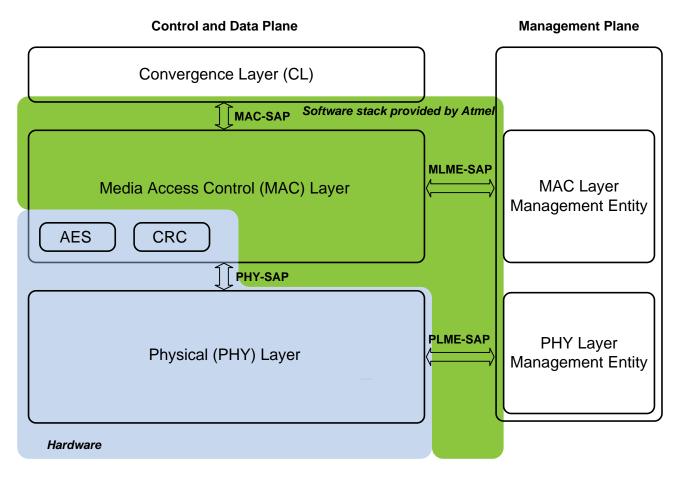
Na	me	Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	B it 0
AGC_	PADS			•				P46_MODE	SWITCH_AGC
Name:	AGC_PAD	S							
Address:	0xFE61								
Access:	Read/write	•							
Reset:	0x00								
٠	:		Reserv	ed bits					
٠	P46_MOD	E:	This fie	ld contro	ls the P4	.6/T2/AG	C1 outpu	t pin (pin no.9 [,]	4).
			• '0': P	in no.94	works as	P4.6/T2	output pir	า.	
			• '1': P	in no.94	works as	AGC1 or	utput pin.		
•	SWITCH_	AGC:	This bit	switches	s the AG	C0 and A	GC1 outp	outs.	
			• '0': N	ot switch	ed AGC	outputs.			
			• '1': S	witched /	AGC outp	outs.			
			• 1:5	witched /		Juis.			



12.2 SAM4SP32A MAC Layer

The SAM4SP32A hardware MAC layer consists of a hardware implementation of some functionalities of the MAC Layer Entity specified in PRIME specification. These features are CRC calculation and AES128 block.

Figure 12-9. SAM4SP32A Software Stack Diagram



Atmel PRIME stack implements by software the rest of the MAC layer requirements and capabilities. Furthermore, the software package allows the communication with the Management Plane by means of the two Access points described by PRIME (PHY Layer Management Entity SAP and MAC Layer Management Entity SAP) and the interface to communicate MAC layer with the upper layer (Convergence Layer).

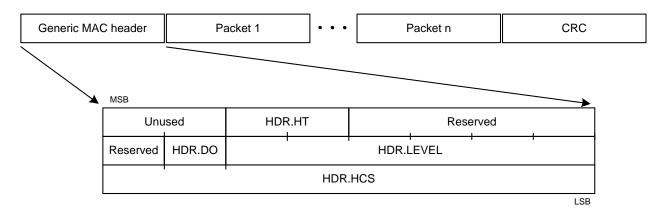
Please check the "Atmel PRIME Stack User Manual" for software package detailed description and functionality.

12.2.1 Cyclic Redundancy Check (CRC)

There are three types of MAC PDUs (generic, promotion and beacon) for different purposes, and each one has its own specific CRC. In SAM4SP32A there is a hardware implementation of every CRC type calculated by the MAC layer. This CRC hardware-calculation is enabled by default. Note that the CRC included at the physical layer is also a hardware implementation available in SAM4SP32A and it is also enabled by default.



Figure 12-10. Generic MAC PDU format and generic MAC header detail



In transmission all CRC bytes are real-time calculated and the last bytes of the MAC PDU are overwritten with these values, (provided that the field HT in the first byte of the MAC header in transmission data is equal to the corresponding MAC PDU type).

In reception the CRC bytes are also real-time calculated and these bytes are checked with the last bytes of the MAC PDU. If the CRC is not correct, then an error flag is activated, the complete frame is discarded, and the corresponding error counter is increased. These counters allow the MAC layer to take decisions according to error ratio.

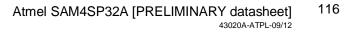
For the Generic MAC PDU, there is an 8-bit CRC in the Generic MAC header, which corresponds to PRIME HDR.HCS. In reception if this CRC doesn't check successfully, the current frame is discarded and no interruption is generated.

This works in the same way as CRC for the PHY layer (CRC Ctrl, located in the PHY header, see PRIME specification for further information).

There is another CRC for the Generic MAC PDU which is the last field of the GPDU. It is 32 bits long and it is used to detect transmission errors. The CRC shall cover the concatenation of the SNA with the GPDU except for the CRC field itself. In reception, if the CRC is not successful then an internal flag is set and the error counter is increased.

For the Promotion Needed PDU there is an 8-bit CRC, calculated with the first 13 bytes of the header. In reception, if this CRC is not correct, then an internal flag is set and the corresponding error counter is increased.

For the Beacon PDU there is a 32-bit CRC calculated with the same algorithm as the one defined for the CRC of the Generic MAC PDU. This CRC shall be calculated over the complete BPDU except for the CRC field itself. In reception, if this CRC is not successful, then an internal flag is set and the same error counter as for GPDU is increased. The hardware used for this CRC is the same as the one used for GPDU.

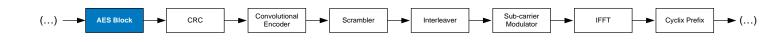




12.2.2 Advanced Encryption Standard (AES)

One of the security functionalities in PRIME is the 128-bit AES encryption of data and its associated CRC. SAM4SP32A includes a hardware implementation of this block, and it is used by the physical layer in real-time transmission/reception. It is possible to use this block externally as a peripheral unit, by accessing the specific registers designed to control it. Therefore there are some configurable parameters and input/output buffers to the block.

Figure 12-11. PHY Layer transmitter block diagram



There are two basic operation ways in SAM4SP32A when using PRIME Security Profile 1. The first one is real-time encryption and the second one is independent encryption from the PHY layer.

Real-Time Encryption: the AES128 core is integrated in the physical chain, and data is encrypted and decrypted in real-time when needed. In transmission, data is transferred to the emission buffer by means of the DMA TX channel. Then the 128 bits located in the buffer are encrypted before starting transmission (Note that Beacon PDU, Promotion PDU and Generic MAC header, as well as several control packets, are not encrypted). Data is extracted when required from this buffer until it is empty, and then a new DMA transfer is requested to fill the 16 bytes and a new encryption is executed. The key used for encryption must be set at the corresponding register, and it can vary from a packet to another.

In reception, data is obtained from the PHY layer and it is passed to the AES128 block. When the reception buffer is full with incoming data, the 128 bits are decrypted and transferred to external memory through DMA RX channel. Then the reception buffer is available again to fill with processed data.

The header is always real-time analyzed in order to know if encryption process must be applied.

Independent Encryption: the AES128 core is used as a peripheral unit, accessible with several registers mapped in external memory. In this mode, when in transmission, data must be encrypted previously to the use of the PHY_DATA.request primitive (see PRIME specification), in an independent way. In reception, data passed by the PHY layer is already encrypted and must be decrypted in a subsequent process.

When working with AES block as a peripheral unit, automatic CRC calculation by hardware is disabled.



12.2.3 MAC Layer Registers

12.2.3.1 SNA Registers

Name	Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	B it 0	
SNA				SNA(47:40)				@FE62
				SNA	.(7: 0)				@FE67
Name:	SNA								
Address:	0xFE62 – 0	DxFE67							
Access:	Read/write								
Reset:	0x00,, 0	x00							

• SNA: Sub Network Address

These registers store the 48-bit Sub Network Address. When the system Sub Network Address is available, the SAM4SP32A microcontroller must write it down so the Phy layer will be able to correctly calculate the CRC's, which depend on this parameter.

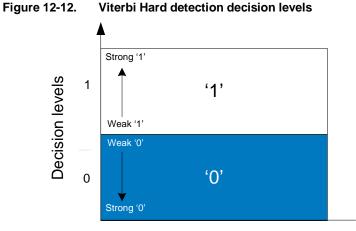


12.2.3.2 VITERBI_BER_HARD Register

Na	Name Bit			Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	B it 0			
VITERBI_BER_HARD VITERBI_BER_HARD(7:0)												
Name:	VITERBI_E	/ITERBI_BER_HARD										
Address:	0xFE36											
Access:	Read only											
Reset:	0x00											

VITERBI_BER_HARD: This register stores the number of errors accumulated in a message reception using Viterbi hard* decision. The value is cleared by hardware each time a new message is received.

*Hard Decision: in "hard" detection there are only two decision levels. If the received value is different than the corrected one, the error value taken is "1". Otherwise, the error value taken is "0".



From the value in VITERBI_BER_HARD register it is possible to calculate de Bit Error Rate according to the following formula:

$$\mathsf{BER} = \frac{10^{\frac{VTB_BER_HARD}{40}} - 1}{100}$$



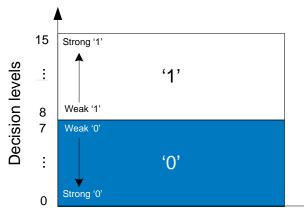
12.2.3.3 VITERBI_BER_SOFT Register

VITERBI_BER_SOFT VITERBI_BER_SOFT(7:0) Name: VITERBI_BER_SOFT
Name: VITERBI_BER_SOFT
Address: 0xFE37
Access: Read only
Reset: 0x00

VITERBI_BER_SOFT: This register stores a value proportional to the number of errors accumulated in a message reception using Viterbi soft* decision. The value is cleared by hardware each time a new message is received.

*Soft Decision: in "soft" decision there are fifteen decision levels. A strong '0' is represented by a value of "0", while a strong '1' is represented by a value of "15". The rest of values are intermediate, so "7" is used to represent a weak '0' and "8" represents a weak '1'. Soft decision calculates the error in one bit received as the distance in decision levels between the value received (a value in the range 0 to 15) and the corrected one (0 or 15).







12.2.3.4 ERR_CRC32_MAC Registers

Nar	ne										
ERR_CRC	32_MAC			ERR_CRC32_MAC(15:8)							
				E	RR_CRC3	2_MAC(7:0)			@0xFEBB	
Name:	ERR_CR	C32_MAC									
Address:	0xFEBA – 0xFEBB										
Access:	Read/write										
Reset:	0x00, 0x00										

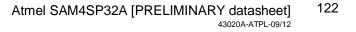
ERR_CRC32_MAC: 16-bit value that stores the number of received messages that have been discarded by an error in the MAC layer CRC32.
 Note: to clear this value, these registers must be reset by the SAM4SP32A microcontroller.



12.2.3.5 ERR_CRC8_MAC Registers

Nar	ne	e Bit 7 Bit 6 Bit 5 Bit 4 Bit 3 Bit 2 Bit 1 Bit 0								
ERR_CR	C8_MAC			E	RR_CRC8	_MAC(15:8))			@0xFEBC
					ERR_CRC8	B_MAC(7:0)				@0xFEBD
Name:	ERR_CR	C8_MAC								
Address:	0xFEBC – 0xFEBD									
Access:	Read/wri	te								
Reset:	0x00, 0x0	00								

• ERR_CRC8_MAC: 16-bit value that stores the number of received messages that have been discarded by an error in the payload MAC layer CRC8. Note: to clear this value, these registers must be reset by the SAM4SP32A microcontroller.





12.2.3.6 ERR_CRC8_AES Registers

Nar										
ERR_CR	C8_AES		ERR_CRC8_AES(15:8)							
					ERR_CRC8	B_AES(7:0)				@0xFEBF
Name:	ERR_CR	C8_AES								
Address:	0xFEBE – 0xFEBF									
Access:	Read/write									
Reset:	0x00, 0x00									

• ERR_CRC8_AES: 16-bit value that stores the number of received messages that have been discarded by an error in the payload AES CRC8. Note: to clear this value, these registers must be reset by the SAM4SP32A microcontroller.



12.2.3.7 ERR_CRC8_MAC_HD Registers

Na	me	Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	B it 0		
ERR_CRC	8_MAC_HD			ER	R_CRC8_M	MAC_HD(15:8)			@0xFEC0	
		ERR_CRC8_MAC_HD(7:0)									
Name:	ERR_CRC	RR_CRC8_MAC_HD									
Address:	0xFEC0-0	0xFEC1									
Access:	Read/write	write									
Reset:	0x00, 0x00	Dx00, 0x00									

ERR_CRC8_MAC_HD:16-bit value that stores the number of received messages that have been discarded by an error in the header MAC layer.
 Note: to clear this value, these registers must be reset by the SAM4SP32A microcontroller.



12.2.3.8 ERR_CRC8_PHY Registers

Nar	ne	Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	B it 0			
ERR_CR	C8_PHY			E	RR_CRC8	_PHY(15:8)				@0xFEC2		
				E	ERR_CRC8	8_PHY(7:0)				@0xFEC3		
Name:	ERR_CR	C8_AES	3_AES									
Address:	0xFEC2 -	- 0xFEC3										
Access:	Read/wri	te										
Reset:	0x00, 0x0)0										

• ERR_CRC8_PHY: 16-bit value that stores the number of received messages that have been discarded by an error in the PHY layer CRC8. Note: to clear this value, these registers must be reset by the SAM4SP32A microcontroller.



12.2.3.9 FALSE_DET_CONFIG Register

			e nog						
Name		Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	B it 0
FALSE_D _CONFI		-	-	ERR_CRC8 _MAC	INVALID _PROTOCOL	ERROR _LEN	ERROR_PAD _LEN	UNKNOWN _PDU	UNKNOWN _SP
Name:	FAL	SE_DE	T_CO	NFIG					
Address:	0xFE	EC4							
Access:	Read	d/write							
Reset:	0x10)							
•	:			Reserved	bits				
٠	ERR	CRC	8_MA(received		a correct	-		error counter if /AC layer CRC
٠	INVA	LID_PR	отосо	received	message has a	a correct	•	C8 but the F	error counter if PROTOCOL fiel
٠	ER	ROR_I	EN:	received r			•		error counter if eld indicates a no
٠	ER	ROR_I	PAD_L	received		a correct	PHY layer C		error counter if PAD_LEN fiel
٠	UN	KNOW	N_PD	received i	nessage has a	correct F		8 but the HT	error counter if field indicates
٠	UN	KNOW	'N_SP	received		ias a	correct PHY		error counter if RC8 but th



12.2.3.10 FALSE_DET Registers

Nar	ne	Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	B it 0		
FALSE	_DET				FALSE_D	DET(15:8)				@0xFEC5	
					FALSE_	DET(7:0)				@0xFEC6	
Name:	FALSE_	DET									
Address:	0xFEC5	- 0xFEC6									
Access:	Read/wri	ite									
Reset:	0x00, 0x	00									
•	FALSE_	DET:	ET: Erroneous non-discarded messages.								
			16-bit va	lue that s	stores the	number of	received	messages	that have	e not been	

16-bit value that stores the number of received messages that have not been discarded since its PHY layer CRC8 is correct, but in which there are other incorrect fields. The fields that shall be taken into account to increase the counter in case they were wrong can be selected by FALSE_DET_CONFIG register.

Note: to clear this value, these registers must be reset by the SAM4SP32A microcontroller



12.2.3.11 MAX_LEN_DBPSK Register

Nar	ne	Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	B it 0
MAX_LEN	_DBPSK	-	-		Ν	MAX_LEN_	DBPSK(5:0))	
Name:	MAX_LE	N_DBPSK							
Address:	0xFEC8								
Access:	Read/wri	te							
Reset:	0xFF								
٠	:		Reserve	d bits					
٠	MAX_L	EN_DBPS	-	allows to re		•	n, measure g with DBP		•

encoding. If a message in such modulation/encoding is received and its LEN field indicates a length above the threshold defined by MAX_LEN_DBPSK value, the message will be discarded.



12.2.3.12 MAX_LEN_DBPSK_VTB Register

Ν	lame	Bit 7 E	Bit 6 Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	B it 0	
MAX_LEN	DBPSK_VTB			MAX	_LEN_DBP	SK_VTB(5:0)		
Name:	MAX_LEN_D	BPSK_VTB							
Address:	0xFEC9								
Access:	Read/write								
Reset:	0xFF								
٠	:		Reserved bi	ts					
۰	MAX_LEN_D	BPSK_VTB:	This register the system Viterbi enco	allows to rec		-		-	
			If a messag indicates MAX_LEN_I	a length	above	the	threshol	d defined	



12.2.3.13 MAX_LEN_DQPSK Register

Nar	ne	Bit 7	Bit 6	Bit 6 Bit 5 Bit 4 Bit 3 Bit 2 Bit 1 Bit 0							
MAX_LEN	_DQPSK	-	-		Γ	MAX_LEN_	DQPSK(5:0)			
Name:	MAX_LE	N_DQPSK									
Address:	0xFECA										
Access:	Read/wri	te									
Reset:	0xFF										
٠	:		Reserve	d bits							
٠	MAX_L	EN_DBPS		gister sets allows to re		•			•		

encoding. If a message in such modulation/encoding is received and its LEN field indicates a length above the threshold defined by MAX_LEN_DQPSK value, the message will be discarded.



12.2.3.14 MAX_LEN_DQPSK_VTB Registers

N	lame	Bit 7 E	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	B it 0	
MAX_LEN	DQPSK_VTB				MAX_	LEN_DQP	SK_VTB(5	:0)		
Name:	MAX_LEN_D	QPSK_VTB								
Address:	0xFECB									
Access:	Read/write									
Reset:	0xFF									
٠	:		Reser	ved bits						
•	MAX_LEN_I	DQPSK_VTB	the sy	•	ows to rece		•		•	
			indica	tes a	n such mo length PSK_VTB	above	the	threshold	d defin	



12.2.3.15 MAX_LEN_D8PSK Registers

Nan	ne	Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	B it 0
MAX_LEN	L_D8PSK	-	-		Ν	MAX_LEN_	D8PSK(5:0)		
Name:	MAX_LE	N_D8PSK							
Address:	0xFECC								
Access:	Read/wri	te							
Reset:	0xFF								
٠	:		Reserved	d bits					
٠	MAX_L	EN_D8PSI	•			•			M symbols ation and i

encoding.

If a message in such modulation/encoding is received and its LEN field indicates a length above the threshold defined by MAX_LEN_D8PSK value, the message will be discarded.



12.2.3.16 MAX_LEN_D8PSK_VTB Register

N	ame	Bit 7 E	Bit 6 E	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	B it 0	
MAX_LEN	_D8PSK_VTB				MAX_	LEN_D8F	SK_VTB	5:0)		
Name:	MAX_LEN_D	8PSK_VTB								
Address:	0xFECD									
Access:	Read/write									
Reset:	0xFF									
٠	:		Reserve	ed bits						
٠	MAX_LEN_	D8PSK_VTB:	the sys		ws to rec		•		•	nbols that ation and
			indicate	es a	length	above	the	is receive threshol e will be di	ld defir	LEN field ned by



12.2.3.17 AES_PAD_LEN Register

Nan	ne	Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	B it 0		
AES_PA	D_LEN						AES_PAD	AD_LEN(3:0)			
Name:	AES_PA	D_LEN									
Address:	0xFE25										
Access:	Read/writ	te									
Reset:	0x00										
٠	:		Reserved	lbits							
٠	AES_P/	AD_LEN:	•		s over 16-					t 16-bytes	
			This regis	ster takes	values betw	ween 0 and	d 15.				
					encryption	•	used, micro	ocontroller	must write	e the AES	
			In no-end used.	crypted tr	ansmission	and in re	eception, th	ne value ii	n this regi	ster is not	



12.2.3.18 AES_DATA_IN Registers

Name		Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	B it 0	
AES_DATA	_IN				AES_DATA_	IN(127:120)				@FFA0
					AES_DAT	A_IN(7: 0)				@FFAF
Name:	AES	_DATA_IN								
Address:	0xFF	FAO – 0xFF	AF							
Access:	Rea	d/write								
Reset:	0x00	D,, 0x00								
٠	AES	_DATA_IN	: Input	buffer for A	ES128 blo	ck.				
				buffer can 12.2.3.20) r		o be encryp	oted/decryp	ted by the	key in KEN	/_PERIPH
			The r	esulting da	ta could be	read at AES	S_DATA_C	UT (see 12	2.2.3.19) re	gisters.



12.2.3.19 AES_DATA_OUT Registers

Nam	e	Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	B it 0	
AES_DAT	A_OUT			А	ES_DATA_(OUT(127:12	0)			@FFB0
					AES_DATA	_OUT(7: 0)				@FFBF
Name:	AES_[DATA_OUT								
Address:	0xFFB	0 – 0xFFBF	=							
Access:	Read	only								
Reset:	0x00, .	, 0x00								
•	AES_I	DATA_OUT	r: Output	buffer for A	AES128 blo	ock.				

This buffer stores the result of the encryption/decryption processing of data in AES_DATA_IN (see 12.2.3.18) register with the key in KEY_PERIPH (see 12.2.3.20) register.



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12.2.3.20 KEY_PERIPH Registers

Name		Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	B it 0	
KEY_PERI	PH				KEY_PERIF	PH(127:120)				@FFC0
	-									
					KEY_PER	IPH (7: 0)				@FFCF
Name:	KEY	_PERIPH								
Address:	0xFF	-0xF	FCF							
Access:	Rea	d/write								
Reset:	KEY	_PERIPH(127:120) :	0x00;	KEY_PERI	PH(119:112)	: 0x01;	KEY_PERI	PH(111:104)	: 0x02;
	KEY	_PERIPH(103:96) :	0x03;	KEY_PERI	PH(95:88) :	0x04;	KEY_PERI	PH(87:80) :	0x05;
	KEY	_PERIPH(79:72) :	0x06;	KEY_PERI	PH(71:64) :	0x07;	KEY_PERI	PH(63:56) :	0x08;
	KEY	_PERIPH(55:48) :	0x09;	KEY_PERI	PH(47:40) :	0x0A;	KEY_PERI	PH(39:32) :	0x0B;
	KEY	_PERIPH(31:24) :	0x0C;	KEY_PERI	PH(23:16) :	0x0D;	KEY_PERI	PH(15:8) :	0x0E;
	KEY	_PERIPH(7:0) :	0x0F;						
•	KEY	_PERIPH	: Key	for AES128	block whe	n used as pe	ripheral p	art.		

This key is used for encrypting/decrypting data in AES_DATA_IN registers.



12.2.3.21 KEY_PHY Registers

Name	Bit 7 Bit 6	В	it 5 Bit 4	Bit 3	E	Bit 2	Bit 1	B it 0	
KEY_PHY			KEY_P	HY(127:120)					@FFD0
			KEY_	_PHY(7: 0)					@FFDF
Name:	KEY_PHY								
Address:	0xFFD0 – 0xFFDF								
Access:	Read/write								
Reset:	KEY_PHY(127:120):	0x00;	KEY_PHY(119	:112) : 0>	x01;	KEY_PH	HY(111:104):	0x02;	
	KEY_PHY(103:96) :	0x03;	KEY_PHY(95:8	88): 02	x04;	KEY_PH	HY(87:80) :	0x05;	
	KEY_PHY(79:72) :	0x06;	KEY_PHY(71:6	64): 0x	x07;	KEY_PH	HY(63:56) :	0x08;	
	KEY_PHY(55:48) :	0x09;	KEY_PHY(47:4	0): 0>	x0A;	KEY_PH	HY(39:32) :	0x0B;	
	KEY_PHY(31:24) :	0x0C;	KEY_PHY(23:1	6): 0>	x0D;	KEY_PH	HY(15:8) :	0x0E;	
	KEY_PHY(7:0) :	0x0F;							

• KEY_PHY: Key for AES128 block when used by the physical layer

This key is used in real time encryption/decryption for Security Profile 1. When any of the DMA channels of the physical layer accesses to the memory, then this key and the input data are multiplexed to the AES128-core. Also output data is multiplexed in order to provide encrypted/decrypted data to the physical buffer.



12.2.3.22 AES_SFR Register

_	5								
Nar	ne 🛛	Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	B it 0
AES_	SFR						READY	START	CIPHER
Name:	AES_SFF	R							
Address:	0xFFE0								
Access:	Read/write	e							
Reset:	0x00								
•	:	Reserv	/ed bits.						
•	READY:	Flag to	indicate	encryption/	decryption	process co	ompletion.		
		When	the encryp	otion/decry	ption has b	een compl	leted, this f	lag is set t	o '1'.
		This fla	ag is autor	natically cl	eared whe	n an encry	ption/decry	ption proc	ess begins.
•	START:		•	set to '1', th				• •	•
									lly cleared
•	CIPHER:			es if data n		•			
•	SITTLA.	1113 116				signed of t	acci ypieu.		

- '0' Decryption mode
- '1' Encryption mode •



13. Electrical Characteristics

13.1 Absolute Maximum Ratings

Permanent device damage may occur if Absolute Maximum Ratings are exceeded. Functional operation should be restricted to the conditions given in the Recommended Operating Conditions section. Exposure to the Absolute Maximum Conditions for extended periods may affect device reliability.

Parameter	Symbol	Rating	Unit
Operating Temperature (Industrial)	ОТ	-40 to +85	°C
Storage Temperature	TST	-55 to 125	S
Voltage on Input Pins With Respect to Ground		-0.3 to +4.0	V
Maximum Operating Voltage (VDDCORE)	VDDCORE max	1.32	V
Maximum Operating Voltage (VDDIO)	VDDIO max	4.0	V
Junction Temperature	TJ	-40 to 125	٥C
Total DC Output Current On all I/O lines	Ю	300	mA

ATTENTION observe EDS precautions



Precautions for handling electrostatic sensitive devices should be taken into account to avoid malfunction. Charged devices and circuit boards can discharge without detection



13.2 DC Characteristics

The following characteristics are applicable to the operating temperature range: $T_A = -40^{\circ}C$ to $+85^{\circ}C$, unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Units
V _{VDDCORE}	DC Supply Core		1.08	1.20	1.32	
V _{VDDIO}	DC Supply I/Os	(1) (2)	3.00	3.30	3.60	
Vvddpll	PLLA, PLLB and Main Oscillator Suplly		1.08		1.32	
A _{VDD}	PLC Analog Converter Power Supply		3.00	3.30	3.60	
VIL	Input Low-level Voltage	PA0-PA25, PB0-PB12, PC0, PC5, PC26	-0.3		MIN[0.8V:0.3 x V _{VDDIO}]	
VIH	Input High-level Voltage	PA0-PA25, PB0 PB12, PC0, PC5, PC26	MIN[2.0V:0.7 x V _{VDDIO}]		V _{VDDIO+} 0.3V	V
V _{OH}	Output High-level Voltage	PA0-PA25, PB0-PB12, PC0, PC5, PC26 $I_{OL} = 4.0 \text{ mA}$	V _{VDDIO} -0.4V			
		VDDIO [3.0V : 3.60V] PB0-PB12	V _{VDDIO} -0.15V			
V _{OL}	Output Low-level Voltage	PA0-PA25, PB0 PB12, PC0, PC5, PC26 $I_{OL} = 4.0 \text{ mA}$			0.4	
		VDDIO [3.0V : 3.60V] PB0-PB12			0.15	
V _{Hys}	Hysteresis Voltage	PA0-PA25, PB0-PB9, PB12, PC0,PC5,PC26 (Hysteresis mode enabled)	150			mV
Іон	IOH (OT ISOURCE)	VDDIO [3V : 3.60V] ;V _{OH} = V _{VDDIO} - 0.4V - PA14 (SPCK) - PA[12-13], - PA[0-3] - Other pins ⁽¹⁾ VDDIO [3.0V : 3.60V] - PB[10-11] -EMIT[1:6] -Other PLC pins VDDIO [3V : 3.60V] ; V _{OH} =			-4 -4 -2 -2 -30 -20 -10	mA
		VDDIO [3V : 3.80V] , V _{0H} = V _{VDDIO} - 0.4V - NRST			-2	

Table 13-2. SAM4SP32A DC Characteristics



Symbol	Parameter	Conditions	Min	Тур	Max	Units
		VDDIO [3V : 3.60V] ;V _{OH} =				
		V _{VDDIO} - 0.4V			4	
		- PA14 (SPCK)			4	
		- PA[12-13],			2	
		- PA[0-3]			2	
	I _{OL} (or I _{SINK})	- Other pins ⁽¹⁾				
I _{OL}		VDDIO [3.0V : 3.60V]			30	
		- PB[10-11]			20	
		-EMIT[1:6]			10	
		-Other PLC pins				
		VDDIO [3V : 3.60V] ; V _{OH} =				
		V _{VDDIO} - 0.4V			2	
		- NRST				
IIL	Input Low	Pull_up OFF	-1		1	
ΠL		Pull_up ON	10		50	
I _{IH}	Input High	Pull_up OFF	-1		1	μA
		Pull_up ON	10		50	
R _{PULLUP}	Internal Pull-up Resistor	PA0-PA25, PB0- PB12, PC0, PC5, PC26, NRST	70	100	130	
Rpulldown	Internal Pull-down Resistor	PA0-PA25, PB0-PB12, PC0, PC5, PC26, NRST	70	100	130	kΩ
PLC _{RPU}	PLC Internal Pull-up Resistor	3.3v I/O	10	33	80	K12
PLC _{RPD}	PLC Internal Pull- down Resistor	3.3v I/O	10	33	80	

Table 13-2. SAM4SP32A DC Characteristics (Continued)

Note:

1. At power-up VDDIO needs to reach 0.6V before VDDIN reaches 1.0V

2. VDDIO voltage needs to be equal or below to (VDDIN voltage +0.5V)

Symbol	Parameter	Conditions	Min	Тур	Max	Units
V _{VDDIN}	DC Input Voltage Range	(4)(5)	1.6	3.3	3.6	V
Vvddout	DC Output Voltage	Normal Mode Standby Mode		1.2 0		V
VACCURACY	Output Voltage Accuracy	I _{Load} = 0.8mA to 80 mA (after trimming)	-3		3	%
I _{LOAD}	Maximum DC Output Current	$V_{VDDIN} > 1.8V$ $V_{VDDIN} \le 1.8V$			80 40	mA
I _{LOAD-START}	Maximum Peak Current during startup	See Note ⁽³⁾			400	mA
D _{DROPOUT}	Dropout Voltage	$V_{VDDIN} = 1.6V, I_{Load} = Max$		400		mV
V _{LINE}	Line Regulation	V_{VDDIN} from 2.7V to 3.6V; I_{Load} MAX		10	30	
$V_{LINE-TR}$	Transient Line regulation	V_{VDDIN} from 2.7V to 3.6V; tr = tf = 5µs; I_{Load} Max		50	150	mV
VLOAD	Load Regulation	$V_{VDDIN} \ge 1.8V;$ $I_{Load} = 10\%$ to 90% MAX $V_{VDDIN} \ge 1.8V;$		20	40	mV
$V_{\text{LOAD-TR}}$	Transient Load Regulation	$I_{Load} = 10\%$ to 90% MAX tr = tf = 5 µs		50	150	
Ι _Q	Quiescent Current	Normal Mode; @ I _{Load} = 0 mA @ I _{Load} = 80 mA Standby Mode;		5 500	1	μA
CD _{IN}	Input Decoupling Capacitor	Cf. External Capacitor Requirements (1)		4.7		μF
CD _{OUT}	Output Decoupling	Cf. External Capacitor Requirements (2)	1.85	2.2	5.9	μF
	Capacitor	ESR	0.1		10	Ω
T _{ON}	Turn on Time	CD _{OUT} = 2.2µF, V _{VDDOUT} reaches 1.2V (+/- 3%)		300		μs
T _{OFF}	Turn off Time	CD _{OUT} = 2.2µF			40	ms

Table 13-3. 1.2V Voltage Regulator Characteristics (VDDOUT12)



Note:

- A 10μF or higher ceramic capacitor must be connected between VDDIN and the closest GND pin of the device. This large decoupling capacitor is mandatory to reduce startup current, improving transient response and noise rejection.
 - 2. To ensure stability, an external 2.2µF output capacitor, CDOUT must be connected between the VDDOUT and the closest GND pin of the device. The ESR (Equivalent Series Resistance) of the capacitor must be in the range 0.1 to 10 ohms. Solid tantalum and multilayer ceramic capacitors are all suitable as output capacitor. A 100nF bypass capacitor between VDDOUT and the closest GND pin of the device helps decreasing output noise and improves the load transient response.
 - 3. Defined as the current needed to charge external bypass/decoupling capacitor network.
 - 4. At power-up VDDIO needs to reach 0.6V before VDDIN reaches 1.0V
 - 5. VDDIO voltage needs to be equal or below to (VDDIN voltage +0.5V)

Table 13-4. Core Power Supply Brownout Detector Characteristics

Parameter	Symbol	Conditions	Min	Тур	Max	Units
Supply Falling Threshold ⁽¹⁾	V _{TH-}		0.98	1.0	1.04	V
Hysteresis	V _{HYST}				110	mV
Supply Rising Threshold	V _{TH+}		0.8	1.0	1.08	V
Current Consumption	IDDON	Brownout Detector enabled			24	
on VDDCOARE		Brownout Detector disable			2	
Current Consumption	I _{DD33ON}	Brownout Detector enabled			24	μA
on VDDIO	I _{DD330FF}	Brownout Detector disable			1.04 110 1.08 24 2	
V _{TH-} detection propagation time	Td-	[-40/+85°C]	-2.5		+2.5	%
Start Time	T _{START}	From disable state to enable state			320	μs

Note:

 $_{\mbox{\scriptsize 1.}}$ The product is guaranteed to be functional at V $_{\mbox{\scriptsize TH-}}$



Figure 13-1.

Core Brownout Output Waveform

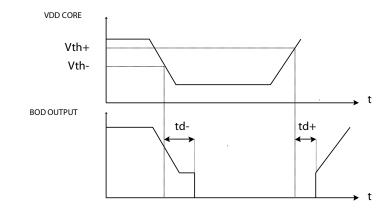


Table 13-5. VDDIO Supply Monitor

Parameter	Symbol	Conditions	Min	Тур	Max	Units
Supply Monitor Threshold	V _{TH}	16 selectable steps	1.6		3.34	V
Threshold Level Accuracy	TACCURACY	[-40/+85°C]	-2.5		+2.5	%
Hysteresis	V _{HYST}			20	30	mV
Current Consumption	I _{DDON}	Enabled			40	
on VDDCOARE	IDDOFF	Disable			10	μA
Start Time	T _{START}	From disable state to enable state			320	μs



Table 13-6. Threshold Selection

Digital Code	Threshold min (V)	Threshold typ (V)	Threshold max (V)
0000	1.58	1.6	1.62
0001	1.7	1.72	1.74
0010	1.82	1.84	1.86
0011	1.94	1.96	1.98
0100	2.05	2.08	2.11
0101	2.17	2.2	2.23
0110	2.29	2.32	2.35
0111	2.41	2.44	2.47
1000	2.53	2.56	2.59
1001	2.65	2.68	2.71
1010	2.77	2.8	2.83
1011	2.8	2.92	2.95
1100	3.0	3.04	3.07
1101	3.12	3.16	3.2
1110	3.24	3.28	3.32
1111	3.36	3.4	3.44

Figure 13-2. VDDIO Supply Monitor

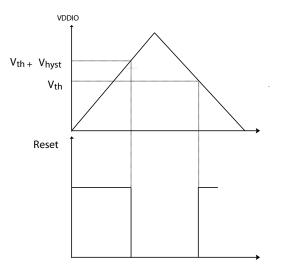




Table 13-7.	Zero-Power-on Reset Characteristics
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Parameter	Symbol	Coditions	Min	Тур	Max	Units
Threshold voltage rising	V _{TH+}	At Startup	1.45	1.53	1.59	V
Threshold voltage falling	V _{TH-}		1.35	1.45	1.55	V
Reset Time-out Period	Tres		100	240	500	μs

Figure 13-3. Zero-Power-on Reset Characteristics

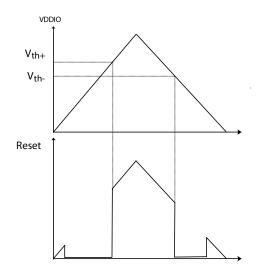


Table 13-8.DC Flash Characteristics

Parameter	Symbol	Coditions	Тур	Max	Units
		andom 144-bit Read:		25	
Active current I _{cc}	Maximum Read Frequency onto VDDCORE = 1.2 @ 25°C	16	25	mA	
	Random 72-bit Read:	10	10		
		Maximum Read Frequency onto VDDCORE = 1.2 @ 25°C	10	18	
		Program onto VDDCORE = 1.2V @ 25°C	3	5	



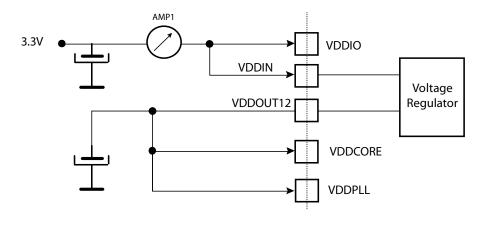
13.3 Power Consumption

- Power consumption of the device according to the different Low Power Mode Capabilities (Backup, Wait, Sleep) and Active Mode.
- Power consumption on power supply in different modes: Backup, Wait, Sleep and Active.
- Power consumption by peripheral: calculated as the difference in current measurement after having enabled then disabled the corresponding clock.

13.3.1 Backup Mode Current Consuption

The Backup Mode configuration and measurements are defined as follows.

Figure 13-4. Measurement Setup



13.3.1.1 Configuration A

- Supply Monitor on VDDIO is disabled
- RTT and RTC not used
- Embedded slow clock RC Oscillator used
- One WKUPx enabled
- Current measurement on AMP1 (See Figure 13-4)

13.3.1.2 Configuration B

- Supply Monitor on VDDIO is disabled
- RTT used
- One WKUPx enabled
- Current measurement on AMP1 (See Figure 13-4)
- 32 KHz Crystal Oscillator used



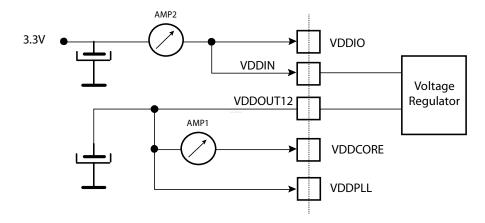
Conditions	Total Consumption (AMP1) Configuration A	Total Consumption (AMP1) Configuration B	Unit
VDDIO = 3.3V @25°C	1.98	1.85	
VDDIO = 3.0V @25°C	1.79	1.66	
VDDIO = 2.5V @25°C	1.51	1.37	μA
VDDIO = 1.8V @25°C	1	0.95	
VDDIO = 3.3V @85°C	13.0	12.42	
VDDIO = 3.0V @85°C	12.0	11.42	
VDDIO = 2.5V @85°C	10.5	10.05	μA
VDDIO = 1.8V @85°C	8.78	8.42	

Table 13-9. Power Consumption for Backup Mode Configuration A and B

13.3.2 Sleep and Wait Mode Current Consumption

The Wait Mode and Sleep Mode configuration and measurements are defined below.

Figure 13-5. Measurement Setup for Sleep Mode



13.3.2.1 Sleep Mode

- Core Clock OFF
- Master Clock (MCK) running at various frequencies with PLLA or the fast RC oscillator.
- Fast start-up through WKUP0-15 pins
- Current measurement as shown in figure Figure 13-6
- All peripheral clocks deactivated

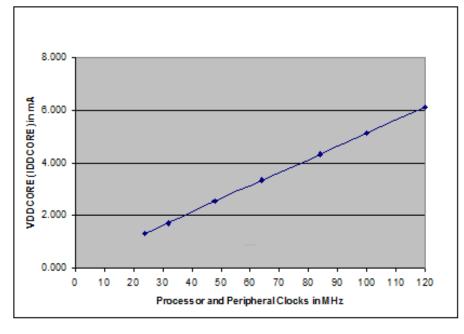
Table 13-10 below gives current consumption in typical conditions.



Table 13-10. Typical Current Consumption for Sleep Mode

Conditions	VDDCORE Consumption (AMP1)	Total Consumption (AMP2)	Unit
Figure 13-6 @25°C MCK = 48 MHz There is no activity on the I/Os of the device.	2.52	3.04	mA

Figure 13-6. Current Consumption in Sleep Mode (AMP1) versus Master Clock ranges (Condition from Table 13-10)



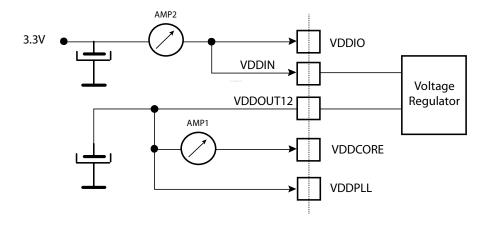


VDDCORE Consumption Unit **Total Consumption** Core Clock/MCK (MHz) (AMP1) (AMP2) 9.9 120 8.1 mΑ 100 8.3 6.7 mΑ 84 5.7 7.1 mΑ 64 4.5 6.4 mΑ 48 3.4 4.8 mΑ 32 2.3 3.38 mΑ 24 1.8 3.31 mΑ

Table 13-11. Sleep mode Current consumptionversus Master Clock (MCK) variation with PLLA

13.3.2.2 Wait Mode

Figure 13-7. Measurement Setup for Wait Mode



- Core Clock and Master Clock Stopped
- Current measurement as shown in the above figure
- All Peripheral clocks deactivated

Table 13-12 gives current consumption in typical conditions.



Table 13-12. Typical Current Consumption in Wait Mode

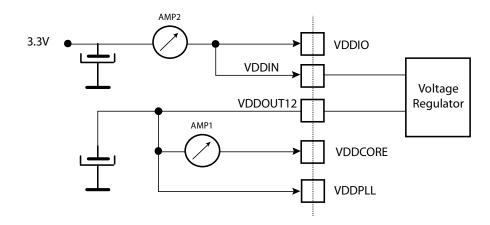
Conditions	VDDOUT Consumption (AMP1)	Total Consumption (AMP2)	Unit
See Figure 13-7 @25°C There is no activity on the I/Os of the device. With the Flash in Standby Mode	20.4	32.2	μΑ
See Figure 13-7 @25°C There is no activity on the I/Os of the device. With the Flash in Deep Power Down Mode	20.5	27.6	μA

13.3.3 Active Mode Power Consumption

The Active Mode configuration and measurements are defined as follows:

- VDDIO = VDDIN = 3.3V
- VDDCORE = 1.2V (Internal Voltage regulator used)
- TA = 25°C
- Application Running from Flash Memory with128-bit access Mode
- All Peripheral clocks are deactivated.
- Master Clock (MCK) running at various frequencies with PLLA or the fast RC oscillator.
- Current measurement on AMP1 (VDDCORE) and total current on AMP2

Figure 13-8. Active Mode Measurement Setup



Tables below give Active Mode Current Consumption in typical conditions.

- VDDCORE at 1.2V
- Temperature = 25°C

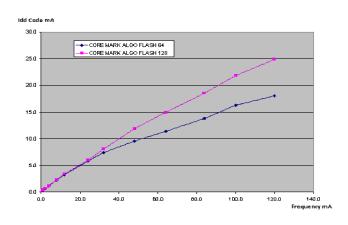


T-LL- 40 40	Active Power Consumption with VDDCORE @ 1.2V (VDDOUT12) running from Flash Memory or SRAM
Table 13-13.	Active Power Consumption with VUUCORE (ψ 1.2V (VUUCUL12) running from Flash Memory of SRAM

		CoreMark				
Core Clock (MHz)	128-bit Flas	sh access ⁽¹⁾	64-bit Flas	sh access ⁽¹⁾	Unit	
	AMP1	AMP2	AMP1	AMP2		
120	24.9	28.8	18	21.4		
100	21.9	25.4	16.3	19.5		
84	18.5	21.4	13.8	16.6		
64	15.0	17.6	11.4	13.9		
48	11.9	14.3	9.6	11.8		
32	8.1	9.9	7.4	9.3		
24	6.0	7.7	5.8	7.5	mA	
12	3.4	6.1	3.2	6.0		
8	2.3	4.5	2.2	4.5	-	
4	1.2	2.6	1.2	2.9	-	
2	0.7	1.9	0.7	2.0		
1	0.4	1.3	0.4	1.6		
0.5	0.3	1.1	0.3	1.3		

Note:

^{1.} Flash Wait State (FWS) in EEFC_FMR adjusted versus Core Frequency





13.3.4 Peripheral Power Consumption in Active Mode

Peripheral	Consumption (Typ)	Unit
PIO Controller A (PIOA)	5.6	
PIO Controller B (PIOB)	7.5	
PIO Controller C (PIOC)	5.9	
UART	3.8	
USART	7.7	
PWM	10.5	
тwi	5.8	
PLC_Bridge	6.9	µA/MHz
Timer Counter (TCx)	4.7	
ACC	1.3	
CRCCU	1.4	
SMC	3.6	
SSC	6.1	
UDP	5	

 Table 13-14.
 Power Consumption on V_{VDDCORE}⁽¹⁾ (when PRIME PLC Transceiver is turned off)

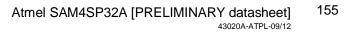


 Table 13-15.
 PRIME PLC Transceiver Peripheral Power Consumption

Parameter	Condition Symbol		Rating			Unit	
	Condition	Min.		Тур.	Max.	Onit	
Power Consumption	(2)	P ₂₅		260		mW	
Power Consumption (worst case)	(3)	P ₈₅			355		

Note:

- 1. VDDIO = 3.3V, $V_{VDDCORE}$ = 1.08V, TA = 25°C
- 2. VDDIO = 3.3V, $V_{VDDCORE}$ = 1.08V, TA = 25°C
- 3. VDDIO = 3.3V, $V_{VDDCORE}$ = 1.08V, TA = 25°C





13.4 Oscillator Characteristics

13.4.1 32 kHz RC Oscillator Characteristics

Table 13-16.	32 kHz RC Oscillator	Characteristics
		onaraotoriotioo

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
	RC Oscillator Frequency		20	32	44	kHz
	Frequency Supply Dependency		-3		3	%/V
	Frequency Temperature Dependency	Over temperature range (-40°C/ +85°C) versus 25°C	-7		7	%
Duty	Duty Cycle		45	50	55	%
T _{ON}	Startup Time				100	μs
I _{DDON}	Current Consumption	After Startup Time Temp. Range = -40°C to +125°C Typical Consumption at 2.2V supply and Temp = 25°C		540	860	nA





13.4.2 4/8/12 MHz RC Oscillators Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
F _{Range}	RC Oscillator Frequency Range	(1)	4		12	MHz
ACC ₄	4 MHz Total Accuracy	-40°C <temp<+85°c 4 MHz output selected ⁽¹⁾⁽²⁾</temp<+85°c 			±30	%
ACC ₈		-40°C <temp<+85°c 8 MHz output selected ⁽¹⁾⁽²⁾</temp<+85°c 			±30	
8 MHz Total Accuracy		-40°C <temp<+85°c 8 MHz output selected ⁽¹⁾⁽³⁾</temp<+85°c 			±5	%
		-40°C <temp<+85°c 12 MHz output selected ⁽¹⁾⁽²⁾</temp<+85°c 			±30	
ACC ₁₂	12 MHz Total Accuracy	-40°C <temp<+85°c 12 MHz output selected ⁽¹⁾⁽³⁾</temp<+85°c 			±5	%
	Frequency deviation versus trimming code	8 MHz 12 MHz		47 64		kHz/trimming code
Duty	Duty Cycle		45	50	55	%
T _{ON}	Startup Time				10	μs
IDDON	Active Current Consumption ⁽²⁾	4MHz 8MHz 12MHz		50 65 82	75 95 118	μΑ

Table 13-17. 4/8/12 MHz RC Oscillators Characteristic

Note:

- 1. Frequency range can be configured in the Supply Controller Registers
- 2. Not trimmed from factory
- 3. After Trimming from factory

The 4/8/12 MHz Fast RC oscillator is calibrated in production. This calibration can be read through the Get CALIB Bit command (see EEFC section) and the frequency can be trimmed by software through the PMC.



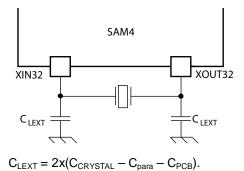
13.4.3 32.768 kHz Crystal Oscillator Characteristics

Symbol	Parameter	Conditions		Min	Тур	Мах	Unit
F _{req}	Operating Frequency	Normal mode with crystal				32.768	KHz
	Supply Ripple Voltage (on VDDIO)	Rms value, 10 k	Rms value, 10 KHz to 10 MHz			30	mV
	Duty Cycle			40	50	60	%
	Startup Time	Rs < 50KΩ Rs < 100KΩ ⑴	$C_{crystal} = 12.5pF$ $C_{crystal} = 6pF$ $C_{crystal} = 12.5pF$ $C_{crystal} = 6pF$			900 300 1200 500	ms
lddon	Current consumption	Rs < 50KΩ Rs < 100KΩ	$\begin{array}{l} C_{crystal} = 12.5 pF\\ C_{crystal} = 6 pF\\ C_{crystal} = 12.5 pF\\ C_{crystal} = 6 pF \end{array}$		550 380 820 530	1150 980 1600 1350	nA
P _{ON}	Drive level					0.1	μW
R _f	Internal resistor	between XIN32 and XOUT32			10		MΩ
C _{LEXT}	Maximum external capacitor on XIN32 and XOUT32					20	pF
C _{para}	Internal Parasitic Capacitance			0.6	0.7	0.8	pF

Table 13-18.	32.768 kHz Crystal Oscillator Characteristics
--------------	---

Note:

1. R_s is the series resitor



Where C_{PCB} is the capacitance of the printed circuit board (PCB) track layout from the crystal to the SAM4 pin.



13.4.4 32.768 kHz Crystal Characteristics

Table 13-19. Crystal Characteristics

Symbol	Parameter	Conditions	Min	Тур	Мах	Unit
ESR	Equivalent Series Resistor (R _{s)}	Crystal @ 32.768 KHz		50	100	KΩ
См	Motional capacitance	Crystal @ 32.768 KHz	0.6		3	fF
CSHUNT	Shunt capacitance	Crystal @ 32.768 KHz	0.6		2	pF

13.4.5 3 to 20 MHz Crystal Oscillator Characteristics

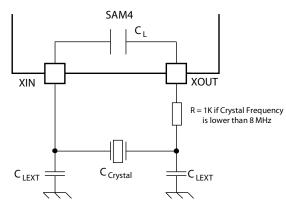
Table 13-20.	3 to 20 MHz Crystal Oscillator Characteristics
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Symbol	Parameter	Conditions	Min	Тур	Max	Unit
F _{req}	Operating Frequency	Normal mode with crystal	3	16	20	MHz
	Supply Ripple Voltage (on VDDPLL)	Rms value, 10 KHz to 10 MHz			30	mV
	Duty Cycle		40	50	60	%
T _{ON}	Startup Time	3 MHz, $C_{SHUNT} = 3pF$ 8 MHz, $C_{SHUNT} = 7pF$ 16 MHz, $C_{SHUNT} = 7pF$ with Cm = 8fF 16 MHz, $C_{SHUNT} = 7pF$ with Cm = 1.6fF 20 MHz, $C_{SHUNT} = 7pF$			14.5 4 1.4 2.5 1	ms
I _{DD_ON}	Current consumption (on VDDIO)	3 MHz ⁽²⁾ 8 MHz ⁽³⁾ 16 MHz ⁽⁴⁾ 20 MHz ⁽⁵⁾		230 300 390 450	350 400 470 560	μA
P _{ON}	Drive level	3 MHz 8 MHz 16 MHz, 20 MHz			15 30 50	μW
R _f	Internal resistor	between XIN and XOUT		0.5		MΩ
C _{LEXT}	Maximum external capacitor on XIN and XOUT		12.5		17.5	pF
CL	Internal Equivalent Load Capacitance	Integrated Load Capacitance (XIN and XOUT in series)	7.5	9.5	10.5	pF



Note:

- R_s = 100-200 Ohms; Cs = 2.0 2.5pF; Cm = 2 1.5 fF(typ, worst case) using 1 K<Symbol>W serial resistor on XOUT.
- 2. $R_s = 50-100 \text{ Ohms}$; Cs = 2.0 2.5 pF; Cm = 4 3 fF(typ, worst case).
- 3. $R_s = 25-50$ Ohms; Cs = 2.5 3.0 pF; Cm = 7 5 fF (typ, worst case).
- 4. $R_s = 20-50$ Ohms; Cs = 3.2 4.0pF; Cm = 10 8 fF(typ, worst case).



 $C_{\text{LEXT}} = 2x(C_{\text{CRYSTAL}} - C_{\text{L}} - C_{\text{PCB}}).$

Where C_{PCB} is the capacitance of the printed circuit board (PCB) track layout from the crystal to the SAM4 pin

13.4.6 3 to 20 MHz Crystal Characteristics

Table 13-21.	3 to 20 MHz (Crystal Characteristics
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Symbol	Parameter	Conditions	Min	Тур	Мах	Unit
ESR	Equivalent Series Resistor (Rs)	Fundamental @ 3 MHz Fundamental @ 8 MHz Fundamental @ 12 MHz Fundamental @ 16 MHz Fundamental @ 20 MHz			200 100 80 80 50	Ω
См	Motional capacitance				8	fF
CSHUNT	Shunt capacitance				7	pF



13.4.7 Crystal Oscillator Design Considerations Information

13.4.7.1 Choosing a Crystal

When choosing a crystal for the 32768 Hz Slow Clock Oscillator or for the 3-20 MHz Oscillator, several parameters must be taken into account. Important parameters between crystal and SAM4S specifications are as follows:

- Load Capacitance
 - C_{crystal} is the equivalent capacitor value the oscillator must "show" to the crystal in order to oscillate at the target frequency. The crystal must be chosen according to the internal load capacitance (C_L) of the on-chip oscillator. Having a mismatch for the load capacitance will result in a frequency drift.
- Drive Level
 - Crystal drive level >= Oscillator Drive Level. Having a crystal drive level number lower than the oscillator specification may damage the crystal.
- Equivalent Series Resistor (ESR)
 - Crystal ESR <= Oscillator ESR Max. Having a crystal with ESR value higher than the oscillator may cause the oscillator to not start.
- Shunt Capacitance
 - Max. crystal Shunt capacitance <= Oscillator Shunt Capacitance (C_{SHUNT}). Having a crystal with ESR value higher than the oscillator may cause the oscillator to not start.

13.4.7.2 Printed Circuit Board (PCB)

SAM4SP32A Oscillators are low power oscillators requiring particular attention when designing PCB systems.



13.5 PLLA, PLLB Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
	Supply Voltage Range		1.08	1.2	1.32	V
VDDPLL	Allowable Voltage Ripple	RMS Value 10 kHz to 10 MHz RMS Value > 10 MHz			20 10	mV

Table 13-22. Supply Voltage Phase Lock Loop Characteristics

Table 13-23. PLLA and PLLB Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
F _{IN}	Input Frequency		3		32	MHz
F _{OUT}	Output Frequency		80		240	MHz
I _{PLL}	Current Consumption	Active mode @ 80 MHz @1.2V Active mode @ 96 MHz @1.2V Active mode @ 160 MHz @1.2V Active Mode @240 MHz @1.2V		0.94 1.2 2.1 3.34	1.2 1.5 2.5 4	mA
T _{START}	Settling Time			60	150	μS



13.6 USB Transceiver Characteristics

13.6.1 Typical Connections

For typical connection please refer to the USB Device Section.

13.6.2 Electrical Characteristics

Table 13-24. Electrical Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
		Input Levels				
VIL	Low Level				0.8	V
V _{IH}	High Level		2.0			V
V _{DI}	Differential Input Sensitivity	(D+) - (D-)	0.2			V
V _{CM}	Differential Input Common Mode Range		0.8		2.5	V
C _{IN}	Transceiver capacitance	Capacitance to ground on each line			9.18	pF
I	Hi-Z State Data Line Leakage	0V < V _{IN} < 3.3V	-10		+10	μA
R _{EXT}	Recommended External USB Series Resistor	In series with each USB pin with $\pm 5\%$		27		Ω
		Output Levels				
V _{OL}	Low Level Output	Measured with R_L of 1.425 $k\Omega$ tied to 3.6V	0.0		0.3	V
V _{OH}	High Level Output	Measured with R_L of 14.25 k Ω tied to GND	2.8		3.6	V
V _{CRS}	Output Signal Crossover Voltage	Measure conditions described in Figure 13-9	1.3		2.0	V
		Consumption	·	·		
	Current Consumption	Transceiver enabled in input mode		105	200	μΑ
IVDDCORE	Current Consumption	DDP = 1 and $DDM = 0$		80	150	μA



Table 13-23. Electrical Characteristics (Continued)

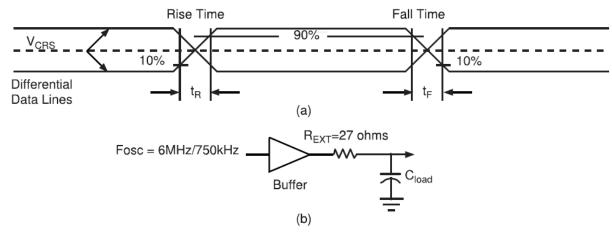
Symbol	Parameter	Conditions	Min	Тур	Мах	Unit
	Pull-up Res	istor				
R _{PUI}	Bus Pull-up Resistor on Upstream Port (idle bus)		0.900		1.575	kΩ
R _{PUA}	Bus Pull-up Resistor on Upstream Port (upstream port receiving)		1.425		3.090	kΩ

13.6.3 Switching Characteristics

Table 13-24. In Full Speed

Symbol	Parameter	Conditions	Min	Тур	Мах	Unit
t _{FR}	Transition Rise Time	$C_{LOAD} = 50 \text{ pF}$	4		20	ns
t _{FE}	Transition Fall Time	$C_{LOAD} = 50 \text{ pF}$	4		20	ns
t _{FRFM}	Rise/Fall time Matching		90		111.11	%

Figure 13-9. USB Data Signal Rise and Fall Times





13.7 Analog Comparator Characteristics

Parameter	Conditions	Min	Тур	Max	Units
Voltage Range	The Analog Comparator is supplied by VDDIN	1.62	3.3	3.6	V
Input Voltage Range		GND + 0.2		VDDIN - 0.2	V
Input Offset Voltage				20	mV
Current Consumption	On VDDIN Low Power Option (ISEL = 0) High Speed Option (ISEL = 1)			25 170	μA
Hysteresis	HYST = 0x01 or 0x10 HYST = 0x11		15 30	50 90	mV
Settling Time	Given for overdrive > 100 mV Low Power Option High Speed Option			1 0.1	μs

 Table 13-25.
 Analog Comparator Characteristics



13.8 Temperature Sensor

The temperature sensor is connected to Channel 15 of the ADC.

The temperature sensor provides an output voltage (V_T) that is proportional to absolute temperature (PTAT). The V_T output voltage linearly varies with a temperature slope $dV_T/dT = 4.72 \text{ mV/}^{\circ}\text{C}$.

The V_T voltage equals 1.44V at 27°C, with a ±50mV accuracy. The V_T slope versus temperature $dV_T/dT = 4.72 \text{ mV/}^{\circ}C$ only shows a ±8% slight variation over process, mismatch and supply voltage.

The user needs to calibrate it (offset calibration) at ambient temperature in order to get rid of the VT spread at ambient temperature (+/-15%).

Symbol	Parameter	Conditions	Min	Тур	Max	Units
V _T	Output Voltage	T° = 27° C		1.44		V
<symbol> DV_T</symbol>	Output Voltage Accuracy	T° = 27° C	-50		+50	mV
dV _T /dT	Temperature Sensitivity (slope voltage versus temperature)			4.72		mV/°C
	Slope accuracy	Over temperature range [-40°C / +85°C]	-8		+8	%
	T	After offset calibration Over temperature range [-40°C / +85°C]	-5		+5	°C
	Temperature accuracy	After offset calibration Over temperature range [0°C / +80°C]	-3		+3	°C
T _{START-UP}	Startup Time	After TSON = 1		5	10	μs
	Current Consumption		50	70	80	μA

Table 13-26. Temperature Sensor Characteristics



13.9 AC Characteristics

13.9.1 Master Clock Characteristics

Table 13-27. Master Clock Waveform Parameters

Symbol	Parameter	Conditions	Min	Max	Units
1/(t _{СРМСК})	Master Clock Frequency	VDDCORE @ 1.20V		120	MHz
1/(t _{СРМСК})	Master Clock Frequency	VDDCORE @ 1.08V		100	MHz

13.9.2 I/O Characteristics

Criteria used to define the maximum frequency of the I/Os:

- Output duty cycle (40%-60%)
- Minimum output swing: 100 mV to VDDIO 100 mV
- Minimum output swing: 100 mV to VDDIO 100 mV
- Addition of rising and falling time inferior to 75% of the period



Table 13-28. I/O Characteristics

Symbol	Parameter		Conditions	Min	Max	Units
FreqMax1	Pin Group 1 ⁽¹⁾ Maximum output frequency	10 pF	$V_{DDIO} = 1.62V$		70	MHz
	Trequency	30 pF	V _{DDIO} = 1.62V		45	
PulseminH ₁	Pin Group 1 ⁽¹⁾ High Level Pulse Width	10 pF	$V_{DDIO} = 1.62V$	7.2		ns
		30 pF	$V_{DDIO} = 1.62V$	11		
PulseminL ₁	Pin Group 1 ⁽¹⁾ Low Level Pulse Width	10 pF	V _{DDIO} = 1.62V	7.2		ns
		30 pF	$V_{DDIO} = 1.62V$	11		
FreqMax2	Pin Group 2 ⁽²⁾ Maximum output frequency	10 pF	V _{DDIO} = 1.62V		46	MHz
	Поционоу	25 pF	$V_{DDIO} = 1.62V$		23	3
PulseminH ₂	Pin Group 2 ⁽²⁾ High Level Pulse Width	10 pF	V _{DDIO} = 1.62V	11		ns
		25pF	$V_{DDIO} = 1.62V$	21.8		
PulseminL ₂	Pin Group 2 ⁽²⁾ Low Level Pulse Width	10 pF	$V_{DDIO} = 1.62V$	11		ns
		25 pF	$V_{DDIO} = 1.62V$	21.8		
FreqMax3	Pin Group3 ⁽³⁾ Maximum output frequency	10 pF	$V_{DDIO} = 1.62V$		70	MHz
		25 pF	$V_{DDIO} = 1.62V$		35	
$PulseminH_3$	Pin Group 3 ⁽³⁾ High Level Pulse Width	10 pF	$V_{DDIO} = 1.62V$	7.2		ns
		25 pF	$V_{DDIO} = 1.62V$	14.2		
PulseminL ₃	Pin Group 3 ⁽³⁾ Low Level Pulse Width	10 pF	$V_{DDIO} = 1.62V$	7.2		ns
		25 pF	V _{DDIO} = 1.62V	14.2		



Table 13-28. I/O Characteristics

Symbol	Parameter		Conditions	Min	Max	Units
FreqMax4	Pin Group 4 ⁽⁴⁾ Maximum output frequency	10 pF	$V_{DDIO} = 1.62V$		58	MHz
Пермалт		25 pF	$V_{DDIO} = 1.62V$		29	
PulseminH₄	Pin Group 4 ⁽⁴⁾ High Level Pulse Width	10 pF	$V_{DDIO} = 1.62V$	8.6		ns
		25pF	$V_{DDIO} = 1.62V$	17.2		
PulseminL₄	Pin Group 4 ⁽⁴⁾ Low Level Pulse Width	10 pF	V _{DDIO} = 1.62V	8.6		ns
1 0100111124		25 pF	$V_{DDIO} = 1.62V$	17.2		
FreqMax5	Pin Group 5 ⁽⁵⁾ Maximum output frequency	25 pF	V _{DDIO} = 1.62V		25	MHz

Note:

- 1. Pin Group 1 = PA14, PA29
- 2. Pin Group 2 = PA[4-11], PA[15-25], PA[30-31], PB[0-9], PB[12-14], PC[0-31]
- 3. Pin Group 3 = PA[12-13], PA[26-28], PA[30-31]
- 4. Pln Group 4 = PA[0-3]
- 5. Pln Group 5 = PB[10-11]

13.9.3 SSC Timings

Timings are given in the following domain:

1.8V domain: VDDIO from 1.65V to 1.95V, maximum external capacitor = 20 pF

3.3V domain: VDDIO from 2.85V to 3.6V, maximum external capacitor = 30 pF.

Figure 13-10. SSC Transmitter, TK and TF as output

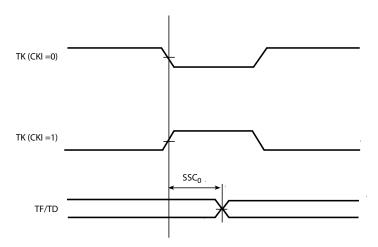




Figure 13-11. SSC Transmitter, TK as input and TF as output

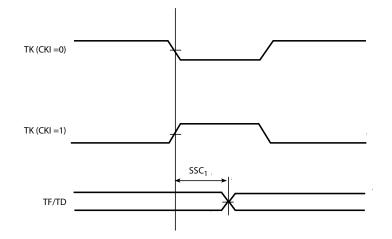
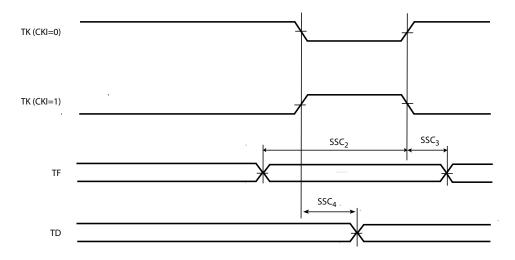
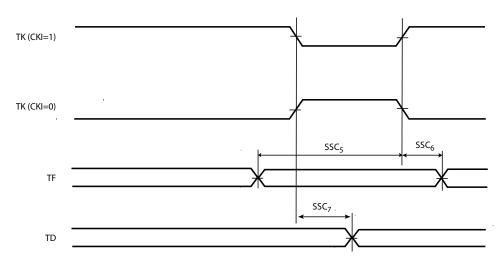


Figure 13-12. SSC Transmitter, TK as output and TF as input







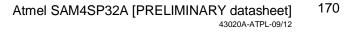




Figure 13-14. SSC Receiver RK and RF as input

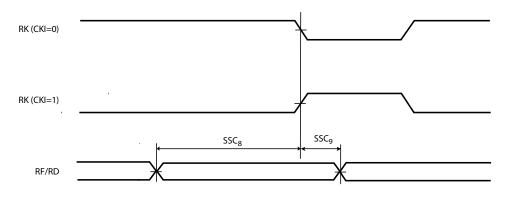
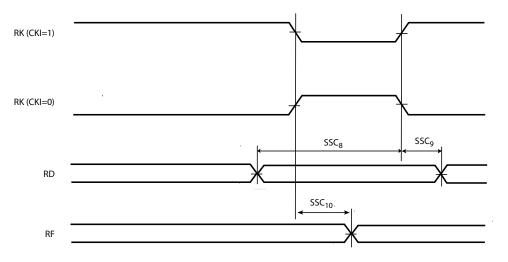
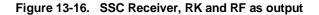
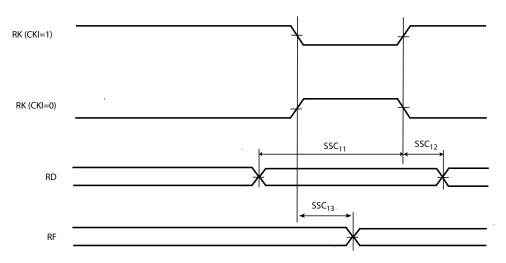


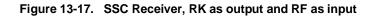
Figure 13-15. SSC Receiver, RK as input and RF as output

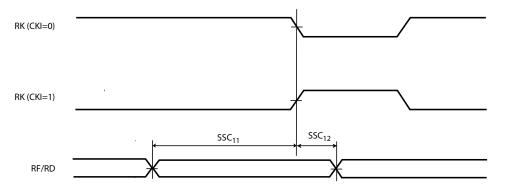














13.9.3.2 SSC Timings

Table 13-29. SSC Timings

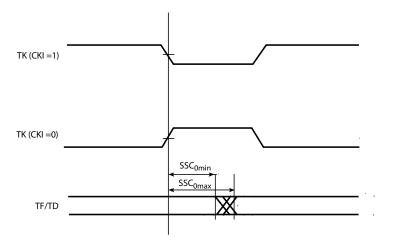
Symbol	Parameter	Condition	Min	Мах	Units
		Transmitter		-	
SSC ₀	TK edge to TF/TD (TK output, TF output)	1.8v domain ⁽³⁾ 3.3v domain ⁽⁴⁾	-3 -2.6	5.4 5.0	ns
SSC1	TK edge to TF/TD (TK input, TF output)	1.8v domain ⁽³⁾ 3.3v domain ⁽⁴⁾	4.5 3.8	16.3 13.3	ns
SSC ₂	TF setup time before TK edge (TK output)	1.8v domain ⁽³⁾ 3.3v domain ⁽⁴⁾	14.8 12.0		ns
SSC₃	TF hold time after TK edge (TK output)	1.8v domain ⁽³⁾ 3.3v domain ⁽⁴⁾	0		ns
SSC4 ⁽¹⁾	TK edge to TF/TD (TK output, TF input)	1.8v domain ⁽³⁾ 3.3v domain ⁽⁴⁾	2.6(+2*t _{СРМСК}) ⁽¹⁾⁽⁴⁾ 2.3(+2*t _{СРМСК}) ⁽¹⁾⁽⁴⁾	5.4(+2*t _{СРМСК}) ⁽¹⁾⁽⁴⁾ 5.0(+2*t _{СРМСК}) ⁽¹⁾⁽⁴⁾	ns
SSC₅	TF setup time before TK edge (TK input)	1.8v domain ⁽³⁾ 3.3v domain ⁽⁴⁾	0		ns
SSC ₆	TF hold time after TK edge (TK input)	1.8v domain ⁽³⁾ 3.3v domain ⁽⁴⁾	t _{СРМСК}		ns
SSC7 ⁽¹⁾	TK edge to TF/TD (TK input, TF input)	1.8v domain ⁽³⁾ 3.3v domain ⁽⁴⁾	4.5(+3*t _{СРМСК}) ⁽¹⁾⁽⁴⁾ 3.8(+3*t _{СРМСК}) ⁽¹⁾⁽⁴⁾	16.3(+3*t _{CPMCK}) ⁽¹⁾⁽⁴⁾ 13.3(+3*t _{CPMCK}) ⁽¹⁾⁽⁴⁾	ns
		Receiver	I		I
SSC ₈	RF/RD setup time before RK edge (RK input)	1.8v domain ⁽³⁾ 3.3v domain ⁽⁴⁾	0		ns
SSC ₉	RF/RD hold time after RK edge (RK input)	1.8v domain ⁽³⁾ 3.3v domain ⁽⁴⁾	t _{СРМСК}		ns
SSC ₁₀	RK edge to RF (RK input)	1.8v domain ⁽³⁾ 3.3v domain ⁽⁴⁾	4.7 4	16.1 12.8	ns
SSC ₁₁	RF/RD setup time before RK edge (RK output)	1.8v domain ⁽³⁾ 3.3v domain ⁽⁴⁾	15.8 - t _{СРМСК} 12.5- t _{СРМСК}		ns
SSC ₁₂	RF/RD hold time after RK edge (RK output)	1.8v domain ⁽³⁾ 3.3v domain ⁽⁴⁾	t _{срмск} - 4.3 t _{срмск} - 3.6		ns
SSC ₁₃	RK edge to RF (RK output)	1.8v domain ⁽³⁾ 3.3v domain ⁽⁴⁾	-3 -2.6	4.3 3.8	ns



Note:

- 1. Timings SSC4 and SSC7 depend on the start condition. When STTDLY = 0 (Receive start delay) and START = 4, or 5 or 7(Receive Start Selection), two Periods of the MCK must be added to timings.
- 2. For output signals (TF, TD, RF), Min and Max access times are defined. The Min access time is the time between the TK (or RK) edge and the signal change. The Max access timing is the time between the TK edge and the signal stabilization. Figure 13-18 illustrates Min and Max accesses for SSC0. The same applies for SSC1, SSC4, and SSC7, SSC10 and SSC13.
- 3. 1.8V domain: V_{VDDIO} from 1.65V to 1.95V, maximum external capacitor = 20 pF.
- 4. 3.3V domain: V_{VDDIO} from 2.85V to 3.6V, maximum external capacitor = 30 pF..

Figure 13-18. Min and Max Access Time of Output Signals





13.9.4 SMC Timings

Timings are given in the following domain:

1.8V domain: VDDIO from 1.65V to 1.95V, maximum external capacitor = 30 pF

3.3V domain: VDDIO from 2.85V to 3.6V, maximum external capacitor = 50 pF.

Timings are given assuming a capacitance load on data, control and address pads:

In the following tables $t_{\mbox{\scriptsize CPMCK}}$ is MCK period. Timing extraction

13.9.4.1 Read Timings

Table 13-30. SMC Read Signals - NRD Controlled (READ_MODE = 1)

Symbol	Parameter	М	lin	M	ax	Units
	VDDIO Supply	1.8V ⁽²⁾	3.3V ⁽³⁾	1.8V ⁽²⁾	3.3V ⁽³⁾	
	N	O HOLD SETTING	GS (nrd hold = 0)			
SMC ₁	Data Setup before NRD High	19.9	17.9			ns
SMC ₂	Data Hold after NRD High	0	0			ns
	HOL	D SETTINGS (nrc	l hold <symbol>1</symbol>	0)		
SMC ₃	Data Setup before NRD High	16.0	14.0			ns
SMC ₄	Data Hold after NRD High	0	0			ns
	HOLD or NO HOL	D SETTINGS (nrd	I hold <symbol>1</symbol>	0, nrd hold = 0)		
SMC ₅	A0 - A22 Valid before NRD High	(nrd setup + nrd pulse) * t _{СРМСК} - 6.5	(nrd setup + nrd pulse)* t _{СРМСК} - 6.3			ns
SMC ₆	NCS low before NRD High	(nrd setup + nrd pulse - ncs rd setup) * t _{СРМСК} - 4.6	(nrd setup + nrd pulse - ncs rd setup) * t _{СРМСК} - 5.1			ns
SMC ₇	NRD Pulse Width	nrd pulse * t _{СРМСК} - 7.2	nrd pulse * t _{СРМСК} - 6.2			ns



Symbol	Parameter	Min		Мах		Units
	VDDIO supply	1.8V ⁽²⁾	3.3V ⁽³⁾	1.8V ⁽²⁾	3.3V ⁽³⁾	
	NC	HOLD SETTINGS (n	cs rd hold = 0)			
SMC ₈	Data Setup before NCS High	20.7	18.4			ns
SMC ₉	Data Hold after NCS High	0	0			ns
HOLD SET	TINGS (ncs rd hold <symbol>¹ 0)</symbol>					
SMC ₁₀	Data Setup before NCS High	16.8	14.5			ns
SMC ₁₁	Data Hold after NCS High	0	0			ns
	HOLD or NO HOLD	SETTINGS (ncs rd ho	old <symbol>¹ 0, nc</symbol>	s rd hold = 0)		
SMC ₁₂	A0 - A22 valid before NCS High	(ncs rd setup + ncs rd pulse)* t _{СРМСК} - 6.5	(ncs rd setup + ncs rd pulse)* t _{CPMCK} - 6.3			ns
SMC ₁₃	NRD low before NCS High	(ncs rd setup + ncs rd pulse - nrd setup)* t _{СРМСК} - 5.6	(ncs rd setup + ncs rd pulse - nrd setup)* t _{CPMCK} - 5.4			ns
SMC ₁₄	NCS Pulse Width	ncs rd pulse length * t _{CPMCK} -7.7	ncs rd pulse length * t _{CPMCK} - 6.7			ns

Table 13-31. SMC Read Signals - NCS Controlled (READ_MODE= 0)



13.9.4.2 Write Timings

		Mi	n	Max				
Symbol	Parameter	1.8V ⁽²⁾	3.3V ⁽³⁾	1.8V ⁽²⁾	3.3V ⁽³⁾	Units		
HOLD or NO HOLD SETTINGS (nwe hold <symbol>¹ 0, nwe hold = 0)</symbol>								
SMC ₁₅	Data Out Valid before NWE High	nwe pulse * t _{CPMCK} - 6.9	nwe pulse * t _{CPMCK} - 6.7			ns		
SMC ₁₆	NWE Pulse Width	nwe pulse * t _{CPMCK} - 7.3	nwe pulse * t _{CPMCK} - 6.3			ns		
SMC ₁₇	A0 - A22 valid before NWE low	nwe setup * t _{CPMCK} - 7.2	nwe setup * t _{CPMCK} - 7.0			ns		
SMC ₁₈	NCS low before NWE high	(nwe setup - ncs rd setup + nwe pulse) * t _{СРМСК} -7.1	(nwe setup - ncs rd setup + nwe pulse) * t _{CPMCK} - 6.8			ns		
	HOLD) SETTINGS (nwe ho	ld <symbol>1 0)</symbol>			-		
SMC ₁₉	NWE High to Data OUT, NBS0/A0 NBS1, NBS2/A1, NBS3, A2 - A25 change	nwe hold * t _{CPMCK} - 8.8	nwe hold * t _{CPMCK} - 6.9			ns		
SMC ₂₀	NWE High to NCS Inactive ⁽¹⁾	(nwe hold - ncs wr hold)* t _{СРМСК} - 5.2	(nwe hold - ncs wr hold)* t _{CPMCK} - 5.0			ns		
	NC	HOLD SETTINGS (nwe hold = 0)					
SMC ₂₁	NWE High to Data OUT, NBS0/A0 NBS1, NBS2/A1, NBS3, A2 - A25, NCS change ⁽¹⁾	3.0	2.8			ns		



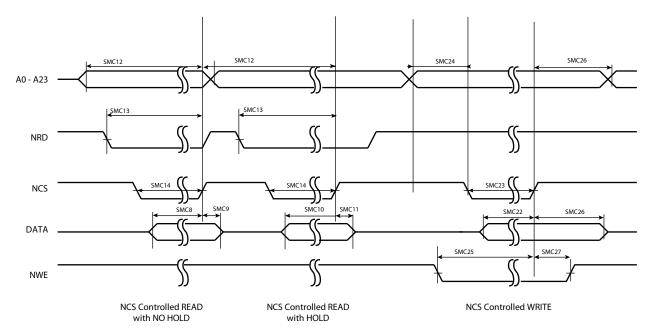
Table 13-33. SMC Write NCS Controlled (WRITE_MODE = 0)

		Min		Max		
Symbol	Parameter	1.8V ⁽²⁾	3.3V ⁽³⁾	1.8V ⁽²⁾	3.3V ⁽³⁾	Units
SMC ₂₂	Data Out Valid before NCS High	ncs wr pulse * t _{СРМСК} - 6.3	ncs wr pulse * t _{СРМСК} - 6.2			ns
SMC ₂₃	NCS Pulse Width	ncs wr pulse * t _{CPMCK} - 7.7	ncs wr pulse * t _{СРМСК} - 6.7			ns
SMC ₂₄	A0 - A22 valid before NCS low	ncs wr setup * t _{СРМСК} - 6.5	ncs wr setup * t _{СРМСК} - 6.3			ns
SMC ₂₅	NWE low before NCS high	(ncs wr setup - nwe setup + ncs pulse)* t _{СРМСК} - 5.1	(ncs wr setup - nwe setup + ncs pulse)* t _{CPMCK} - 4.9			ns
SMC ₂₆	NCS High to Data Out,A0 - A25, change	ncs wr hold * t _{CPMCK} - 10.2	ncs wr hold * t _{CPMCK} - 8.4			ns
SMC ₂₇	NCS High to NWE Inactive	(ncs wr hold - nwe hold)* t _{CPMCK} - 7.4	(ncs wr hold - nwe hold)* t _{СРМСК} - 7.1			ns

Note:

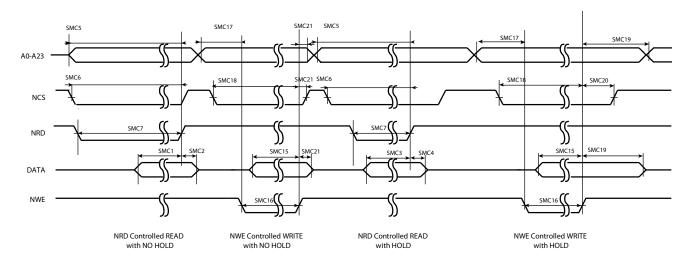
- 1. Hold length = total cycle duration setup duration pulse duration. "hold length" is for "ncs wr hold length" or "NWE hold length".
- 2. 1.8V domain: VDDIO from 1.65 V to 1.95V, maximum external capacitor = 30pF
- 3. 3.3V domain: VDDIO from 2.85V to 3.6V, maximum external capacitor = 50pF.













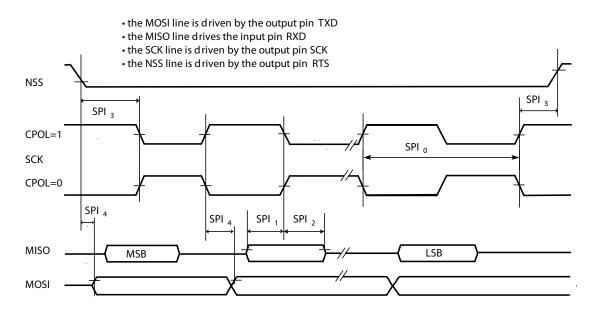
13.9.5 USART in SPI Mode Timings

Timings are given in the following domain:

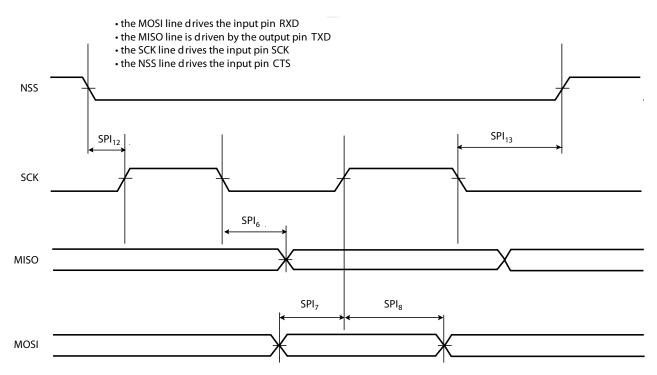
1.8V domain: VDDIO from 1.65V to 1.95V, maximum external capacitor = 20 pF

3.3V domain: VDDIO from 2.85V to 3.6V, maximum external capacitor = 40 pF.



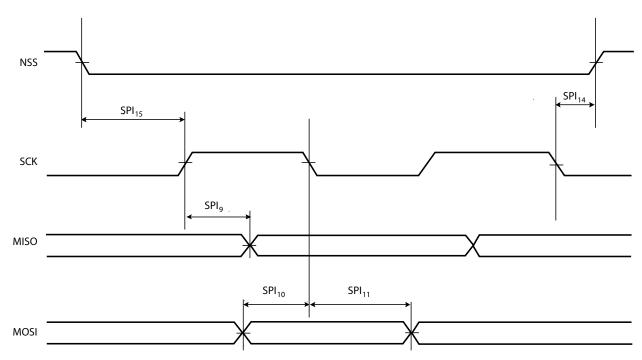














13.9.5.2 USART SPI TImings

Table 13-34. USART SPI Timings

Symbol	Parameter	Conditions	Min	Max	Units	
		Master Mode				
SPI ₀	SCK Period	1.8v domain 3.3v domain	MCK/6		ns	
SPI1	Input Data Setup Time	1.8v domain 3.3v domain	0.5 * MCK + 0.8 0.5 * MCK + 1.0		ns	
SPI ₂	Input Data Hold Time	1.8v domain 3.3v domain	1.5 * MCK + 0.3 1.5 * MCK + 0.1		ns	
SPI3	Chip Select Active to Serial Clock	1.8v domain 3.3v domain	1.5 * SPCK - 1.5 1.5 * SPCK - 2.1		ns	
SPI4	Output Data Setup Time	1.8v domain 3.3v domain	- 7.9 - 7.2	9.9 10.7	ns	
SPI₅	Serial Clock to Chip Select Inactive	1.8v domain 3.3v domain	1 * SPCK - 4.1 1 * SPCK - 4.8		ns	
	Slave Mode					
SPI ₆	SCK falling to MISO	1.8V domain 3.3V domain	4.7 4	17.3 15.2	ns	
SPI7	MOSI Setup time before SCK rises	1.8V domain 3.3V domain	2 * MCK + 0.7 2 * MCK		ns	
SPI8	MOSI Hold time after SCK rises	1.8v domain 3.3v domain	0 0.1		ns	
SPI9	SCK rising to MISO	1.8v domain 3.3v domain	4.7 4.1	17.1 15.5	ns	
SPI ₁₀	MOSI Setup time before SCK falls	1.8v domain 3.3v domain	2 * MCK + 0.7 2 * MCK + 0.6		ns	
SPI ₁₁	MOSI Hold time after SCK falls	1.8v domain 3.3v domain	0.2 0.1		ns	



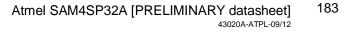
Table 13-34. USART SPI Timings (Continued)

Symbol	Parameter	Conditions	Min	Max	Units
0.01	NDCS0 actus to SCK rising	1.8v domain	2,5 * MCK + 0.5		
SPI ₁₂	NPCS0 setup to SCK rising	3.3v domain	2,5 * MCK		ns
SPI ₁₃	NPCS0 hold after SCK falling	1.8v domain	1,5 * MCK + 0.2		
		3.3v domain	1,5 * MCK		ns
SPI ₁₄	NPCS0 setup to SCK falling	1.8v domain	2,5 * MCK + 0.5		ns
		3.3v domain	2,5 * MCK + 0.3		
	NDCS0 hold offer SCK rising	1.8v domain	1,5 * MCK		n 0
SPI ₁₅	NPCS0 hold after SCK rising	3.3v domain	1,5 * MCK		ns

Note:

1. 1.8V domain: VDDIO from 1.65V to 1.95V, maximum external capacitor = 20 pF

2. 3.3V domain: VDDIO from2.85V to 3.6V, maximum external capacitor = 40 pF.





13.9.6 **Two-wire Serial Interface Characteristics**

Following table describes the requirements for devices connected to the Two-wire Serial Bus. For timing symbols refer to Figure 13-24

Table 13-35.	Two-wire Serial	Bus Requirements
--------------	------------------------	-------------------------

Symbol	Parameter	Condition	Min	Max	Units
VIL	Input Low-voltage		-0.3	0.3 V _{VDDIO}	V
VIH	Input High-voltage		0.7xV _{VDDIO}	V _{CC} + 0.3	V
V _{HYS}	Hysteresis of Schmitt Trigger Inputs		0.150	_	V
V _{OL}	Output Low-voltage	3 mA sink current	-	0.4	V
t _R	Rise Time for both TWD and TWCK		$20 + 0.1 C_{b}^{(1)(2)}$	300	ns
t _{OF}	Output Fall Time from V_{IHmin} to V_{ILmax}	10 pF < C _b < 400 pF Figure 13-24	20 + 0.1C _b ⁽¹⁾⁽²⁾	250	ns
Ci ⁽¹⁾	Capacitance for each I/O Pin		-	10	pF
fтwcк	TWCK Clock Frequency		0	400	kHz
Rp	Value of Pull-up resistor	f _{TWCK} ≤100 kHz			Ω
· .		f _{тwск} > 100 kHz			Ω



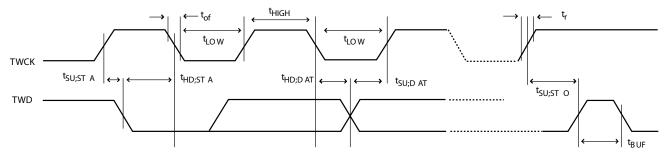
Table 13-35.	Two-wire	Serial	Bus	Requirements	(Continued)
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Symbol	Parameter	Condition	Min	Max	Units
		f _{™CK} ≤100 kHz	(3)	—	μs
t _{LOW}	Low Period of the TWCK clock	$f_{TWCK} > 100 \text{ kHz}$	(3)	-	μs
		f _{™CK} ≤ 100 kHz	(4)	_	μs
t _{HIGH}	High period of the TWCK clock	f _{тwcк} > 100 kHz	(4)	-	μs
		f _{TWCK} ≤ 100 kHz	t _{ніGH}	_	μs
t _{HD;STA}	Hold Time (repeated) START Condition	f_{TWCK} > 100 kHz	t _{HIGH}	-	μs
t _{SU;STA} Set	Set-up time for a repeated START condition	f _{™CK} ≤ 100 kHz	t _{HIGH}	_	μs
		$f_{TWCK} > 100 \text{ kHz}$	t _{HIGH}	-	μs
t _{HD;DAT} Data hold time		f _{™CK} ≤ 100 kHz	0	3 х Т _{СР_МСК} ⁽⁵⁾	μs
	Data hold time	f _{TWCK} > 100 kHz	0	3 x T _{CP_MCK} ⁽⁵⁾	μs
		f _{TWCK} ≤ 100 kHz	t _{LOW} - 3 x t _{CP_MCK} ⁽⁵⁾	_	ns
t _{su;dat}	Data setup time	$f_{TWCK} > 100 \text{ kHz}$	t_{LOW} - 3 x t_{CP_MCK} ⁽⁵⁾	-	ns
		f _{™CK} ≤ 100 kHz	t _{HIGH}	_	μs
t _{SU;STO} Set	Setup time for STOP condition	f _{TWCK} > 100 kHz	tніgн	-	μs
		f _{TWCK} ≤ 100 kHz	t _{ніGH}	_	μs
t _{HD;STA}	Hold Time (repeated) START Condition	f _{тwск} > 100 kHz	tніgн	-	μs

Note:

- 1. Required only for $f_{TWCK} > 100 \text{ kHz}$.
- 2. C_B = capacitance of one bus line in pF. Per I2C Standard, C_b Max = 400pF
- 3. The TWCK low Period is defined as follows: $T_{low} = ((CLDIV \times 2^{CKDIV}) + 4) \times T_{MCK}$
- 4. The TWCK high period is defined as follows: $T_{High} = ((CHDIV \times 2^{CKDIV}) + 4) \times T_{MCK}$
- 5. $t_{CP_MCK} = MCK$ Bus Period.







13.9.7 Embedded Flash Characteristics

The maximum operating frequency is given in Table 13-36 to Table 13-39 below but is limited by the Embedded Flash access time when the processor is fetching code out of it. The tables below give the device maximum operating frequency depending on the field FWS of the MC_FMR register. This field defines the number of wait states required to access the Embedded Flash Memory.

The embedded flash is fully tested during production test, the flash contents are not set to a known state prior to shipment. Therefore, the flash contents should be erased prior to programming an application.

FWS	Read Operations	Maximum Operating Frequency (MHz)
0	1 cycle	16
1	2 cycles	33
2	3 cycles	50
3	4 cycles	67
4	5 cycles	84
5	6 cycles	100

Table 13-36. Embedded Flash Wait State VDDCORE set at 1.08V and VDDIO 1.62V to 3.6V @85

Table 13-37.	Embedded Flash Wait State VDDCORE set at 1.08V and VDDIO 2.7V to 3.6V @85C
	Embedded Flash wait State VDDCORE set at 1.00V and VDDIO 2.7V to 3.0V @05C

FWS	Read Operations	Maximum Operating Frequency (MHz)
0	1 cycle	20
1	2 cycles	40
2	3 cycles	60
3	4 cycles	80
4	5 cycles	100



FWS	Read Operations	Maximum Operating Frequency (MHz)
0	1 cycle	17
1	2 cycles	34
2	3 cycles	52
3	4 cycles	69
4	5 cycles	87
5	6 cycles	104
6	7 cycles	121

Table 13-38. Embedded Flash Wait State VDDCORE set at 1.2V and VDDIO 1.62V to 3.6V @ 85C

Table 13-39. Embedded Flash wait State VDCORE set at 1.20V and VDDO 2.7V to 3.6V @ 850	Table 13-39.	Embedded Flash Wait State VDDCORE set at 1.20V and VDDIO 2.7V to 3.6V @ 85C
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FWS	Read Operations	Maximum Operating Frequency (MHz)
0	1 cycle	21
1	2 cycles	42
2	3 cycles	63
3	4 cycles	84
4	5 cycles	105
5	6 cycles	123



Table 13-40.AC Flash Characteristics

Parameter	Conditions	Min	Тур	Max	Units
	Erase page mode		10	50	ms
Program Cycle Time	Erase block mode (by 4Kbytes)		50	200	ms
	Erase sector mode		400	950	ms
Full Chip Erase	1 MBytes 512 KBytes		9 5.5	18 11	S
Data Retention	Not Powered or Powered		20		Years
Endurance	Write/Erase cycles per page, block or sector @ 25°C Write/Erase cycles per page, block or sector @ 85°C	10K	100K		cycles



13.10 Recommended Operating Conditions

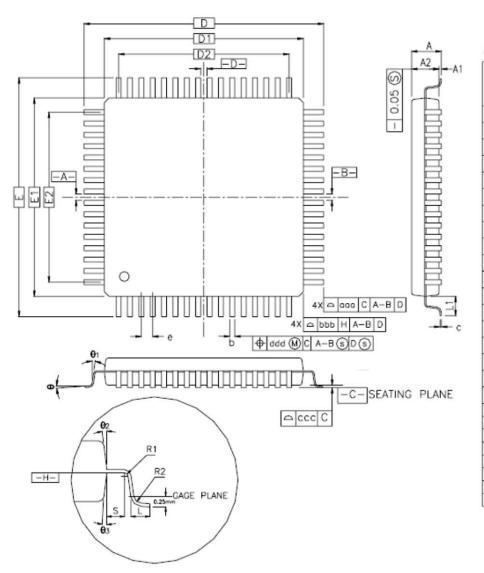
Table 13-41. SAM4SP32A Recommended Operating Conditions

Parameter	Cum h al	Rating			l la it	
Parameter	Symbol Mir	Min	Тур	Мах	Unit	
	Vvddcore	1.08	1.20	1.32		
	V_{VDDIN}	3.00	3.30	3.60		
Supply Voltage	V _{VDDIO}	3.00	3.30	3.60	V	
	Vvddpll	1.08		1.32		
	A _{VDD}	3.00	3.30	3.60		
Junction Temperature	TJ	-40	25	+125		
Ambient Temperature	ТА	-40		+85	°C	



14. Mechanical Characteristics

Figure 14-1. 128-lead LQFP Package Mechanical Drawing



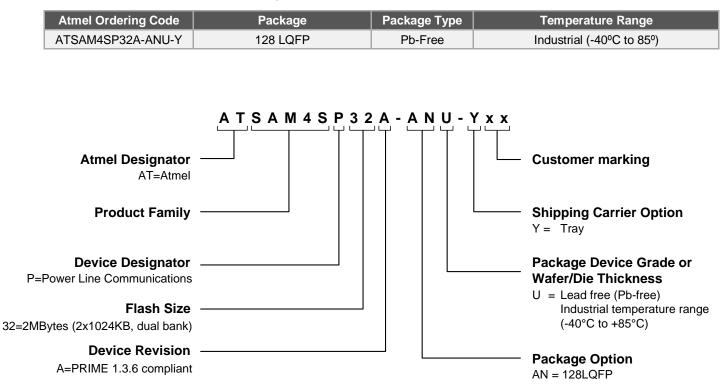
SYMBOL	MILLIMETER			INCH		
	MIN.	NOM.	MAX.	MIN.	NOM.	MAX.
A	—	—	1.60	-	-	0.063
A1	0.05		0.15	0.002	_	0.006
A2	1.35	1.40	1.45	0.053	0.055	0.057
D	16.00 BSC.			0.630 BSC.		
D1	14.00 BSC.			0.551 BSC.		
E	16.00 BSC.			0.630 BSC.		
E1	14.00 BSC.			0.	551 BS	SC.
R2	0.08	—	0.20	0.003	—	0.008
R1	0.08	-	-	0.003		· —
θ	0.	3.5*	7'	0,	3.5*	7'
θι	0.	-	—	0.	—	-
θε	11*	12	13	11*	12	13
θз	11*	12'	13	11.	12*	13
с	0.09	-1	0.20	0.004	-	0.008
L	0.45	0.60	0.75	0.018	0.024	0.030
Lı	1.00 REF			0.039 REF		
S	0.20	-	-	0.008	—	-
b	0.13	0.16	0.23	0.005	0.006	0.009
е	0.40 BSC.			0.0)16 BS	C.
D2	12.40			0.488		
E2	12.40			0.488		
TC	DLERAN	CES OF	FORM	AND	POSITIO	N
000	0.20			0.008		
bbb	0.20			0.008		
ccc	0.08			0.003		
ddd		0.07	0.07			

Note: 1. This drawing is for general information only. Refer to JEDEC Drawing MS-026 for additional information.



15. Ordering Information

Table 15-1. Atmel SAM4SP32A Ordering Codes





16. Revision History

Doc. Rev.	Date	Comments
А	10/2012	Initial release





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Atmel Corporation

1600 Technology Drive San Jose, CA 95110 USA **Tel:** (+1)(408) 441-0311 **Fax:** (+1)(408) 487-2600 www.atmel.com

Atmel Asia Limited

Unit 01-5 & 16, 19F BEA Tower, Millennium City 5 418 Kwun Tong Road Kwun Tong, Kowloon HONG KONG Tel: (+852) 2245-6100 Fax: (+852) 2722-1369

Atmel Munich GmbH

Business Campus Parkring 4 D-85748 Garching b. Munich GERMANY **Tel:** (+49) 89-31970-0 **Fax:** (+49) 89-3194621 Atmel Japan G.K.

16F Shin-Osaki Kangyo Building 1-6-4 Osaki Shinagawa-ku, Tokyo 141-0032 JAPAN **Tel:** (+81)(3) 6417-0300 **Fax:** (+81)(3) 6417-0370

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